

## K61P144M120SF3

### K61 Sub-Family

Supports the following:

MK61FX512VMD12,  
MK61FN1M0VMD12

#### Key features

- Operating Characteristics
  - Voltage range: 1.71 to 3.6 V
  - Flash write voltage range: 1.71 to 3.6 V
  - Temperature range (ambient): -40 to 105°C
- Performance
  - Up to 120 MHz ARM Cortex-M4 core with DSP instructions delivering 1.25 Dhrystone MIPS per MHz
- Memories and memory interfaces
  - Up to 1024 KB program flash memory on non-FlexMemory devices
  - Up to 512 KB program flash memory on FlexMemory devices
  - Up to 512 KB FlexNVM on FlexMemory devices
  - 16 KB FlexRAM on FlexMemory devices
  - Up to 128 KB RAM
  - Serial programming interface (EzPort)
  - FlexBus external bus interface
  - NAND flash controller interface
- Clocks
  - 3 to 32 MHz crystal oscillator
  - 32 kHz crystal oscillator
  - Multi-purpose clock generator
- System peripherals
  - Multiple low-power modes to provide power optimization based on application requirements
  - Memory protection unit with multi-master protection
  - 32-channel DMA controller, supporting up to 128 request sources
  - External watchdog monitor
  - Software watchdog
  - Low-leakage wakeup unit
- Security and integrity modules
  - Hardware CRC module to support fast cyclic redundancy checks
  - Tamper detect and secure storage
  - Hardware random-number generator
  - Hardware encryption supporting DES, 3DES, AES, MD5, SHA-1, and SHA-256 algorithms
  - 128-bit unique identification (ID) number per chip
- Human-machine interface
  - Low-power hardware touch sensor interface (TSI)
  - General-purpose input/output
- Analog modules
  - Four 16-bit SAR ADCs
  - Programmable gain amplifier (PGA) (up to x64) integrated into each ADC
  - Two 12-bit DACs
  - Four analog comparators (CMP) containing a 6-bit DAC and programmable reference input
  - Voltage reference
- Timers
  - Programmable delay block
  - Two 8-channel motor control/general purpose/PWM timers
  - Two 2-channel quadrature decoder/general purpose timers
  - IEEE 1588 timers
  - Periodic interrupt timers
  - 16-bit low-power timer
  - Carrier modulator transmitter
  - Real-time clock

Freescale reserves the right to change the detail specifications as may be required to permit improvements in the design of its products.

- Communication interfaces
  - Ethernet controller with MII and RMII interface to external PHY and hardware IEEE 1588 capability
  - USB high-/full-/low-speed On-the-Go controller with ULPI interface
  - USB high-/full-/low-speed On-the-Go controller with on-chip high speed transceiver
  - USB full-/low-speed On-the-Go controller with on-chip transceiver
  - USB Device Charger detect
  - Two Controller Area Network (CAN) modules
  - Three SPI modules
  - Two I2C modules
  - Six UART modules
  - Secure Digital host controller (SDHC)
  - Two I2S modules

# Table of Contents

1	Ordering parts.....	5	5.4.2	Thermal attributes.....	25
1.1	Determining valid orderable parts.....	5	5.5	Power sequencing.....	25
2	Part identification.....	5	6	Peripheral operating requirements and behaviors.....	26
2.1	Description.....	5	6.1	Core modules.....	26
2.2	Format.....	5	6.1.1	Debug trace timing specifications.....	26
2.3	Fields.....	5	6.1.2	JTAG electricals.....	27
2.4	Example.....	6	6.2	System modules.....	30
3	Terminology and guidelines.....	6	6.3	Clock modules.....	30
3.1	Definition: Operating requirement.....	6	6.3.1	MCG specifications.....	30
3.2	Definition: Operating behavior.....	6	6.3.2	Oscillator electrical specifications.....	32
3.3	Definition: Attribute.....	7	6.3.3	32 kHz oscillator electrical characteristics.....	34
3.4	Definition: Rating.....	7	6.4	Memories and memory interfaces.....	35
3.5	Result of exceeding a rating.....	8	6.4.1	Flash (FTFE) electrical specifications.....	35
3.6	Relationship between ratings and operating requirements.....	8	6.4.2	EzPort switching specifications.....	39
3.7	Guidelines for ratings and operating requirements.....	8	6.4.3	NFC specifications.....	40
3.8	Definition: Typical value.....	9	6.4.4	Flexbus switching specifications.....	43
3.9	Typical value conditions.....	10	6.5	Security and integrity modules.....	46
4	Ratings.....	10	6.5.1	DryIce Tamper Electrical Specifications.....	46
4.1	Thermal handling ratings.....	10	6.6	Analog.....	47
4.2	Moisture handling ratings.....	11	6.6.1	ADC electrical specifications.....	47
4.3	ESD handling ratings.....	11	6.6.2	CMP and 6-bit DAC electrical specifications.....	54
4.4	Voltage and current operating ratings.....	11	6.6.3	12-bit DAC electrical characteristics.....	56
5	General.....	12	6.6.4	Voltage reference electrical specifications.....	59
5.1	AC electrical characteristics.....	12	6.7	Timers.....	60
5.2	Nonswitching electrical specifications.....	12	6.8	Communication interfaces.....	60
5.2.1	Voltage and current operating requirements.....	12	6.8.1	Ethernet switching specifications.....	60
5.2.2	LVD and POR operating requirements.....	13	6.8.2	USB electrical specifications.....	62
5.2.3	Voltage and current operating behaviors.....	14	6.8.3	USB DCD electrical specifications.....	62
5.2.4	Power mode transition operating behaviors.....	16	6.8.4	USB VREG electrical specifications.....	63
5.2.5	Power consumption operating behaviors.....	17	6.8.5	ULPI timing specifications.....	63
5.2.6	EMC radiated emissions operating behaviors.....	21	6.8.6	CAN switching specifications.....	64
5.2.7	Designing with radiated emissions in mind.....	21	6.8.7	DSPI switching specifications (limited voltage range).....	65
5.2.8	Capacitance attributes.....	22	6.8.8	DSPI switching specifications (full voltage range).....	66
5.3	Switching specifications.....	22	6.8.9	Inter-Integrated Circuit Interface (I2C) timing.....	68
5.3.1	Device clock specifications.....	22	6.8.10	UART switching specifications.....	69
5.3.2	General switching specifications.....	23	6.8.11	SDHC specifications.....	69
5.4	Thermal specifications.....	24	6.8.12	I2S/SAI switching specifications.....	70
5.4.1	Thermal operating requirements.....	24			

6.9 Human-machine interfaces (HMI).....	77	8.1 Pins with active pull control after reset.....	78
6.9.1 TSI electrical specifications.....	77	8.2 K61 Signal Multiplexing and Pin Assignments.....	79
7 Dimensions.....	78	8.3 K61 Pinouts.....	84
7.1 Obtaining package dimensions.....	78	9 Revision History.....	85
8 Pinout.....	78		

# 1 Ordering parts

## 1.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to [freescale.com](http://freescale.com) and perform a part number search for the following device numbers: PK61 and MK61

## 2 Part identification

### 2.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

### 2.2 Format

Part numbers for this device have the following format:

Q K## A M FFF T PP CC N

### 2.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

Field	Description	Values
Q	Qualification status	<ul style="list-style-type: none"> <li>M = Fully qualified, general market flow</li> <li>P = Prequalification</li> </ul>
K##	Kinetis family	<ul style="list-style-type: none"> <li>K61</li> </ul>
A	Key attribute	<ul style="list-style-type: none"> <li>F = Cortex-M4 w/ DSP and FPU</li> </ul>
M	Flash memory type	<ul style="list-style-type: none"> <li>N = Program flash only</li> <li>X = Program flash and FlexMemory</li> </ul>
FFF	Program flash memory size	<ul style="list-style-type: none"> <li>512 = 512 KB</li> <li>1M0 = 1 MB</li> </ul>

*Table continues on the next page...*

## Terminology and guidelines

Field	Description	Values
T	Temperature range (°C)	<ul style="list-style-type: none"><li>• V = -40 to 105</li><li>• C = -40 to 85</li></ul>
PP	Package identifier	<ul style="list-style-type: none"><li>• MD = 144 MAPBGA (13 mm x 13 mm)</li><li>• MJ = 256 MAPBGA (17 mm x 17 mm)</li></ul>
CC	Maximum CPU frequency (MHz)	<ul style="list-style-type: none"><li>• 12 = 120 MHz</li></ul>
N	Packaging type	<ul style="list-style-type: none"><li>• R = Tape and reel</li><li>• (Blank) = Trays</li></ul>

## 2.4 Example

This is an example part number:

MK61FN1M0VMD12

## 3 Terminology and guidelines

### 3.1 Definition: Operating requirement

An *operating requirement* is a specified value or range of values for a technical characteristic that you must guarantee during operation to avoid incorrect operation and possibly decreasing the useful life of the chip.

#### 3.1.1 Example

This is an example of an operating requirement:

Symbol	Description	Min.	Max.	Unit
V <sub>DD</sub>	1.0 V core supply voltage	0.9	1.1	V

### 3.2 Definition: Operating behavior

An *operating behavior* is a specified value or range of values for a technical characteristic that are guaranteed during operation if you meet the operating requirements and any other specified conditions.

### 3.2.1 Example

This is an example of an operating behavior:

Symbol	Description	Min.	Max.	Unit
$I_{WP}$	Digital I/O weak pullup/pulldown current	10	130	$\mu A$

### 3.3 Definition: Attribute

An *attribute* is a specified value or range of values for a technical characteristic that are guaranteed, regardless of whether you meet the operating requirements.

#### 3.3.1 Example

This is an example of an attribute:

Symbol	Description	Min.	Max.	Unit
CIN_D	Input capacitance: digital pins	—	7	pF

### 3.4 Definition: Rating

A *rating* is a minimum or maximum value of a technical characteristic that, if exceeded, may cause permanent chip failure:

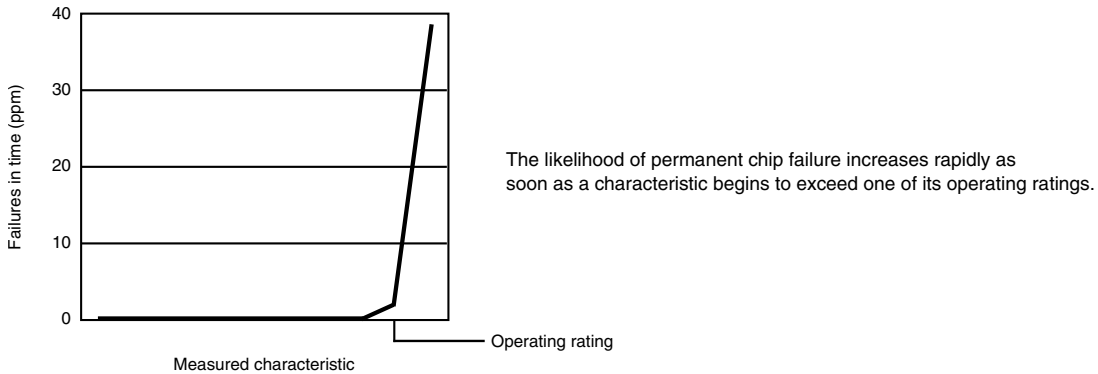
- *Operating ratings* apply during operation of the chip.
- *Handling ratings* apply when the chip is not powered.

#### 3.4.1 Example

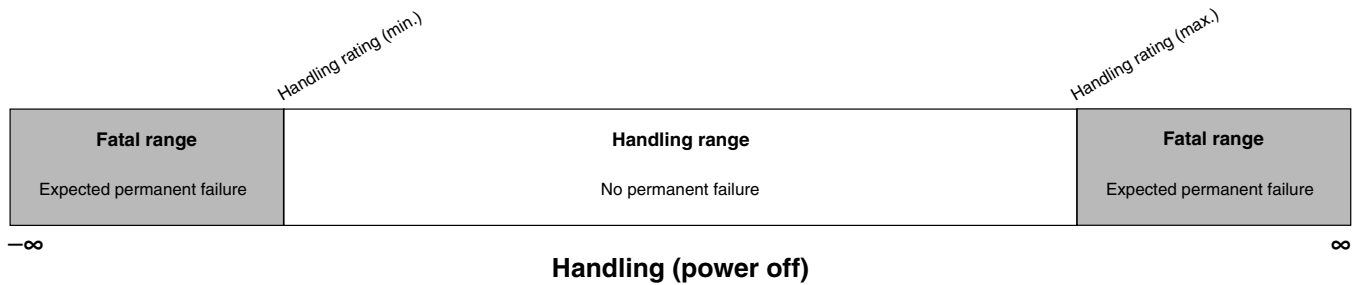
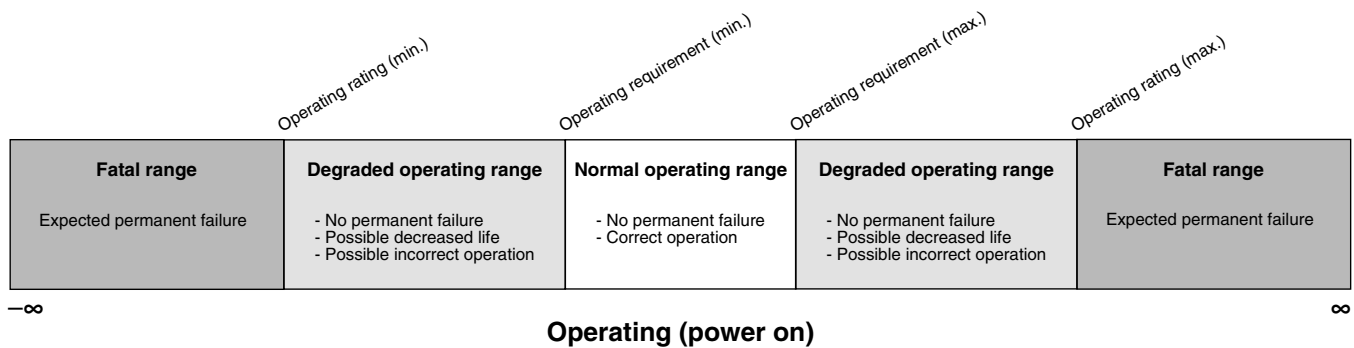
This is an example of an operating rating:

Symbol	Description	Min.	Max.	Unit
$V_{DD}$	1.0 V core supply voltage	-0.3	1.2	V

### 3.5 Result of exceeding a rating



### 3.6 Relationship between ratings and operating requirements



### 3.7 Guidelines for ratings and operating requirements

Follow these guidelines for ratings and operating requirements:

- Never exceed any of the chip’s ratings.



- During normal operation, don't exceed any of the chip's operating requirements.
- If you must exceed an operating requirement at times other than during normal operation (for example, during power sequencing), limit the duration as much as possible.

### 3.8 Definition: Typical value

A *typical value* is a specified value for a technical characteristic that:

- Lies within the range of values specified by the operating behavior
- Given the typical manufacturing process, is representative of that characteristic during operation when you meet the typical-value conditions or other specified conditions

Typical values are provided as design guidelines and are neither tested nor guaranteed.

#### 3.8.1 Example 1

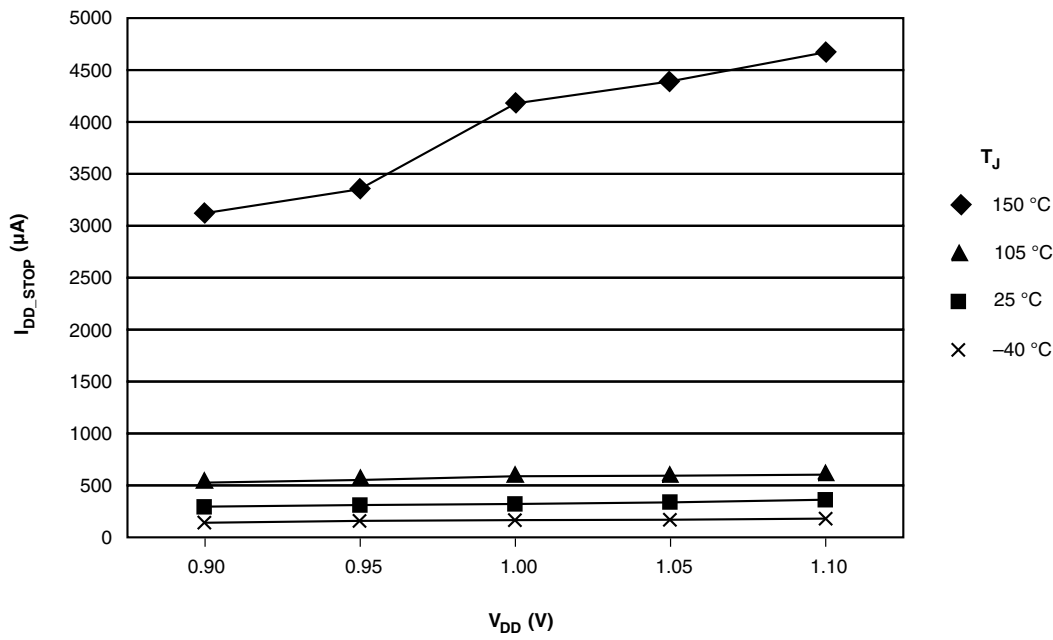
This is an example of an operating behavior that includes a typical value:

Symbol	Description	Min.	Typ.	Max.	Unit
$I_{WP}$	Digital I/O weak pullup/pulldown current	10	70	130	$\mu A$

#### 3.8.2 Example 2

This is an example of a chart that shows typical values for various voltage and temperature conditions:

## Ratings



## 3.9 Typical value conditions

Typical values assume you meet the following conditions (or other conditions as specified):

Symbol	Description	Value	Unit
T <sub>A</sub>	Ambient temperature	25	°C
V <sub>DD</sub>	3.3 V supply voltage	3.3	V

## 4 Ratings

### 4.1 Thermal handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
T <sub>STG</sub>	Storage temperature	-55	150	°C	1
T <sub>SDR</sub>	Solder temperature, lead-free	—	260	°C	2

1. Determined according to JEDEC Standard JESD22-A103, *High Temperature Storage Life*.
2. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

## 4.2 Moisture handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
MSL	Moisture sensitivity level	—	3	—	1

1. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

## 4.3 ESD handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
V <sub>HBM</sub>	Electrostatic discharge voltage, human body model	-2000	+2000	V	1
V <sub>CDM</sub>	Electrostatic discharge voltage, charged-device model	-500	+500	V	2
I <sub>LAT</sub>	Latch-up current at ambient temperature of 105°C	-100	+100	mA	3

1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
2. Determined according to JEDEC Standard JESD22-C101, *Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components*.
3. Determined according to JEDEC Standard JESD78, *IC Latch-Up Test*.

## 4.4 Voltage and current operating ratings

Symbol	Description	Min.	Max.	Unit
V <sub>DD</sub>	Digital supply voltage <sup>1</sup>	-0.3	3.8	V
I <sub>DD</sub>	Digital supply current	—	300	mA
V <sub>DIO</sub>	Digital input voltage (except RESET, EXTAL0/XTAL0, and EXTAL1/XTAL1) <sup>2</sup>	-0.3	5.5	V
V <sub>AIO</sub>	Analog <sup>3</sup> , RESET, EXTAL0/XTAL0, and EXTAL1/XTAL1 input voltage	-0.3	V <sub>DD</sub> + 0.3	V
I <sub>D</sub>	Maximum current single pin limit (applies to all digital pins)	-25	25	mA
V <sub>DDA</sub>	Analog supply voltage	V <sub>DD</sub> - 0.3	V <sub>DD</sub> + 0.3	V
V <sub>USB0_DP</sub>	USB0_DP input voltage	-0.3	3.63	V
V <sub>USB1_DP</sub>	USB1_DP input voltage	-0.3	3.63	V
V <sub>USB0_DM</sub>	USB0_DM input voltage	-0.3	3.63	V
V <sub>USB1_DM</sub>	USB1_DM input voltage	-0.3	3.63	V
V <sub>REGIN</sub>	USB regulator input	-0.3	6.0	V
V <sub>BAT</sub>	RTC battery supply voltage	-0.3	3.8	V

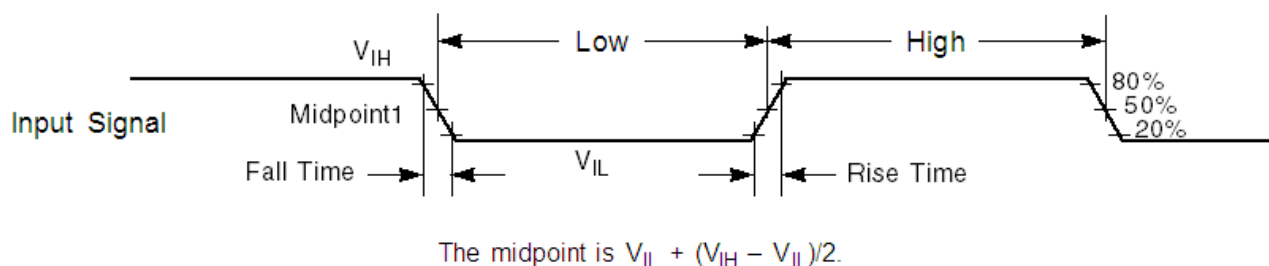
1. It applies for all port pins except Tamper pins.

2. It covers digital pins except Tamper pins.
3. Analog pins are defined as pins that do not have an associated general purpose I/O port function.

## 5 General

### 5.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.



**Figure 1. Input signal measurement reference**

All digital I/O switching characteristics assume:

1. output pins
  - have  $C_L=30\text{pF}$  loads,
  - are configured for fast slew rate ( $\text{PORTx\_PCRn[SRE]}=0$ ), and
  - are configured for high drive strength ( $\text{PORTx\_PCRn[DSE]}=1$ )
2. input pins
  - have their passive filter disabled ( $\text{PORTx\_PCRn[PFE]}=0$ )

### 5.2 Nonswitching electrical specifications

#### 5.2.1 Voltage and current operating requirements

**Table 1. Voltage and current operating requirements**

Symbol	Description	Min.	Max.	Unit	Notes
$V_{DD}$	Supply voltage	1.71	3.6	V	
$V_{DDA}$	Analog supply voltage	1.71	3.6	V	
$V_{DD} - V_{DDA}$	$V_{DD}$ -to- $V_{DDA}$ differential voltage	-0.1	0.1	V	
$V_{SS} - V_{SSA}$	$V_{SS}$ -to- $V_{SSA}$ differential voltage	-0.1	0.1	V	

*Table continues on the next page...*

**Table 1. Voltage and current operating requirements (continued)**

Symbol	Description	Min.	Max.	Unit	Notes
V <sub>BAT</sub>	RTC battery supply voltage	1.71	3.6	V	
V <sub>IH</sub>	Input high voltage (digital pins except Tamper pins ) <ul style="list-style-type: none"> <li>• 2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V</li> <li>• 1.7 V ≤ V<sub>DD</sub> ≤ 2.7 V</li> </ul>	0.7 × V <sub>DD</sub> 0.75 × V <sub>DD</sub>	— —	V V	
V <sub>IL</sub>	Input low voltage (digital pins except Tamper pins ) <ul style="list-style-type: none"> <li>• 2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V</li> <li>• 1.7 V ≤ V<sub>DD</sub> ≤ 2.7 V</li> </ul>	— —	0.35 × V <sub>DD</sub> 0.3 × V <sub>DD</sub>	V V	
V <sub>HYS</sub>	Input hysteresis (digital pins except Tamper pins )	0.06 × V <sub>DD</sub>	—	V	
I <sub>CDIO</sub>	Digital pin (except Tamper pins) negative DC injection current — single pin <ul style="list-style-type: none"> <li>• V<sub>IN</sub> &lt; V<sub>SS</sub>-0.3V</li> </ul>	-5	—	mA	
I <sub>CAIO</sub>	Analog <sup>2</sup> , EXTAL0/XTAL0, and EXTAL1/XTAL1 pin DC injection current — single pin <ul style="list-style-type: none"> <li>• V<sub>IN</sub> &lt; V<sub>SS</sub>-0.3V (Negative current injection)</li> <li>• V<sub>IN</sub> &gt; V<sub>DD</sub>+0.3V (Positive current injection)</li> </ul>	-5 —	— +5	mA	
I <sub>Ccont</sub>	Contiguous pin DC injection current —regional limit, includes sum of negative injection currents or sum of positive injection currents of 16 contiguous pins <ul style="list-style-type: none"> <li>• Negative current injection</li> <li>• Positive current injection</li> </ul>	-25 —	— +25	mA	
V <sub>ODPU</sub>	Open drain pullup voltage level	V <sub>DD</sub>	V <sub>DD</sub>	V	4
V <sub>RAM</sub>	V <sub>DD</sub> voltage required to retain RAM	1.2	—	V	
V <sub>RFVBAT</sub>	V <sub>BAT</sub> voltage required to retain the VBAT register file	V <sub>POR_VBAT</sub>	—	V	

1. Analog pins are defined as pins that do not have an associated general purpose I/O port function. Additionally, EXTAL and XTAL are analog pins.
2. Open drain outputs must be pulled to VDD.

## 5.2.2 LVD and POR operating requirements

**Table 2. LVD and POR operating requirements**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V <sub>POR</sub>	Falling VDD POR detect voltage	0.8	1.1	1.5	V	
V <sub>LVDH</sub>	Falling low-voltage detect threshold — high range (LV <sub>DV</sub> =01)	2.48	2.56	2.64	V	
V <sub>LVW1H</sub>	Low-voltage warning thresholds — high range <ul style="list-style-type: none"> <li>• Level 1 falling (LV<sub>WV</sub>=00)</li> <li>• Level 2 falling (LV<sub>WV</sub>=01)</li> </ul>	2.62	2.70	2.78	V	
V <sub>LVW2H</sub>		2.72	2.80	2.88	V	
V <sub>LVW3H</sub>		2.82	2.90	2.98	V	

Table continues on the next page...

**Table 2. LVD and POR operating requirements (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V <sub>LW4H</sub>	<ul style="list-style-type: none"> <li>Level 3 falling (LVWV=10)</li> <li>Level 4 falling (LVWV=11)</li> </ul>	2.92	3.00	3.08	V	
V <sub>HYSH</sub>	Low-voltage inhibit reset/recover hysteresis — high range	—	±80	—	mV	
V <sub>LVDL</sub>	Falling low-voltage detect threshold — low range (LVDV=00)	1.54	1.60	1.66	V	
V <sub>LW1L</sub>	Low-voltage warning thresholds — low range	1.74	1.80	1.86	V	1
V <sub>LW2L</sub>	<ul style="list-style-type: none"> <li>Level 1 falling (LVWV=00)</li> </ul>	1.84	1.90	1.96	V	
V <sub>LW3L</sub>	<ul style="list-style-type: none"> <li>Level 2 falling (LVWV=01)</li> </ul>	1.94	2.00	2.06	V	
V <sub>LW4L</sub>	<ul style="list-style-type: none"> <li>Level 3 falling (LVWV=10)</li> <li>Level 4 falling (LVWV=11)</li> </ul>	2.04	2.10	2.16	V	
V <sub>HYSL</sub>	Low-voltage inhibit reset/recover hysteresis — low range	—	±60	—	mV	
V <sub>BG</sub>	Bandgap voltage reference	0.97	1.00	1.03	V	
t <sub>LPO</sub>	Internal low power oscillator period factory trimmed	900	1000	1100	µs	

1. Rising thresholds are falling threshold + hysteresis voltage

**Table 3. VBAT power operating requirements**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V <sub>POR_VBAT</sub>	Falling VBAT supply POR detect voltage	0.8	1.1	1.5	V	

### 5.2.3 Voltage and current operating behaviors

**Table 4. Voltage and current operating behaviors**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V <sub>OH</sub>	Output high voltage — high drive strength			—		
	<ul style="list-style-type: none"> <li>2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, I<sub>OH</sub> = -9mA</li> </ul>	V <sub>DD</sub> - 0.5	—	—	V	
	<ul style="list-style-type: none"> <li>1.71 V ≤ V<sub>DD</sub> ≤ 2.7 V, I<sub>OH</sub> = -3mA</li> </ul>	V <sub>DD</sub> - 0.5	—	—	V	
	Output high voltage — low drive strength			—		
	<ul style="list-style-type: none"> <li>2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, I<sub>OH</sub> = -2mA</li> </ul>	V <sub>DD</sub> - 0.5	—	—	V	
	<ul style="list-style-type: none"> <li>1.71 V ≤ V<sub>DD</sub> ≤ 2.7 V, I<sub>OH</sub> = -0.6mA</li> </ul>	V <sub>DD</sub> - 0.5	—	—	V	
I <sub>OHT</sub>	Output high current total for all ports	—	—	100	mA	
I <sub>OHT_io60</sub>	Output high current total for fast digital ports	—	—	100	mA	
V <sub>OH_Tamper</sub>	Output high voltage — high drive strength	V <sub>BAT</sub> - 0.5	—	—	V	
		V <sub>BAT</sub> - 0.5	—	—	V	

Table continues on the next page...

**Table 4. Voltage and current operating behaviors (continued)**

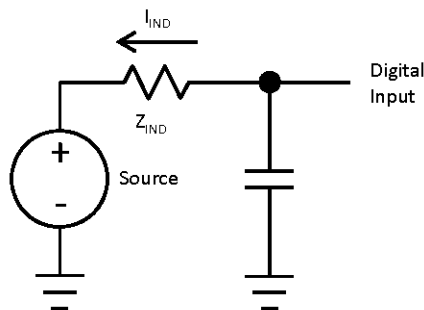
Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	<ul style="list-style-type: none"> <li>• <math>2.7\text{ V} \leq V_{\text{BAT}} \leq 3.6\text{ V}</math>, <math>I_{\text{OH}} = -10\text{mA}</math></li> <li>• <math>1.71\text{ V} \leq V_{\text{BAT}} \leq 2.7\text{ V}</math>, <math>I_{\text{OH}} = -3\text{mA}</math></li> </ul>					
	Output high voltage — low drive strength	$V_{\text{BAT}} - 0.5$	—	—	V	
	<ul style="list-style-type: none"> <li>• <math>2.7\text{ V} \leq V_{\text{BAT}} \leq 3.6\text{ V}</math>, <math>I_{\text{OH}} = -2\text{mA}</math></li> <li>• <math>1.71\text{ V} \leq V_{\text{BAT}} \leq 2.7\text{ V}</math>, <math>I_{\text{OH}} = -0.6\text{mA}</math></li> </ul>	$V_{\text{BAT}} - 0.5$	—	—	V	
$I_{\text{OH\_Tamper}}$	Output high current total for Tamper pins	—	—	100	mA	
$V_{\text{OL}}$	Output low voltage — high drive strength					
	<ul style="list-style-type: none"> <li>• <math>2.7\text{ V} \leq V_{\text{DD}} \leq 3.6\text{ V}</math>, <math>I_{\text{OL}} = 10\text{ mA}</math></li> <li>• <math>1.71\text{ V} \leq V_{\text{DD}} \leq 2.7\text{ V}</math>, <math>I_{\text{OL}} = 5\text{ mA}</math></li> </ul>	—	—	0.5	V	
	<ul style="list-style-type: none"> <li>• <math>1.71\text{ V} \leq V_{\text{DD}} \leq 2.7\text{ V}</math>, <math>I_{\text{OL}} = 5\text{ mA}</math></li> </ul>	—	—	0.5	V	
	Output low voltage — low drive strength					
	<ul style="list-style-type: none"> <li>• <math>2.7\text{ V} \leq V_{\text{DD}} \leq 3.6\text{ V}</math>, <math>I_{\text{OL}} = 2\text{ mA}</math></li> <li>• <math>1.71\text{ V} \leq V_{\text{DD}} \leq 2.7\text{ V}</math>, <math>I_{\text{OL}} = 1\text{ mA}</math></li> </ul>	—	—	0.5	V	
	<ul style="list-style-type: none"> <li>• <math>1.71\text{ V} \leq V_{\text{DD}} \leq 2.7\text{ V}</math>, <math>I_{\text{OL}} = 1\text{ mA}</math></li> </ul>	—	—	0.5	V	
$I_{\text{OLT}}$	Output low current total for all ports	—	—	100	mA	
$I_{\text{OLT\_io60}}$	Output low current total for fast digital ports	—	—	100	mA	
$V_{\text{OL\_Tamper}}$	Output low voltage — high drive strength					
	<ul style="list-style-type: none"> <li>• <math>2.7\text{ V} \leq V_{\text{BAT}} \leq 3.6\text{ V}</math>, <math>I_{\text{OL}} = 10\text{mA}</math></li> <li>• <math>1.71\text{ V} \leq V_{\text{BAT}} \leq 2.7\text{ V}</math>, <math>I_{\text{OL}} = 3\text{mA}</math></li> </ul>	—	—	0.5	V	
	<ul style="list-style-type: none"> <li>• <math>1.71\text{ V} \leq V_{\text{BAT}} \leq 2.7\text{ V}</math>, <math>I_{\text{OL}} = 3\text{mA}</math></li> </ul>	—	—	0.5	V	
	Output low voltage — low drive strength					
	<ul style="list-style-type: none"> <li>• <math>2.7\text{ V} \leq V_{\text{BAT}} \leq 3.6\text{ V}</math>, <math>I_{\text{OL}} = 2\text{mA}</math></li> <li>• <math>1.71\text{ V} \leq V_{\text{BAT}} \leq 2.7\text{ V}</math>, <math>I_{\text{OL}} = 0.6\text{mA}</math></li> </ul>	—	—	0.5	V	
	<ul style="list-style-type: none"> <li>• <math>1.71\text{ V} \leq V_{\text{BAT}} \leq 2.7\text{ V}</math>, <math>I_{\text{OL}} = 0.6\text{mA}</math></li> </ul>	—	—	0.5	V	
$I_{\text{OL\_Tamper}}$	Output low current total for Tamper pins	—	—	100	mA	
$I_{\text{INA}}$	Input leakage current, analog pins and digital pins configured as analog inputs					1,
	<ul style="list-style-type: none"> <li>• <math>V_{\text{SS}} \leq V_{\text{IN}} \leq V_{\text{DD}}</math> <ul style="list-style-type: none"> <li>• All pins except EXTAL32, XTAL32, EXTAL, XTAL</li> <li>• EXTAL (PTA18) and XTAL (PTA19)</li> <li>• EXTAL32, XTAL32</li> </ul> </li> </ul>	—	0.002	0.5	$\mu\text{A}$	
		—	0.004	1.5	$\mu\text{A}$	
		—	0.075	10	$\mu\text{A}$	
$I_{\text{IND}}$	Input leakage current, digital pins					2,
	<ul style="list-style-type: none"> <li>• <math>V_{\text{SS}} \leq V_{\text{IN}} \leq V_{\text{IL}}</math> <ul style="list-style-type: none"> <li>• All digital pins</li> </ul> </li> <li>• <math>V_{\text{IN}} = V_{\text{DD}}</math> <ul style="list-style-type: none"> <li>• All digital pins except PTD7</li> <li>• PTD7</li> </ul> </li> </ul>	—	0.002	0.5	$\mu\text{A}$	
		—	0.002	0.5	$\mu\text{A}$	
		—	0.004	1	$\mu\text{A}$	
$I_{\text{IND}}$	Input leakage current, digital pins					2, 3,

Table continues on the next page...

**Table 4. Voltage and current operating behaviors (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	<ul style="list-style-type: none"> <li><math>V_{IL} &lt; V_{IN} &lt; V_{DD}</math></li> <li><math>V_{DD} = 3.6\text{ V}</math></li> <li><math>V_{DD} = 3.0\text{ V}</math></li> <li><math>V_{DD} = 2.5\text{ V}</math></li> <li><math>V_{DD} = 1.7\text{ V}</math></li> </ul>	—	18	26	$\mu\text{A}$	
$I_{IND}$	Input leakage current, digital pins <ul style="list-style-type: none"> <li><math>V_{DD} &lt; V_{IN} &lt; 5.5\text{ V}</math></li> </ul>	—	1	50	$\mu\text{A}$	2, 3
$Z_{IND}$	Input impedance examples, digital pins <ul style="list-style-type: none"> <li><math>V_{DD} = 3.6\text{ V}</math></li> <li><math>V_{DD} = 3.0\text{ V}</math></li> <li><math>V_{DD} = 2.5\text{ V}</math></li> <li><math>V_{DD} = 1.7\text{ V}</math></li> </ul>	—	—	48	$\text{k}\Omega$	2, 5
$I_{IN\_Tamper}$	Input leakage current (per Tamper pin) for full temperature range	—	—	1	$\mu\text{A}$	
$I_{IN\_Tamper}$	Input leakage current (per Tamper pin) at 25°C	—	—	0.025	$\mu\text{A}$	
$R_{PU}$	Internal pullup resistors (except Tamper pins)	20	—	50	$\text{k}\Omega$	6
$R_{PD}$	Internal pulldown resistors (except Tamper pins)	20	—	50	$\text{k}\Omega$	7

1. Analog pins are defined as pins that do not have an associated general purpose I/O port function.
2. Digital pins have an associated GPIO port function and have 5V tolerant inputs, except EXTAL and XTAL.
3. Internal pull-up/pull-down resistors disabled.
4. Examples calculated using  $V_{IL}$  relation,  $V_{DD}$ , and max  $I_{IND}$ :  $Z_{IND} = V_{IL} / I_{IND}$ . This is the impedance needed to pull a high signal to a level below  $V_{IL}$  due to leakage when  $V_{IL} < V_{IN} < V_{DD}$ . These examples assume signal source low = 0 V. See [Figure 1](#).
5. Measured at  $V_{DD}$  supply voltage =  $V_{DD}$  min and  $V_{input} = V_{SS}$
6. Measured at  $V_{DD}$  supply voltage =  $V_{DD}$  min and  $V_{input} = V_{DD}$



**Figure 2. 5 V Tolerant Input  $I_{IND}$  Parameter**



## 5.2.4 Power mode transition operating behaviors

All specifications except  $t_{POR}$ , and  $VLLSx \rightarrow RUN$  recovery times in the following table assume this clock configuration:

- CPU and system clocks = 100 MHz
- Bus clock = 50 MHz
- FlexBus clock = 50 MHz
- Flash clock = 25 MHz
- MCG mode: FEI

**Table 5. Power mode transition operating behaviors**

Symbol	Description	Min.	Max.	Unit	Notes
$t_{POR}$	After a POR event, amount of time from the point $V_{DD}$ reaches 1.71 V to execution of the first instruction across the operating temperature range of the chip. <ul style="list-style-type: none"> <li>• <math>V_{DD}</math> slew rate <math>\geq 5.7</math> kV/s</li> <li>• <math>V_{DD}</math> slew rate <math>&lt; 5.7</math> kV/s</li> </ul>	—	300 1.7 V / ( $V_{DD}$ slew rate)	$\mu$ s	1
	• $VLLS1 \rightarrow RUN$	—	160	$\mu$ s	
	• $VLLS2 \rightarrow RUN$	—	114	$\mu$ s	
	• $VLLS3 \rightarrow RUN$	—	114	$\mu$ s	
	• $LLS \rightarrow RUN$	—	5.0	$\mu$ s	
	• $VLPS \rightarrow RUN$	—	5	$\mu$ s	
	• $STOP \rightarrow RUN$	—	4.8	$\mu$ s	

1. Normal boot (FTFE\_FOFT[LPBOOT]=1)

## 5.2.5 Power consumption operating behaviors

**Table 6. Power consumption operating behaviors**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$I_{DDA}$	Analog supply current	—	—	See note	mA	1
$I_{DD\_RUN}$	Run mode current — all peripheral clocks disabled, code executing from flash <ul style="list-style-type: none"> <li>• @ 1.8V</li> <li>• @ 3.0V</li> </ul>	—	51.1 51.7	160 162	mA mA	
$I_{DD\_RUN}$	Run mode current — all peripheral clocks enabled, code executing from flash					

Table continues on the next page...

**Table 6. Power consumption operating behaviors (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	<ul style="list-style-type: none"> <li>@ 1.8V</li> <li>@ 3.0V</li> </ul>	—	75.2	175	mA	
		—	75.9	177	mA	
I <sub>DD_WAIT</sub>	Wait mode high frequency current at 3.0 V — all peripheral clocks disabled	—	35.7	60	mA	2
I <sub>DD_WAIT</sub>	Wait mode reduced frequency current at 3.0 V — all peripheral clocks disabled	—	19.6	44	mA	
I <sub>DD_STOP</sub>	Stop mode current at 3.0 V <ul style="list-style-type: none"> <li>@ -40 to 25°C</li> <li>@ 70°C</li> <li>@ 105°C</li> </ul>	—	1.3	3.8	mA	
		—	3.0	27	mA	
		—	7.5	42	mA	
I <sub>DD_VLPR</sub>	Very-low-power run mode current at 3.0 V — all peripheral clocks disabled	—	1.4	32	mA	5
I <sub>DD_VLPR</sub>	Very-low-power run mode current at 3.0 V — all peripheral clocks enabled	—	2.2	38	mA	
I <sub>DD_VLPW</sub>	Very-low-power wait mode current at 3.0 V	—	0.926	22	mA	
I <sub>DD_VLPS</sub>	Very-low-power stop mode current at 3.0 V <ul style="list-style-type: none"> <li>@ -40 to 25°C</li> <li>@ 70°C</li> <li>@ 105°C</li> </ul>	—	0.25	1.3	mA	
		—	0.85	7.6	mA	
		—	2.4	12.54	mA	
I <sub>DD_LLS</sub>	Low leakage stop mode current at 3.0 V <ul style="list-style-type: none"> <li>@ -40 to 25°C</li> <li>@ 70°C</li> <li>@ 105°C</li> </ul>	—	0.25	1.3	mA	
		—	0.85	7.6	mA	
		—	2.4	12.54	mA	
I <sub>DD_VLLS3</sub>	Very low-leakage stop mode 3 current at 3.0 V <ul style="list-style-type: none"> <li>@ -40 to 25°C</li> <li>@ 70°C</li> <li>@ 105°C</li> </ul>	—	5.6	20	μA	6
		—	30.1	137	μA	
		—	120.8	246	μA	
I <sub>DD_VLLS2</sub>	Very low-leakage stop mode 2 current at 3.0 V <ul style="list-style-type: none"> <li>@ -40 to 25°C</li> <li>@ 70°C</li> <li>@ 105°C</li> </ul>	—	3.2	14	μA	
		—	11.8	40	μA	
		—	51.2	60	μA	
I <sub>DD_VLLS1</sub>	Very low-leakage stop mode 1 current at 3.0 V <ul style="list-style-type: none"> <li>@ -40 to 25°C</li> <li>@ 70°C</li> <li>@ 105°C</li> </ul>	—	2.8	12	μA	
		—	8.7	29	μA	
		—	39.3	43	μA	
I <sub>DD_VBAT</sub>	Average current when CPU is not accessing RTC registers at 3.0 V					7

**Table 6. Power consumption operating behaviors**

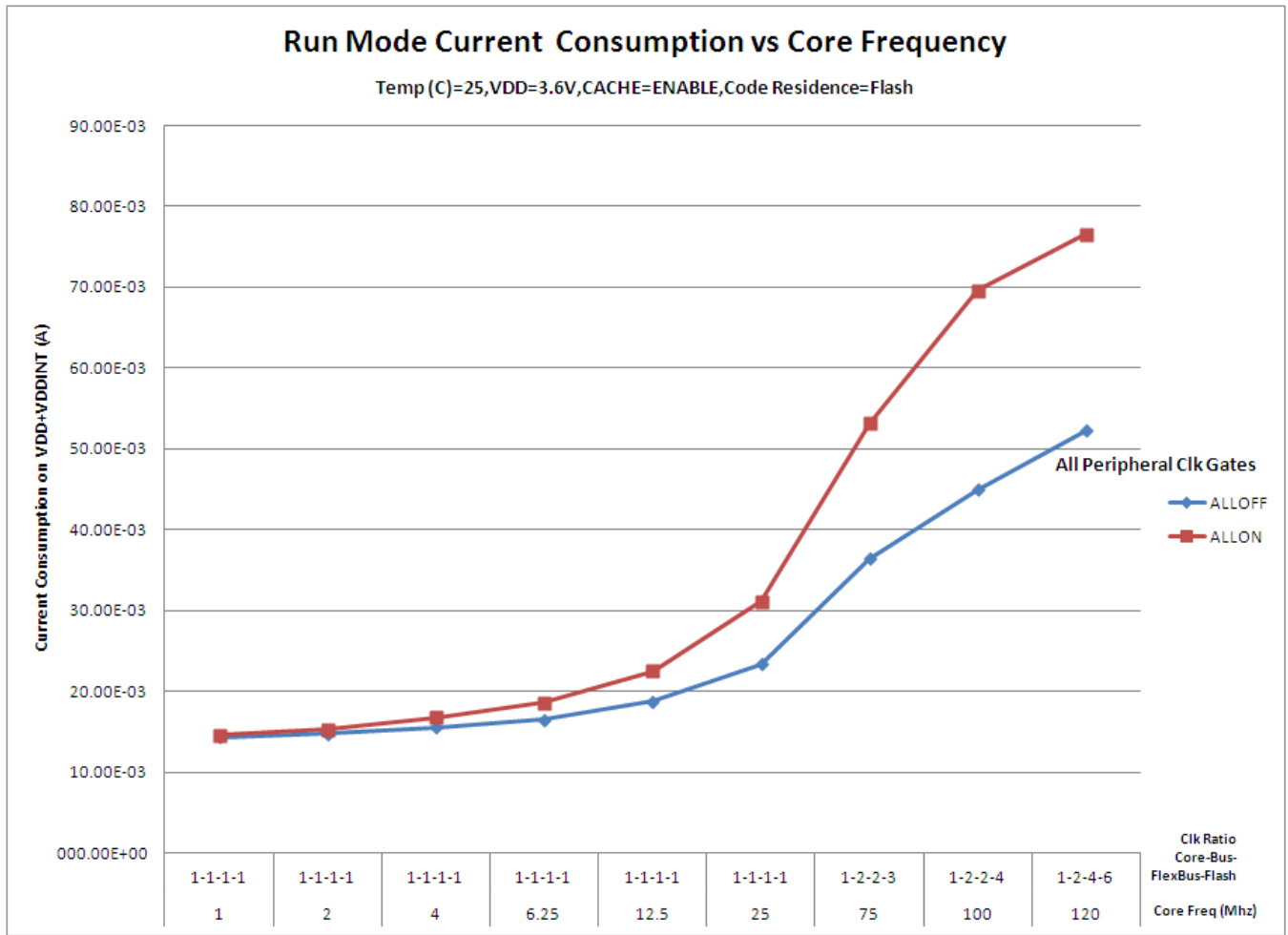
Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	• @ -40 to 25°C	—	0.91	1.1	μA	
	• @ 70°C	—	1.5	1.85	μA	
	• @ 105°C	—	4.3	4.3	μA	

1. The analog supply current is the sum of the active or disabled current for each of the analog modules on the device. See each module's specification for its supply current.
2. 120 MHz core and system clock, 60 MHz bus, 30 MHz FlexBus clock, and 20 MHz flash clock. MCG configured for PEE mode. All peripheral clocks disabled.
3. 4 MHz core, system, 2 MHz FlexBus, and 2 MHz bus clock and 0.5 MHz flash clock. MCG configured for BLPE mode. All peripheral clocks disabled.
4. 4 MHz core, system, 2 MHz FlexBus, and 2 MHz bus clock and 0.5 MHz flash clock. MCG configured for BLPE mode. All peripheral clocks disabled.
5. 4 MHz core, system, 2 MHz FlexBus, and 2 MHz bus clock and 0.5 MHz flash clock. MCG configured for BLPE mode. All peripheral clocks disabled.
6. Data reflects devices with 128 KB of RAM. For devices with 64 KB of RAM, power consumption is reduced by 2 μA.
7. Includes 32kHz oscillator current and RTC operation.

### 5.2.5.1 Diagram: Typical IDD\_RUN operating behavior

The following data was measured under these conditions:

- MCG in FBE mode for 50 MHz and lower frequencies. MCG in FEE mode at greater than 50 MHz frequencies. MCG in PEE mode is greater than 100 MHz frequencies.
- USB regulator disabled
- No GPIOs toggled
- Code execution from flash with cache enabled
- For the ALLOFF curve, all peripheral clocks are disabled except FTFE



**Figure 3. Run mode supply current vs. core frequency**

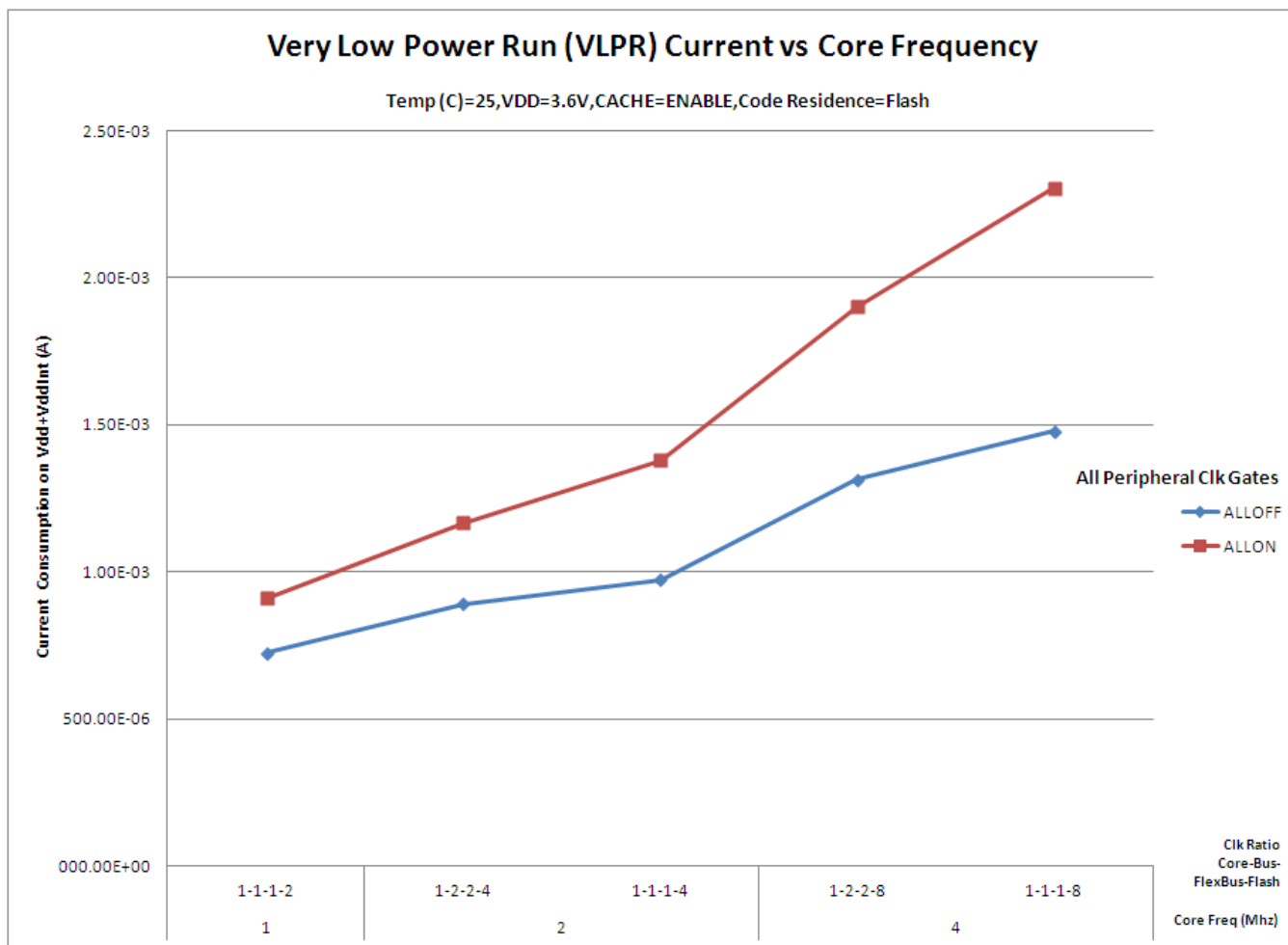


Figure 4. VLPR mode supply current vs. core frequency

## 5.2.6 EMC radiated emissions operating behaviors

Table 7. EMC radiated emissions operating behaviors for 256MAPBGA

Symbol	Description	Frequency band (MHz)	Typ.	Unit	Notes
V <sub>RE1</sub>	Radiated emissions voltage, band 1	0.15–50	21	dBμV	, ,
V <sub>RE2</sub>	Radiated emissions voltage, band 2	50–150	24	dBμV	
V <sub>RE3</sub>	Radiated emissions voltage, band 3	150–500	29	dBμV	
V <sub>RE4</sub>	Radiated emissions voltage, band 4	500–1000	28	dBμV	

## 5.2.7 Designing with radiated emissions in mind

To find application notes that provide guidance on designing your system to minimize interference from radiated emissions:

## General

1. Go to [www.freescale.com](http://www.freescale.com).
2. Perform a keyword search for “EMC design.”

## 5.2.8 Capacitance attributes

Table 8. Capacitance attributes

Symbol	Description	Min.	Max.	Unit
C <sub>IN_A</sub>	Input capacitance: analog pins	—	7	pF
C <sub>IN_D</sub>	Input capacitance: digital pins	—	7	pF
C <sub>IN_D_io60</sub>	Input capacitance: fast digital pins	—	9	pF

## 5.3 Switching specifications

### 5.3.1 Device clock specifications

Table 9. Device clock specifications

Symbol	Description	Min.	Max.	Unit	Notes
Normal run mode					
f <sub>SYS</sub>	System and core clock	—	120	MHz	
f <sub>SYS_USBF5</sub>	System and core clock when Full Speed USB in operation	20	—	MHz	
f <sub>SYS_USBH5</sub>	System and core clock when High Speed USB in operation	60	—	MHz	
f <sub>ENET</sub>	System and core clock when ethernet in operation <ul style="list-style-type: none"><li>• 10 Mbps</li><li>• 100 Mbps</li></ul>	5 50	— —	MHz	
f <sub>BUS</sub>	Bus clock	—	60	MHz	
FB_CLK	FlexBus clock	—	50	MHz	
f <sub>FLASH</sub>	Flash clock	—	25	MHz	
f <sub>LPTMR</sub>	LPTMR clock	—	25	MHz	
VLPR mode <sup>1</sup>					
f <sub>SYS</sub>	System and core clock	—	4	MHz	
f <sub>BUS</sub>	Bus clock	—	4	MHz	
FB_CLK	FlexBus clock	—	4	MHz	
f <sub>FLASH</sub>	Flash clock	—	0.5	MHz	
f <sub>LPTMR</sub>	LPTMR clock	—	4	MHz	

1. The frequency limitations in VLPR mode here override any frequency specification listed in the timing specification for any other module.

### 5.3.2 General switching specifications

These general purpose specifications apply to all pins configured for:

- GPIO signaling
- Other peripheral module signaling not explicitly stated elsewhere

**Table 10. General switching specifications**

Symbol	Description	Min.	Max.	Unit	Notes
	GPIO pin interrupt pulse width (digital glitch filter disabled) — Synchronous path	1.5	—	Bus clock cycles	1, 2
	GPIO pin interrupt pulse width (digital glitch filter disabled, analog filter enabled) — Asynchronous path	100	—	ns	
	GPIO pin interrupt pulse width (digital glitch filter disabled, analog filter disabled) — Asynchronous path	16	—	ns	3
	External reset pulse width (digital glitch filter disabled)	100	—	ns	3
	Mode select ( $\overline{\text{EZP\_CS}}$ ) hold time after reset deassertion	2	—	Bus clock cycles	
	Port rise and fall time (high drive strength) <ul style="list-style-type: none"> <li>• Slew disabled <ul style="list-style-type: none"> <li>• <math>1.71 \leq V_{DD} \leq 2.7V</math></li> <li>• <math>2.7 \leq V_{DD} \leq 3.6V</math></li> </ul> </li> <li>• Slew enabled <ul style="list-style-type: none"> <li>• <math>1.71 \leq V_{DD} \leq 2.7V</math></li> <li>• <math>2.7 \leq V_{DD} \leq 3.6V</math></li> </ul> </li> </ul>	—	14	ns	4
	Port rise and fall time (low drive strength) <ul style="list-style-type: none"> <li>• Slew disabled <ul style="list-style-type: none"> <li>• <math>1.71 \leq V_{DD} \leq 2.7V</math></li> <li>• <math>2.7 \leq V_{DD} \leq 3.6V</math></li> </ul> </li> <li>• Slew enabled <ul style="list-style-type: none"> <li>• <math>1.71 \leq V_{DD} \leq 2.7V</math></li> <li>• <math>2.7 \leq V_{DD} \leq 3.6V</math></li> </ul> </li> </ul>	—	14	ns	5
$t_{i050}$	Port rise and fall time (high drive strength) <ul style="list-style-type: none"> <li>• Slew disabled <ul style="list-style-type: none"> <li>• <math>1.71 \leq V_{DD} \leq 2.7V</math></li> <li>• <math>2.7 \leq V_{DD} \leq 3.6V</math></li> </ul> </li> <li>• Slew enabled <ul style="list-style-type: none"> <li>• <math>1.71 \leq V_{DD} \leq 2.7V</math></li> <li>• <math>2.7 \leq V_{DD} \leq 3.6V</math></li> </ul> </li> </ul>	—	7	ns	—
		—	3	ns	—
		—	28	ns	—
		—	14	ns	—
$t_{i050}$	Port rise and fall time (low drive strength) <ul style="list-style-type: none"> <li>• Slew disabled</li> </ul>				

Table continues on the next page...

**Table 10. General switching specifications (continued)**

Symbol	Description	Min.	Max.	Unit	Notes
	<ul style="list-style-type: none"> <li>• <math>1.71 \leq V_{DD} \leq 2.7V</math></li> <li>• <math>2.7 \leq V_{DD} \leq 3.6V</math></li> <li>• Slew enabled</li> <li>• <math>1.71 \leq V_{DD} \leq 2.7V</math></li> <li>• <math>2.7 \leq V_{DD} \leq 3.6V</math></li> </ul>	—	18	ns	—
		—	9	ns	—
		—	48	ns	—
		—	24	ns	—
$t_{io60}$	Port rise and fall time (high drive strength) <ul style="list-style-type: none"> <li>• Slew disabled <ul style="list-style-type: none"> <li>• <math>1.71 \leq V_{DD} \leq 2.7V</math></li> <li>• <math>2.7 \leq V_{DD} \leq 3.6V</math></li> </ul> </li> <li>• Slew enabled <ul style="list-style-type: none"> <li>• <math>1.71 \leq V_{DD} \leq 2.7V</math></li> <li>• <math>2.7 \leq V_{DD} \leq 3.6V</math></li> </ul> </li> </ul>	—	6	ns	6
		—	3	ns	—
		—	28	ns	—
		—	14	ns	—
$t_{io60}$	Port rise and fall time (low drive strength) <ul style="list-style-type: none"> <li>• Slew disabled <ul style="list-style-type: none"> <li>• <math>1.71 \leq V_{DD} \leq 2.7V</math></li> <li>• <math>2.7 \leq V_{DD} \leq 3.6V</math></li> </ul> </li> <li>• Slew enabled <ul style="list-style-type: none"> <li>• <math>1.71 \leq V_{DD} \leq 2.7V</math></li> <li>• <math>2.7 \leq V_{DD} \leq 3.6V</math></li> </ul> </li> </ul>	—	18	ns	7
		—	6	ns	—
		—	48	ns	—
		—	24	ns	—

1. This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In Stop, VLPS, LLS, and VLLSx modes, the synchronizer is bypassed so shorter pulses can be recognized in that case.
2. The greater synchronous and asynchronous timing must be met.
3. This is the minimum pulse width that is guaranteed to be recognized as a pin interrupt request in Stop, VLPS, LLS, and VLLSx modes.
4. 75 pF load
5. 15 pF load
6. 25 pF load
7. 15 pF load

## 5.4 Thermal specifications

### 5.4.1 Thermal operating requirements

**Table 11. Thermal operating requirements**

Symbol	Description	Min.	Max.	Unit
$T_J$	Die junction temperature	-40	125	°C
$T_A$	Ambient temperature	-40	105	°C



## 5.4.2 Thermal attributes

Board type	Symbol	Description	144 MAPBGA	Unit	Notes
Single-layer (1s)	$R_{\theta JA}$	Thermal resistance, junction to ambient (natural convection)	50	$^{\circ}\text{C}/\text{W}$	
Four-layer (2s2p)	$R_{\theta JA}$	Thermal resistance, junction to ambient (natural convection)	30	$^{\circ}\text{C}/\text{W}$	1
Single-layer (1s)	$R_{\theta JMA}$	Thermal resistance, junction to ambient (200 ft./min. air speed)	41	$^{\circ}\text{C}/\text{W}$	1
Four-layer (2s2p)	$R_{\theta JMA}$	Thermal resistance, junction to ambient (200 ft./min. air speed)	27	$^{\circ}\text{C}/\text{W}$	1
—	$R_{\theta JB}$	Thermal resistance, junction to board	17	$^{\circ}\text{C}/\text{W}$	
—	$R_{\theta JC}$	Thermal resistance, junction to case	10	$^{\circ}\text{C}/\text{W}$	
—	$\Psi_{JT}$	Thermal characterization parameter, junction to package top outside center (natural convection)	2	$^{\circ}\text{C}/\text{W}$	

## 5.5 Power sequencing

Voltage supplies must be sequenced in the proper order to avoid damaging internal diodes. There is no limit on how long after one supply powers up before the next supply must power up. Note that  $V_{DD}$  and  $V_{DD\_INT}$  can use the same power source.

The power-up sequence is:

1.  $V_{DD}$
2.  $V_{DD\_INT}$
3.  $V_{DDA}$
4.  $V_{DD\_DDR}$

The power-down sequence is the reverse:

1.  $V_{DD\_DDR}$
2.  $V_{DDA}$
3.  $V_{DD\_INT}$
4.  $V_{DD}$

## 6 Peripheral operating requirements and behaviors

### 6.1 Core modules

#### 6.1.1 Debug trace timing specifications

Table 12. Debug trace operating behaviors

Symbol	Description	Min.	Max.	Unit
$T_{cyc}$	Clock period	Frequency dependent		MHz
$T_{wl}$	Low pulse width	2	—	ns
$T_{wh}$	High pulse width	2	—	ns
$T_r$	Clock and data rise time	—	3	ns
$T_f$	Clock and data fall time	—	3	ns
$T_s$	Data setup	3	—	ns
$T_h$	Data hold	2	—	ns

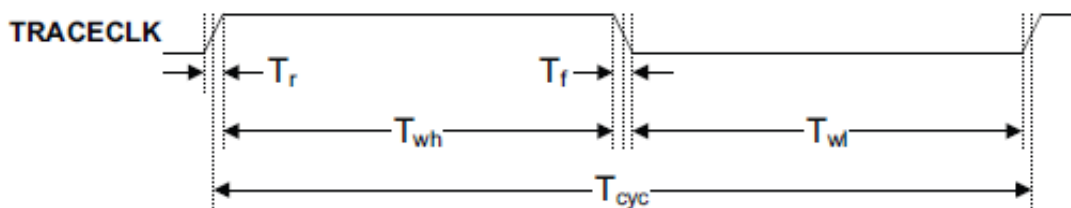


Figure 5. TRACE\_CLKOUT specifications

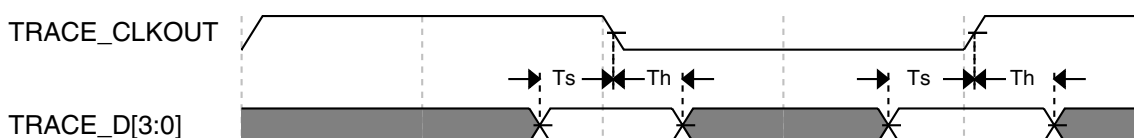


Figure 6. Trace data specifications

## 6.1.2 JTAG electricals

**Table 13. JTAG limited voltage range electricals**

Symbol	Description	Min.	Max.	Unit
	Operating voltage	2.7	3.6	V
J1	TCLK frequency of operation <ul style="list-style-type: none"> <li>Boundary Scan</li> <li>JTAG and CJTAG</li> <li>Serial Wire Debug</li> </ul>	0 0 0	10 25 50	MHz
J2	TCLK cycle period	1/J1	—	ns
J3	TCLK clock pulse width <ul style="list-style-type: none"> <li>Boundary Scan</li> <li>JTAG and CJTAG</li> <li>Serial Wire Debug</li> </ul>	50 20 10	— — —	ns ns ns
J4	TCLK rise and fall times	—	3	ns
J5	Boundary scan input data setup time to TCLK rise	20	—	ns
J6	Boundary scan input data hold time after TCLK rise	2.4	—	ns
J7	TCLK low to boundary scan output data valid	—	25	ns
J8	TCLK low to boundary scan output high-Z	—	25	ns
J9	TMS, TDI input data setup time to TCLK rise	8	—	ns
J10	TMS, TDI input data hold time after TCLK rise	1	—	ns
J11	TCLK low to TDO data valid	—	17	ns
J12	TCLK low to TDO high-Z	—	17	ns
J13	$\overline{\text{TRST}}$ assert time	100	—	ns
J14	$\overline{\text{TRST}}$ setup time (negation) to TCLK high	8	—	ns

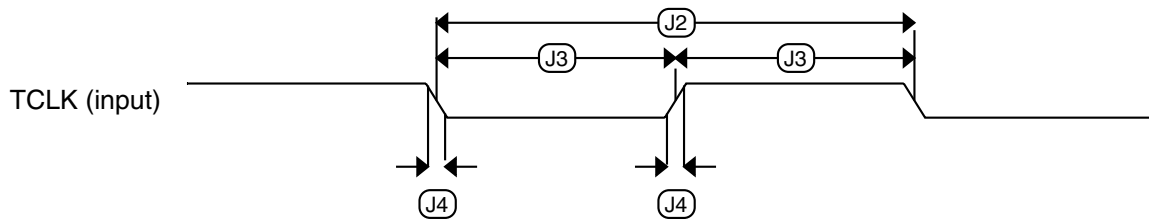
**Table 14. JTAG full voltage range electricals**

Symbol	Description	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
J1	TCLK frequency of operation <ul style="list-style-type: none"> <li>Boundary Scan</li> <li>JTAG and CJTAG</li> <li>Serial Wire Debug</li> </ul>	0 0 0	10 20 40	MHz
J2	TCLK cycle period	1/J1	—	ns
J3	TCLK clock pulse width <ul style="list-style-type: none"> <li>Boundary Scan</li> </ul>	50 25 12.5	— — —	ns ns ns

*Table continues on the next page...*

**Table 14. JTAG full voltage range electricals (continued)**

Symbol	Description	Min.	Max.	Unit
	<ul style="list-style-type: none"> <li>JTAG and CJTAG</li> <li>Serial Wire Debug</li> </ul>			
J4	TCLK rise and fall times	—	3	ns
J5	Boundary scan input data setup time to TCLK rise	20	—	ns
J6	Boundary scan input data hold time after TCLK rise	2.4	—	ns
J7	TCLK low to boundary scan output data valid	—	25	ns
J8	TCLK low to boundary scan output high-Z	—	25	ns
J9	TMS, TDI input data setup time to TCLK rise	8	—	ns
J10	TMS, TDI input data hold time after TCLK rise	1.4	—	ns
J11	TCLK low to TDO data valid	—	22.1	ns
J12	TCLK low to TDO high-Z	—	22.1	ns
J13	$\overline{\text{TRST}}$ assert time	100	—	ns
J14	$\overline{\text{TRST}}$ setup time (negation) to TCLK high	8	—	ns



**Figure 7. Test clock input timing**

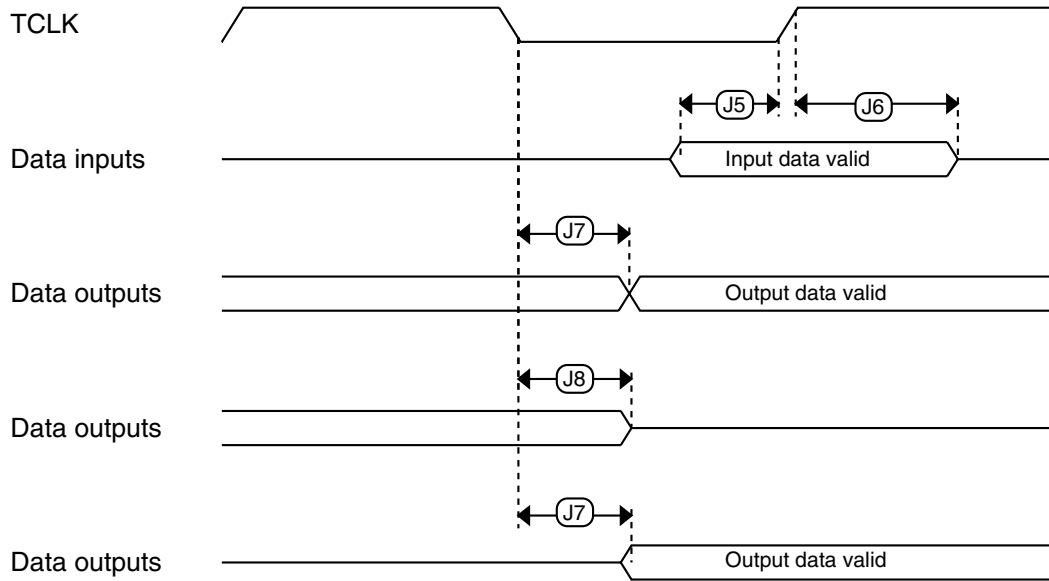


Figure 8. Boundary scan (JTAG) timing

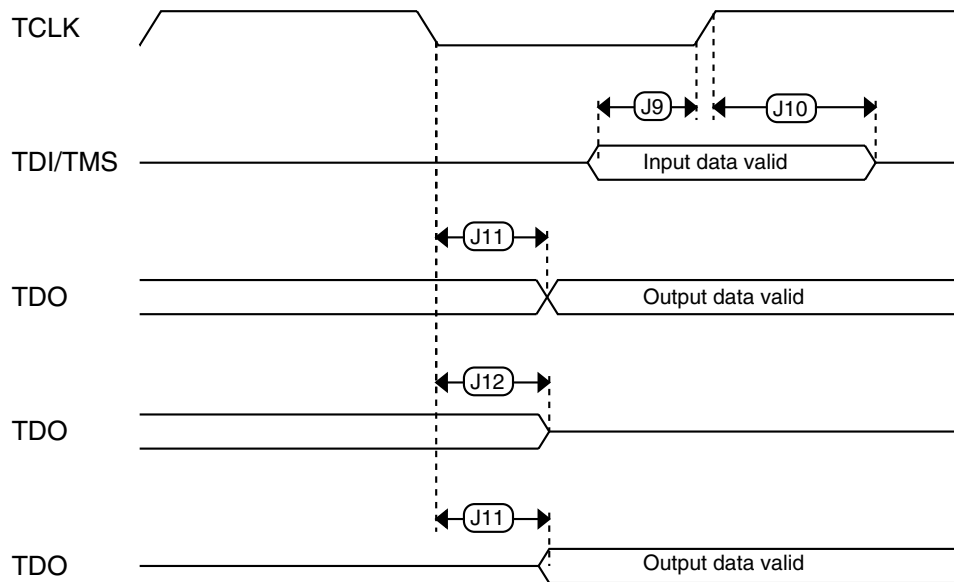


Figure 9. Test Access Port timing

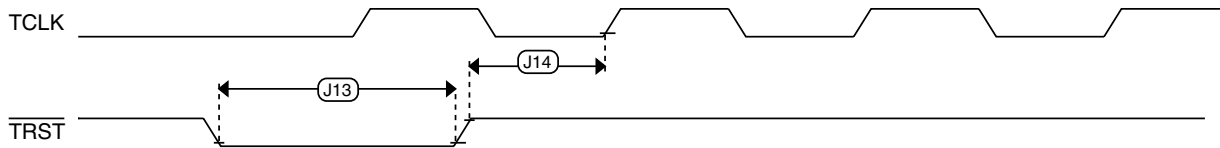


Figure 10. TRST timing

## 6.2 System modules

There are no specifications necessary for the device's system modules.

## 6.3 Clock modules

### 6.3.1 MCG specifications

Table 15. MCG specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$f_{ints\_ft}$	Internal reference frequency (slow clock) — factory trimmed at nominal VDD and 25 °C	—	32.768	—	kHz	
$f_{ints\_t}$	Internal reference frequency (slow clock) — user trimmed	31.25	—	39.0625	kHz	
$\Delta f_{dco\_res\_t}$	Resolution of trimmed average DCO output frequency at fixed voltage and temperature — using SCTRIM and SCFTRIM	—	$\pm 0.3$	$\pm 0.6$	% $f_{dco}$	
$\Delta f_{dco\_res\_t}$	Resolution of trimmed average DCO output frequency at fixed voltage and temperature — using SCTRIM only	—	$\pm 0.2$	$\pm 0.5$	% $f_{dco}$	1
$\Delta f_{dco\_t}$	Total deviation of trimmed average DCO output frequency over fixed voltage and temperature range of 0–70°C	—	$\pm 4.5$	—	% $f_{dco}$	1
$f_{intf\_ft}$	Internal reference frequency (fast clock) — factory trimmed at nominal VDD and 25°C	—	4	—	MHz	
$f_{intf\_t}$	Internal reference frequency (fast clock) — user trimmed at nominal VDD and 25 °C	3	—	5	MHz	
$f_{loc\_low}$	Loss of external clock minimum frequency — RANGE = 00	$(3/5) \times f_{ints\_t}$	—	—	kHz	
$f_{loc\_high}$	Loss of external clock minimum frequency — RANGE = 01, 10, or 11	$(16/5) \times f_{ints\_t}$	—	—	kHz	
FLL						
$f_{fll\_ref}$	FLL reference frequency range	31.25	—	39.0625	kHz	

Table continues on the next page...

**Table 15. MCG specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes	
$f_{dco}$	DCO output frequency range	Low range (DRS=00) $640 \times f_{fill\_ref}$	20	20.97	25	MHz	2, 3
		Mid range (DRS=01) $1280 \times f_{fill\_ref}$	40	41.94	50	MHz	
		Mid-high range (DRS=10) $1920 \times f_{fill\_ref}$	60	62.91	75	MHz	
		High range (DRS=11) $2560 \times f_{fill\_ref}$	80	83.89	100	MHz	
$f_{dco\_t\_DMX32}$	DCO output frequency	Low range (DRS=00) $732 \times f_{fill\_ref}$	—	23.99	—	MHz	4
		Mid range (DRS=01) $1464 \times f_{fill\_ref}$	—	47.97	—	MHz	
		Mid-high range (DRS=10) $2197 \times f_{fill\_ref}$	—	71.99	—	MHz	
		High range (DRS=11) $2929 \times f_{fill\_ref}$	—	95.98	—	MHz	
$J_{cyc\_fill}$	FLL period jitter	—	180	—	ps		
		• $f_{VCO} = 48$ MHz • $f_{VCO} = 98$ MHz	—	150	—		
$t_{fill\_acquire}$	FLL target frequency acquisition time	—	—	1	ms	6	
PLL0,1							
$f_{pll\_ref}$	PLL reference frequency range	8	—	16	MHz		
$f_{vcoclk\_2x}$	VCO output frequency	180	—	360	MHz		
$f_{vcoclk}$	PLL output frequency	90	—	180	MHz		
$f_{vcoclk\_90}$	PLL quadrature output frequency	90	—	180	MHz		
$I_{pll}$	PLL0 operating current	—	2.8	—	mA		
	• VCO @ 180 MHz ( $f_{osc\_hi\_1} = 32$ MHz, $f_{pll\_ref} = 8$ MHz, VDIV multiplier = 22)						
$I_{pll}$	PLL0 operating current	—	4.7	—	mA	6	
	• VCO @ 360 MHz ( $f_{osc\_hi\_1} = 32$ MHz, $f_{pll\_ref} = 8$ MHz, VDIV multiplier = 45)						
$I_{pll}$	PLL1 operating current	—	2.3	—	mA	6	
	• VCO @ 180 MHz ( $f_{osc\_hi\_1} = 32$ MHz, $f_{pll\_ref} = 8$ MHz, VDIV multiplier = 22)						
$I_{pll}$	PLL1 operating current	—	3.6	—	mA	6	
	• VCO @ 360 MHz ( $f_{osc\_hi\_1} = 32$ MHz, $f_{pll\_ref} = 8$ MHz, VDIV multiplier = 45)						
$t_{pll\_lock}$	Lock detector detection time	—	—	$100 \times 10^{-6} + 1075(1/f_{pll\_ref})$	s		
$J_{cyc\_pll}$	PLL period jitter (RMS)						

Table continues on the next page...

**Table 15. MCG specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	<ul style="list-style-type: none"> <li><math>f_{VCO} = 180</math> MHz</li> <li><math>f_{VCO} = 360</math> MHz</li> </ul>	—	100	—	ps	
		—	75	—	ps	
$J_{acc\_pll}$	PLL accumulated jitter over 1 $\mu$ s (RMS)					
	<ul style="list-style-type: none"> <li><math>f_{VCO} = 180</math> MHz</li> <li><math>f_{VCO} = 360</math> MHz</li> </ul>	—	600	—	ps	
		—	300	—	ps	

1. This parameter is measured with the internal reference (slow clock) being used as a reference to the FLL (FEI clock mode).
2. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32=0.
3. The resulting system clock frequencies should not exceed their maximum specified values. The DCO frequency deviation ( $\Delta f_{dco\_t}$ ) over voltage and temperature should be considered.
4. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32=1.
5. This specification applies to any time the FLL reference source or reference divider is changed, trim value is changed, DMX32 bit is changed, DRS bits are changed, or changing from FLL disabled (BLPE, BLPI) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.
6. Excludes any oscillator currents that are also consuming power while PLL is in operation.

## 6.3.2 Oscillator electrical specifications

### 6.3.2.1 Oscillator DC electrical specifications

**Table 16. Oscillator DC electrical specifications**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$V_{DD}$	Supply voltage	1.71	—	3.6	V	
$I_{DDOSC}$	Supply current — low-power mode (HGO=0)					
	<ul style="list-style-type: none"> <li>32 kHz</li> <li>4 MHz</li> <li>8 MHz (RANGE=01)</li> <li>16 MHz</li> <li>24 MHz</li> <li>32 MHz</li> </ul>	—	500	—	nA	
		—	200	—	$\mu$ A	
		—	300	—	$\mu$ A	
		—	950	—	$\mu$ A	
		—	1.2	—	mA	
		—	1.5	—	mA	
$I_{DDOSC}$	Supply current — high-gain mode (HGO=1)					1
	<ul style="list-style-type: none"> <li>32 kHz</li> <li>4 MHz</li> <li>8 MHz (RANGE=01)</li> <li>16 MHz</li> <li>24 MHz</li> <li>32 MHz</li> </ul>	—	25	—	$\mu$ A	
		—	400	—	$\mu$ A	
		—	500	—	$\mu$ A	
		—	2.5	—	mA	
		—	3	—	mA	
		—	4	—	mA	

Table continues on the next page...



**Table 16. Oscillator DC electrical specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
C <sub>x</sub>	EXTAL load capacitance	—	—	—		
C <sub>y</sub>	XTAL load capacitance	—	—	—		2, 3
R <sub>F</sub>	Feedback resistor — low-frequency, low-power mode (HGO=0)	—	—	—	MΩ	2
	Feedback resistor — low-frequency, high-gain mode (HGO=1)	—	10	—	MΩ	
	Feedback resistor — high-frequency, low-power mode (HGO=0)	—	—	—	MΩ	
	Feedback resistor — high-frequency, high-gain mode (HGO=1)	—	1	—	MΩ	
R <sub>S</sub>	Series resistor — low-frequency, low-power mode (HGO=0)	—	—	—	kΩ	
	Series resistor — low-frequency, high-gain mode (HGO=1)	—	200	—	kΩ	
	Series resistor — high-frequency, low-power mode (HGO=0)	—	—	—	kΩ	
	Series resistor — high-frequency, high-gain mode (HGO=1)	—	0	—	kΩ	
V <sub>pp</sub> <sup>5</sup>	Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, low-power mode (HGO=0)	—	0.6	—	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, high-gain mode (HGO=1)	—	V <sub>DD</sub>	—	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, low-power mode (HGO=0)	—	0.6	—	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, high-gain mode (HGO=1)	—	V <sub>DD</sub>	—	V	

1. V<sub>DD</sub>=3.3 V, Temperature =25 °C
2. See crystal or resonator manufacturer's recommendation
3. C<sub>x</sub> and C<sub>y</sub> can be provided by using either integrated capacitors or external components.
4. The EXTAL and XTAL pins should only be connected to required oscillator components and must not be connected to any other device.

### 6.3.2.2 Oscillator frequency specifications

**Table 17. Oscillator frequency specifications**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
f <sub>osc_lo</sub>	Oscillator crystal or resonator frequency — low-frequency mode (MCG_C2[RANGE]=00)	32	—	40	kHz	

Table continues on the next page...

**Table 17. Oscillator frequency specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$f_{osc\_hi\_1}$	Oscillator crystal or resonator frequency — high-frequency mode (low range) (MCG_C2[RANGE]=01)	3	—	8	MHz	1
$f_{osc\_hi\_2}$	Oscillator crystal or resonator frequency — high frequency mode (high range) (MCG_C2[RANGE]=1x)	8	—	32	MHz	
$f_{ec\_extal}$	Input clock frequency (external clock mode)	—	—	60	MHz	2, 3
$t_{dc\_extal}$	Input clock duty cycle (external clock mode)	40	50	60	%	
$t_{cst}$	Crystal startup time — 32 kHz low-frequency, low-power mode (HGO=0)	—	1000	—	ms	,
	Crystal startup time — 32 kHz low-frequency, high-gain mode (HGO=1)	—	500	—	ms	
	Crystal startup time — 8 MHz high-frequency (MCG_C2[RANGE]=01), low-power mode (HGO=0)	—	0.6	—	ms	
	Crystal startup time — 8 MHz high-frequency (MCG_C2[RANGE]=01), high-gain mode (HGO=1)	—	1	—	ms	

1. Frequencies less than 8 MHz are not in the PLL range.
2. Other frequency limits may apply when external clock is being used as a reference for the FLL or PLL.
3. When transitioning from FEI or FBI to FBE mode, restrict the frequency of the input clock so that, when it is divided by FRDIV, it remains within the limits of the DCO input clock frequency.

**NOTE**

The 32 kHz oscillator works in low power mode by default and cannot be moved into high power/gain mode.

**6.3.3 32 kHz oscillator electrical characteristics****6.3.3.1 32 kHz oscillator DC electrical specifications****Table 18. 32kHz oscillator DC electrical specifications**

Symbol	Description	Min.	Typ.	Max.	Unit
$V_{BAT}$	Supply voltage	1.71	—	3.6	V
$R_F$	Internal feedback resistor	—	100	—	M $\Omega$
$C_{para}$	Parasitical capacitance of EXTAL32 and XTAL32	—	5	7	pF
$V_{pp}$ <sup>1</sup>	Peak-to-peak amplitude of oscillation	—	0.6	—	V

1. When a crystal is being used with the 32 kHz oscillator, the EXTAL32 and XTAL32 pins should only be connected to required oscillator components and must not be connected to any other devices.

### 6.3.3.2 32 kHz oscillator frequency specifications

Table 19. 32 kHz oscillator frequency specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$f_{osc\_lo}$	Oscillator crystal	—	32.768	—	kHz	
$t_{start}$	Crystal start-up time	—	1000	—	ms	
$V_{ec\_extal32}$	Externally provided input clock amplitude	700	—	$V_{BAT}$	mV	3

1. The parameter specified is a peak-to-peak value and  $V_{IH}$  and  $V_{IL}$  specifications do not apply. The voltage of the applied clock must be within the range of  $V_{SS}$  to  $V_{BAT}$ .

## 6.4 Memories and memory interfaces

### 6.4.1 Flash (FTFE) electrical specifications

This section describes the electrical characteristics of the FTFE module.

#### 6.4.1.1 Flash timing specifications — program and erase

The following specifications represent the amount of time the internal charge pumps are active and do not include command overhead.

Table 20. NVM program/erase timing specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{hvp8}$	Program Phrase high-voltage time	—	7.5	18	$\mu$ s	
$t_{hverscr}$	Erase Flash Sector high-voltage time	—	13	113	ms	
$t_{hversblk128k}$	Erase Flash Block high-voltage time for 128 KB	—	104	1808	ms	1
$t_{hversblk256k}$	Erase Flash Block high-voltage time for 256 KB	—	208	3616	ms	1

1. Maximum time based on expectations at cycling end-of-life.

#### 6.4.1.2 Flash timing specifications — commands

Table 21. Flash command timing specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{rd1blk128k}$	Read 1s Block execution time					
	• 128 KB data flash	—	—	0.5	ms	
$t_{rd1blk256k}$	• 256 KB program flash	—	—	1.0	ms	
$t_{rd1sec4k}$	Read 1s Section execution time (4 KB flash)	—	—	100	$\mu$ s	1
$t_{pgmchk}$	Program Check execution time	—	—	80	$\mu$ s	1

Table continues on the next page...

**Table 21. Flash command timing specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{rdsrc}$	Read Resource execution time	—	—	40	$\mu$ s	
$t_{pgm8}$	Program Phrase execution time	—	70	150	$\mu$ s	
$t_{ersblk128k}$	Erase Flash Block execution time	—	110	925	ms	2
$t_{ersblk256k}$	<ul style="list-style-type: none"> <li>128 KB data flash</li> <li>256 KB program flash</li> </ul>	—	220	1850	ms	
$t_{ersscr}$	Erase Flash Sector execution time	—	15	115	ms	
$t_{pgmsec4k}$	Program Section execution time (4KB flash)	—	20	—	ms	
$t_{rd1allx}$	Read 1s All Blocks execution time	—	—	3.4	ms	
$t_{rd1alln}$	<ul style="list-style-type: none"> <li>FlexNVM devices</li> <li>Program flash only devices</li> </ul>	—	—	3.4	ms	
$t_{rdonce}$	Read Once execution time	—	—	30	$\mu$ s	1
$t_{pgmonce}$	Program Once execution time	—	70	—	$\mu$ s	
$t_{ersall}$	Erase All Blocks execution time	—	650	5600	ms	2
$t_{vfykey}$	Verify Backdoor Access Key execution time	—	—	30	$\mu$ s	1
$t_{swapx01}$	Swap Control execution time	—	200	—	$\mu$ s	
$t_{swapx02}$	<ul style="list-style-type: none"> <li>control code 0x01</li> <li>control code 0x02</li> </ul>	—	70	150	$\mu$ s	
$t_{swapx04}$	<ul style="list-style-type: none"> <li>control code 0x04</li> </ul>	—	70	150	$\mu$ s	
$t_{swapx08}$	<ul style="list-style-type: none"> <li>control code 0x08</li> </ul>	—	—	30	$\mu$ s	
$t_{pgmpart64k}$	Program Partition for EEPROM execution time	—	235	—	ms	
$t_{pgmpart256k}$	<ul style="list-style-type: none"> <li>64 KB FlexNVM</li> <li>256 KB FlexNVM</li> </ul>	—	240	—	ms	
$t_{setramff}$	Set FlexRAM Function execution time:	—	205	—	$\mu$ s	
$t_{setram64k}$	<ul style="list-style-type: none"> <li>Control Code 0xFF</li> <li>64 KB EEPROM backup</li> </ul>	—	1.6	2.5	ms	
$t_{setram128k}$	<ul style="list-style-type: none"> <li>128 KB EEPROM backup</li> </ul>	—	2.7	3.8	ms	
$t_{setram256k}$	<ul style="list-style-type: none"> <li>256 KB EEPROM backup</li> </ul>	—	4.8	6.2	ms	
$t_{eewr8bers}$	Byte-write to erased FlexRAM location execution time	—	140	225	$\mu$ s	3
$t_{eewr8b64k}$	Byte-write to FlexRAM execution time:	—	400	1700	$\mu$ s	
$t_{eewr8b128k}$	<ul style="list-style-type: none"> <li>64 KB EEPROM backup</li> <li>128 KB EEPROM backup</li> </ul>	—	450	1800	$\mu$ s	
$t_{eewr8b256k}$	<ul style="list-style-type: none"> <li>256 KB EEPROM backup</li> </ul>	—	525	2000	$\mu$ s	
$t_{eewr16bers}$	16-bit write to erased FlexRAM location execution time	—	140	225	$\mu$ s	
$t_{eewr16b64k}$	16-bit write to FlexRAM execution time:	—	400	1700	$\mu$ s	

Table continues on the next page...

**Table 21. Flash command timing specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{\text{eewr16b128k}}$	• 64 KB EEPROM backup	—	450	1800	$\mu\text{s}$	
$t_{\text{eewr16b256k}}$	• 128 KB EEPROM backup • 256 KB EEPROM backup	—	525	2000	$\mu\text{s}$	
$t_{\text{eewr32bers}}$	32-bit write to erased FlexRAM location execution time	—	180	275	$\mu\text{s}$	
	32-bit write to FlexRAM execution time:					
$t_{\text{eewr32b64k}}$	• 64 KB EEPROM backup	—	475	1850	$\mu\text{s}$	
$t_{\text{eewr32b128k}}$	• 128 KB EEPROM backup	—	525	2000	$\mu\text{s}$	
$t_{\text{eewr32b256k}}$	• 256 KB EEPROM backup	—	600	2200	$\mu\text{s}$	

1. Assumes 25MHz or greater flash clock frequency.
2. Maximum times for erase parameters based on expectations at cycling end-of-life.
3. For byte-writes to an erased FlexRAM location, the aligned word containing the byte must be erased.

### 6.4.1.3 Flash high voltage current behaviors

**Table 22. Flash high voltage current behaviors**

Symbol	Description	Min.	Typ.	Max.	Unit
$I_{\text{DD\_PGM}}$	Average current adder during high voltage flash programming operation	—	3.5	7.5	mA
$I_{\text{DD\_ERS}}$	Average current adder during high voltage flash erase operation	—	1.5	4.0	mA

### 6.4.1.4 Reliability specifications

**Table 23. NVM reliability specifications**

Symbol	Description	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
Program Flash						
$t_{\text{nv mretp10k}}$	Data retention after up to 10 K cycles	5	50	—	years	
$t_{\text{nv mretp1k}}$	Data retention after up to 1 K cycles	20	100	—	years	
$n_{\text{nv mcycp}}$	Cycling endurance	10 K	50 K	—	cycles	
Data Flash						
$t_{\text{nv mretd10k}}$	Data retention after up to 10 K cycles	5	50	—	years	
$t_{\text{nv mretd1k}}$	Data retention after up to 1 K cycles	20	100	—	years	
$n_{\text{nv mcycd}}$	Cycling endurance	10 K	50 K	—	cycles	2
FlexRAM as EEPROM						

Table continues on the next page...

**Table 23. NVM reliability specifications (continued)**

Symbol	Description	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
$t_{nvmretee100}$	Data retention up to 100% of write endurance	5	50	—	years	
$t_{nvmretee10}$	Data retention up to 10% of write endurance	20	100	—	years	
$n_{nvmcycee}$	Cycling endurance for EEPROM backup	20 K	50 K	—	cycles	2
	Write endurance					
$n_{nvmwree16}$	• EEPROM backup to FlexRAM ratio = 16	70 K	175 K	—	writes	
$n_{nvmwree128}$	• EEPROM backup to FlexRAM ratio = 128	630 K	1.6 M	—	writes	
$n_{nvmwree512}$	• EEPROM backup to FlexRAM ratio = 512	2.5 M	6.4 M	—	writes	
$n_{nvmwree2k}$	• EEPROM backup to FlexRAM ratio = 2,048	10 M	25 M	—	writes	

1. Typical data retention values are based on measured response accelerated at high temperature and derated to a constant 25°C use profile. Engineering Bulletin EB618 does not apply to this technology. Typical endurance defined in Engineering Bulletin EB619.
2. Cycling endurance represents number of program/erase cycles at  $-40^{\circ}\text{C} \leq T_j \leq 125^{\circ}\text{C}$ .

#### 6.4.1.5 Write endurance to FlexRAM for EEPROM

When the FlexNVM partition code is not set to full data flash, the EEPROM data set size can be set to any of several non-zero values.

The bytes not assigned to data flash via the FlexNVM partition code are used by the FTFE to obtain an effective endurance increase for the EEPROM data. The built-in EEPROM record management system raises the number of program/erase cycles that can be attained prior to device wear-out by cycling the EEPROM data through a larger EEPROM NVM storage space.

While different partitions of the FlexNVM are available, the intention is that a single choice for the FlexNVM partition code and EEPROM data set size is used throughout the entire lifetime of a given application. The EEPROM endurance equation and graph shown below assume that only one configuration is ever used.

$$\text{Writes}_{\text{subsystem}} = \frac{\text{EEPROM} - 2 \times \text{EESPLIT} \times \text{EESIZE}}{\text{EESPLIT} \times \text{EESIZE}} \times \text{Write}_{\text{efficiency}} \times n_{nvmcycee}$$

where

- $\text{Writes}_{\text{subsystem}}$  — minimum number of writes to each FlexRAM location for subsystem (each subsystem can have different endurance)
- $\text{EEPROM}$  — allocated FlexNVM for each EEPROM subsystem based on DEPART; entered with Program Partition command
- $\text{EESPLIT}$  — FlexRAM split factor for subsystem; entered with the Program Partition command

- **EEESIZE** — allocated FlexRAM based on DEPART; entered with Program Partition command
- **Write\_efficiency** —
  - 0.25 for 8-bit writes to FlexRAM
  - 0.50 for 16-bit or 32-bit writes to FlexRAM
- **n<sub>nvmcycee</sub>** — EEPROM-backup cycling endurance

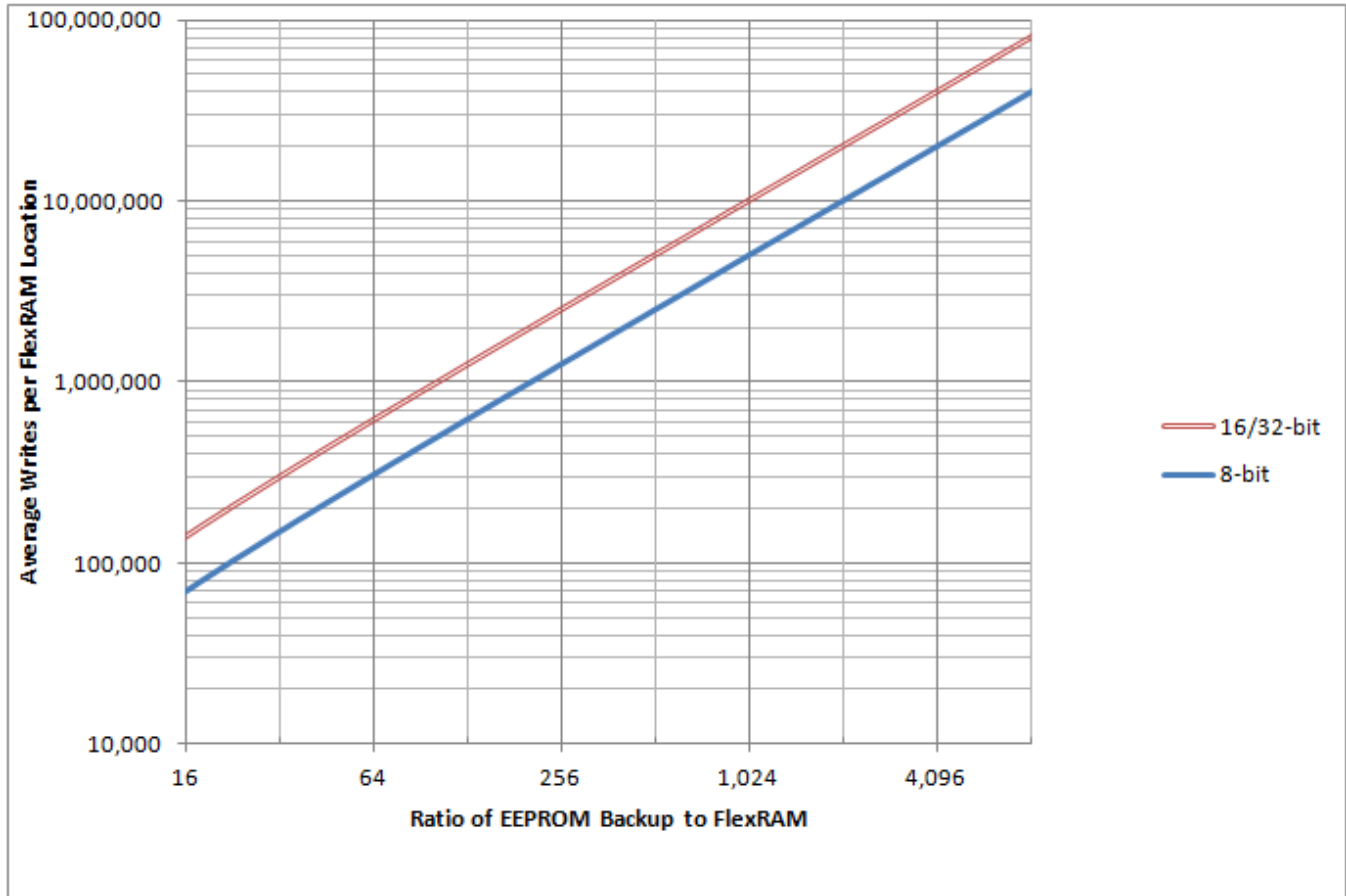


Figure 11. EEPROM backup writes to FlexRAM

## 6.4.2 EzPort switching specifications

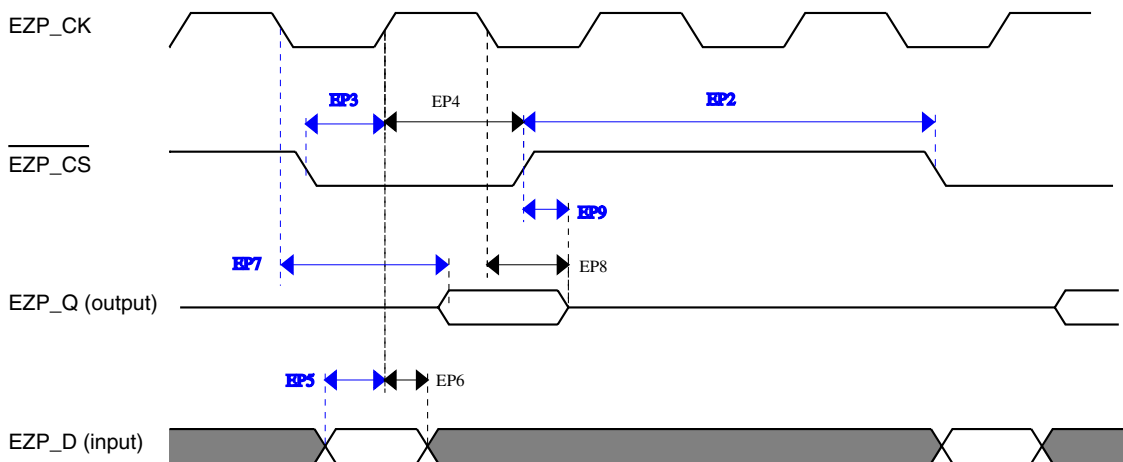
Table 24. EzPort switching specifications

Num	Description	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
EP1	EZP_CK frequency of operation (all commands except READ)	—	f <sub>sys</sub> /2	MHz
EP1a	EZP_CK frequency of operation (READ command)	—	f <sub>sys</sub> /8	MHz
EP2	EZP_CS negation to next EZP_CS assertion	2 x t <sub>EZP_CK</sub>	—	ns
EP3	EZP_CS input valid to EZP_CK high (setup)	5	—	ns

Table continues on the next page...

**Table 24. EzPort switching specifications (continued)**

Num	Description	Min.	Max.	Unit
EP4	EZP_CK high to EZP_CS input invalid (hold)	5	—	ns
EP5	EZP_D input valid to EZP_CK high (setup)	2	—	ns
EP6	EZP_CK high to EZP_D input invalid (hold)	5	—	ns
EP7	EZP_CK low to EZP_Q output valid	—	16	ns
EP8	EZP_CK low to EZP_Q output invalid (hold)	0	—	ns
EP9	EZP_CS negation to EZP_Q tri-state	—	12	ns



**Figure 12. EzPort Timing Diagram**

### 6.4.3 NFC specifications

The NAND flash controller (NFC) implements the interface to standard NAND flash memory devices. This section describes the timing parameters of the NFC.

In the following table:

- $T_H$  is the flash clock high time and
- $T_L$  is flash clock low time,

which are defined as:

$$T_{NFC} = T_L + T_H = \frac{T_{input\ clock}}{SCALER}$$



The SCALER value is derived from the fractional divider specified in the SIM's CLKDIV4 register:

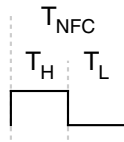
$$\text{SCALER} = \frac{\text{SIM\_CLKDIV4[NFCFRAC]} + 1}{\text{SIM\_CLKDIV4[NFCDIV]} + 1}$$

In case the reciprocal of SCALER is an integer, the duty cycle of NFC clock is 50%, means  $T_H = T_L$ . In case the reciprocal of SCALER is not an integer:

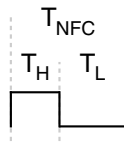
$$T_L = (1 + \text{SCALER} / 2) \times \frac{T_{\text{NFC}}}{2}$$

$$T_H = (1 - \text{SCALER} / 2) \times \frac{T_{\text{NFC}}}{2}$$

For example, if SCALER is 0.2, then  $T_H = T_L = T_{\text{NFC}}/2$ .



However, if SCALER is 0.667, then  $T_L = 2/3 \times T_{\text{NFC}}$  and  $T_H = 1/3 \times T_{\text{NFC}}$ .



### NOTE

The reciprocal of SCALER must be a multiple of 0.5. For example, 1, 1.5, 2, 2.5, etc.

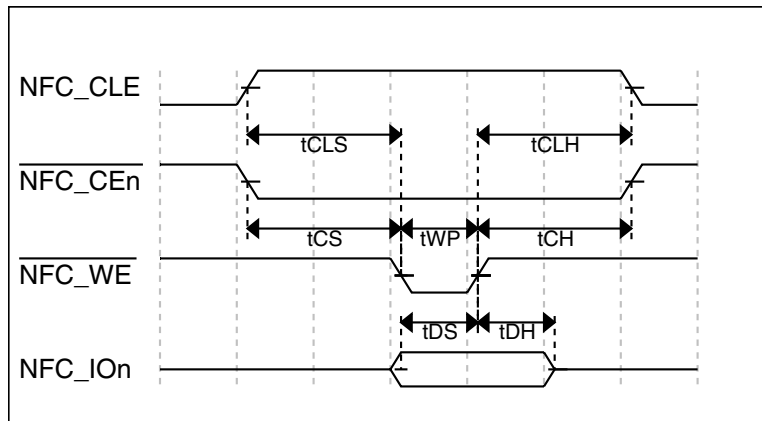
**Table 25. NFC specifications**

Num	Description	Min.	Max.	Unit
$t_{\text{CLS}}$	NFC_CLE setup time	$2T_H + T_L - 1$	—	ns
$t_{\text{CLH}}$	NFC_CLE hold time	$T_H + T_L - 1$	—	ns
$t_{\text{CS}}$	$\overline{\text{NFC\_CEN}}$ setup time	$2T_H + T_L - 1$	—	ns
$t_{\text{CH}}$	$\overline{\text{NFC\_CEN}}$ hold time	$T_H + T_L$	—	ns
$t_{\text{WP}}$	NFC_WP pulse width	$T_L - 1$	—	ns
$t_{\text{ALS}}$	NFC_ALE setup time	$2T_H + T_L$	—	ns
$t_{\text{ALH}}$	NFC_ALE hold time	$T_H + T_L$	—	ns
$t_{\text{DS}}$	Data setup time	$T_L - 1$	—	ns
$t_{\text{DH}}$	Data hold time	$T_H - 1$	—	ns
$t_{\text{WC}}$	Write cycle time	$T_H + T_L - 1$	—	ns
$t_{\text{WH}}$	$\overline{\text{NFC\_WE}}$ hold time	$T_H - 1$	—	ns

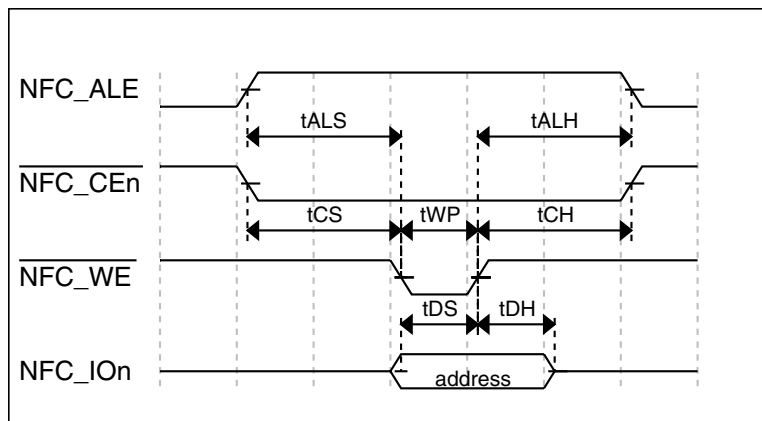
Table continues on the next page...

**Table 25. NFC specifications (continued)**

Num	Description	Min.	Max.	Unit
$t_{RR}$	Ready to $\overline{\text{NFC\_RE}}$ low	$4T_H + 3T_L + 90$	—	ns
$t_{RP}$	$\overline{\text{NFC\_RE}}$ pulse width	$T_L + 1$	—	ns
$t_{RC}$	Read cycle time	$T_L + T_H - 1$	—	ns
$t_{REH}$	$\overline{\text{NFC\_RE}}$ high hold time	$T_H - 1$	—	ns
$t_{IS}$	Data input setup time	11	—	ns



**Figure 13. Command latch cycle timing**



**Figure 14. Address latch cycle timing**

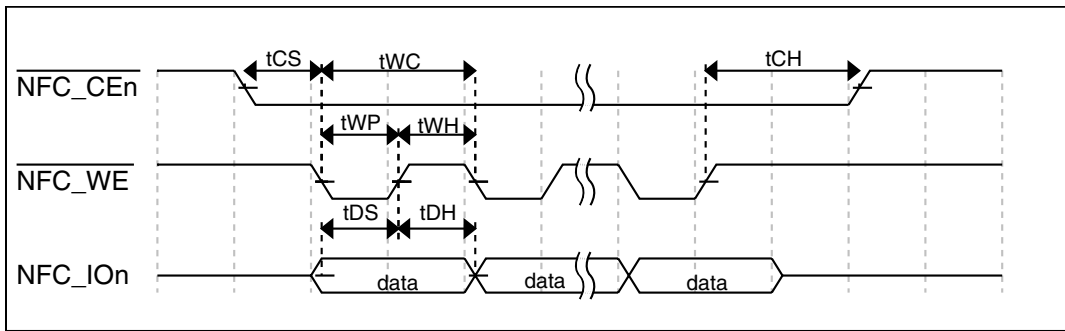


Figure 15. Write data latch cycle timing

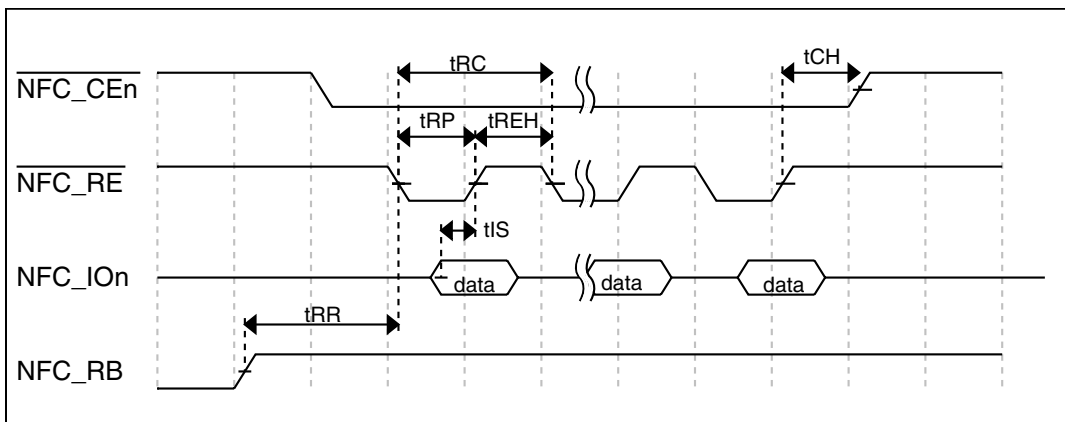


Figure 16. Read data latch cycle timing in non-fast mode

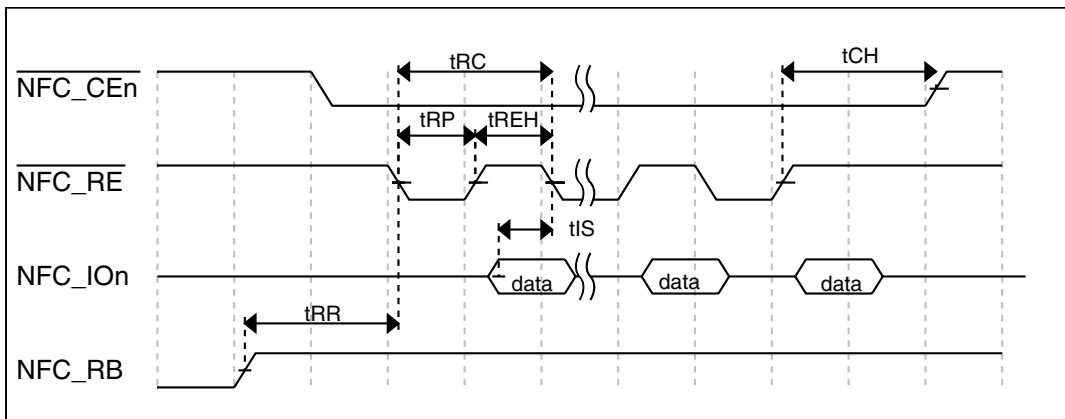


Figure 17. Read data latch cycle timing in fast mode

#### 6.4.4 Flexbus switching specifications

All processor bus timings are synchronous; input setup/hold and output delay are given in respect to the rising edge of a reference clock, FB\_CLK. The FB\_CLK frequency may be the same as the internal system bus frequency or an integer divider of that frequency.

The following timing numbers indicate when data is latched or driven onto the external bus, relative to the Flexbus output clock (FB\_CLK). All other timing relationships can be derived from these values.

**Table 26. Flexbus limited voltage range switching specifications**

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	2.7	3.6	V	
	Frequency of operation	—	FB_CLK	MHz	
FB1	Clock period	20	—	ns	
FB2	Address, data, and control output valid	—	11.5	ns	
FB3	Address, data, and control output hold	0.5	—	ns	1
FB4	Data and $\overline{\text{FB\_TA}}$ input setup	8.5	—	ns	
FB5	Data and $\overline{\text{FB\_TA}}$ input hold	0.5	—	ns	2

1. Specification is valid for all FB\_AD[31:0],  $\overline{\text{FB\_BE/BWE}}_n$ ,  $\overline{\text{FB\_CS}}_n$ ,  $\overline{\text{FB\_OE}}$ , FB\_R/W,  $\overline{\text{FB\_TBST}}$ , FB\_TSI[1:0], FB\_ALE, and  $\overline{\text{FB\_TS}}$ .
2. Specification is valid for all FB\_AD[31:0] and  $\overline{\text{FB\_TA}}$ .

**Table 27. Flexbus full voltage range switching specifications**

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	1.71	3.6	V	
	Frequency of operation	—	FB_CLK	MHz	
FB1	Clock period	1/FB_CLK	—	ns	
FB2	Address, data, and control output valid	—	13.5	ns	
FB3	Address, data, and control output hold	0	—	ns	1
FB4	Data and $\overline{\text{FB\_TA}}$ input setup	13.7	—	ns	
FB5	Data and $\overline{\text{FB\_TA}}$ input hold	0.5	—	ns	2

1. Specification is valid for all FB\_AD[31:0],  $\overline{\text{FB\_BE/BWE}}_n$ ,  $\overline{\text{FB\_CS}}_n$ ,  $\overline{\text{FB\_OE}}$ , FB\_R/W,  $\overline{\text{FB\_TBST}}$ , FB\_TSI[1:0], FB\_ALE, and  $\overline{\text{FB\_TS}}$ .
2. Specification is valid for all FB\_AD[31:0] and  $\overline{\text{FB\_TA}}$ .

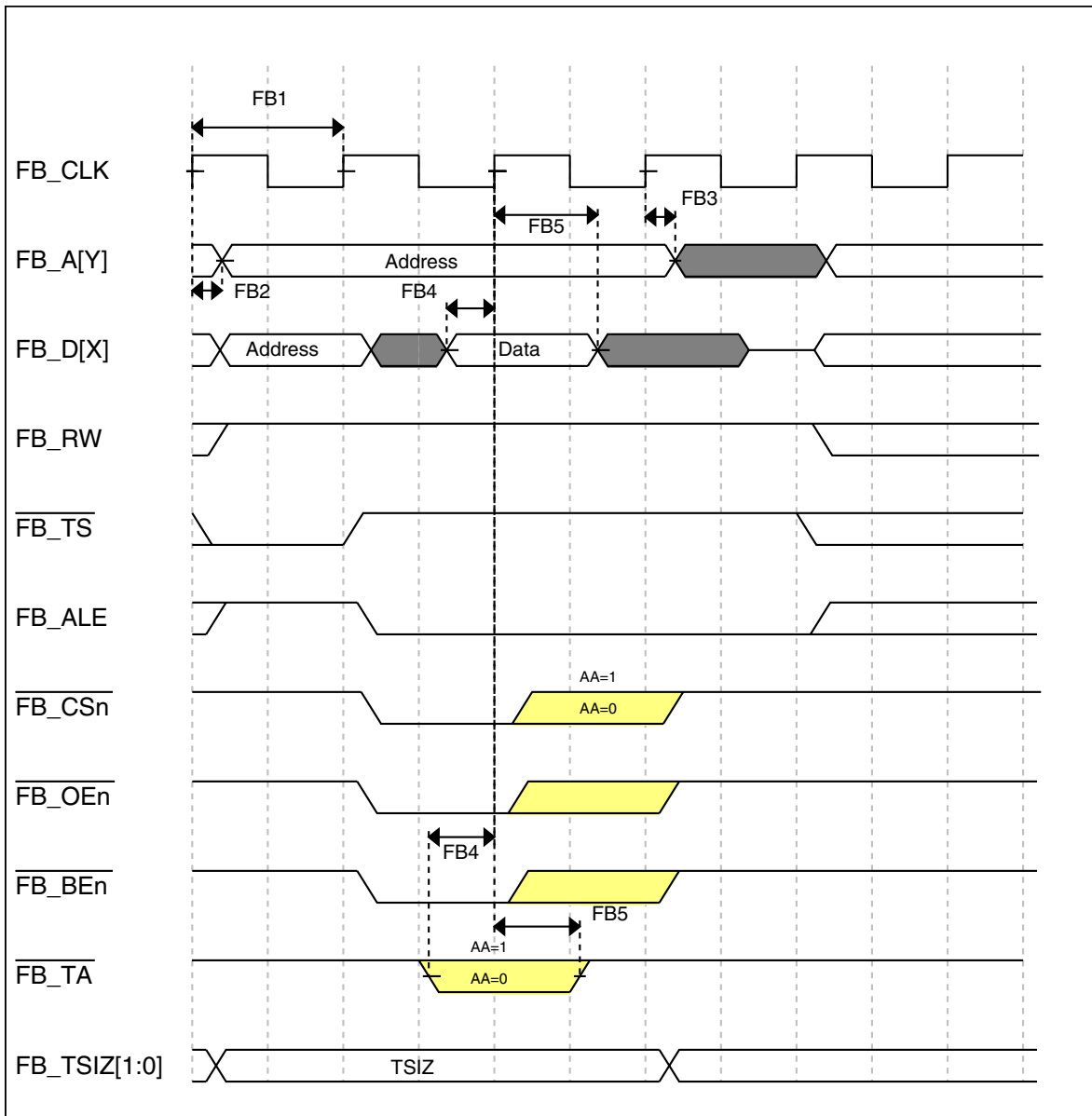


Figure 18. FlexBus read timing diagram

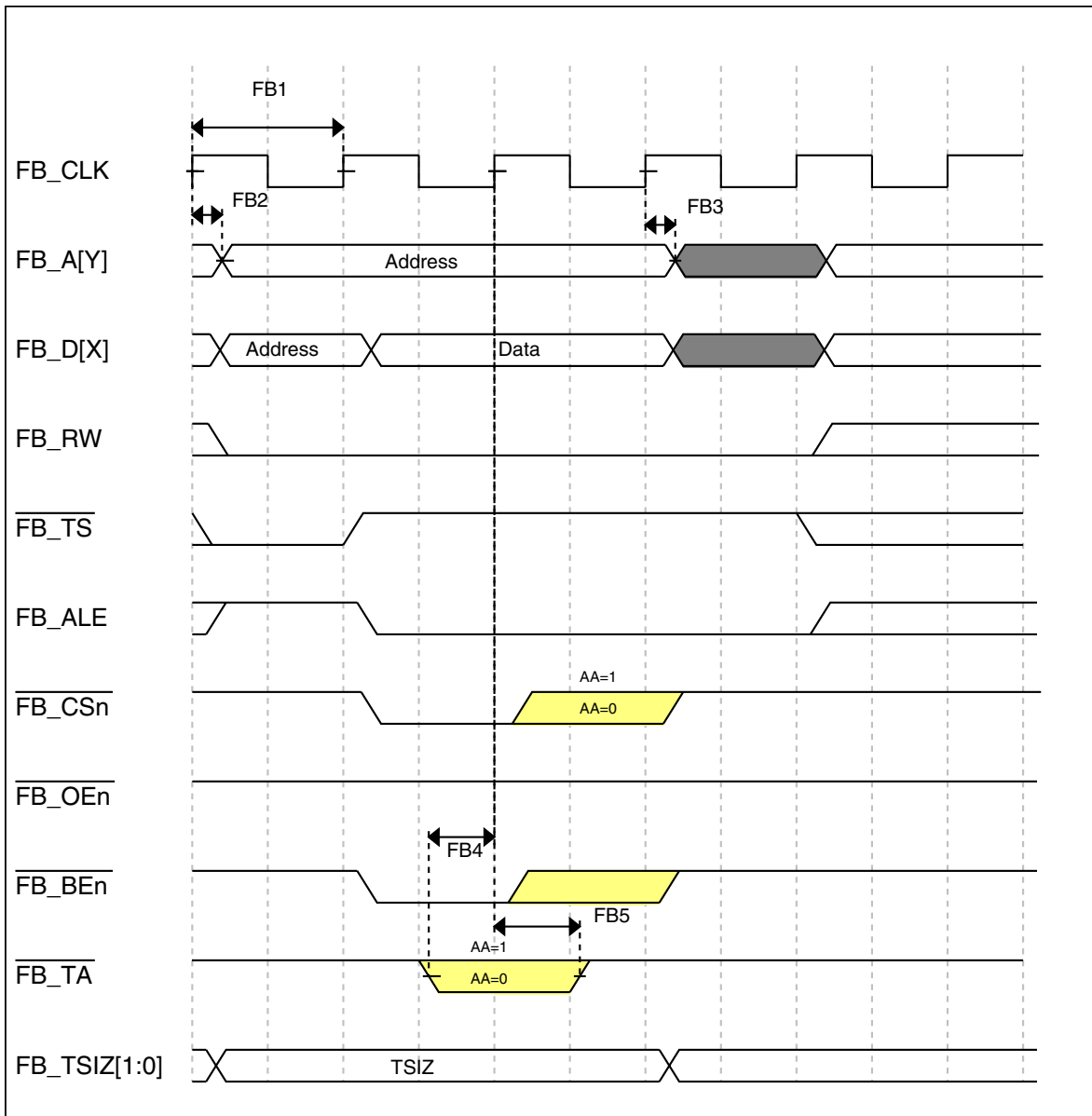


Figure 19. FlexBus write timing diagram

## 6.5 Security and integrity modules

### 6.5.1 DryIce Tamper Electrical Specifications

Information about security-related modules is not included in this document and is available only after a nondisclosure agreement (NDA) has been signed. To request an NDA, please contact your local Freescale sales representative.

## 6.6 Analog

### 6.6.1 ADC electrical specifications

The 16-bit accuracy specifications listed in [Table 28](#) and [Table 29](#) are achievable on the differential pins ADCx\_DP0, ADCx\_DM0.

The ADCx\_DP2 and ADCx\_DM2 ADC inputs are connected to the PGA outputs and are not direct device pins. Accuracy specifications for these pins are defined in [Table 30](#) and [Table 31](#).

All other ADC channels meet the 13-bit differential/12-bit single-ended accuracy specifications.

#### 6.6.1.1 16-bit ADC operating conditions

**Table 28. 16-bit ADC operating conditions**

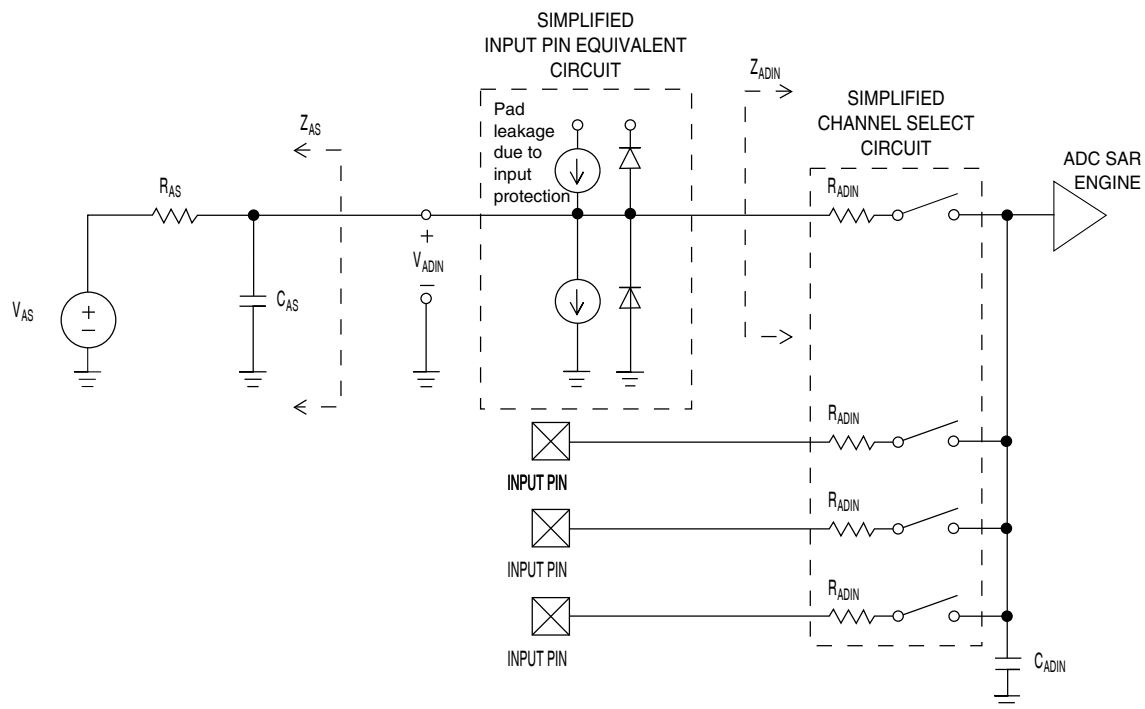
Symbol	Description	Conditions	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
V <sub>DDA</sub>	Supply voltage	Absolute	1.71	—	3.6	V	
ΔV <sub>DDA</sub>	Supply voltage	Delta to V <sub>DD</sub> (V <sub>DD</sub> – V <sub>DDA</sub> )	-100	0	+100	mV	
ΔV <sub>SSA</sub>	Ground voltage	Delta to V <sub>SS</sub> (V <sub>SS</sub> – V <sub>SSA</sub> )	-100	0	+100	mV	<a href="#">2</a>
V <sub>REFH</sub>	ADC reference voltage high		1.13	V <sub>DDA</sub>	V <sub>DDA</sub>	V	
V <sub>REFL</sub>	ADC reference voltage low		V <sub>SSA</sub>	V <sub>SSA</sub>	V <sub>SSA</sub>	V	
V <sub>ADIN</sub>	Input voltage	<ul style="list-style-type: none"> <li>16-bit differential mode</li> <li>All other modes</li> </ul>	V <sub>REFL</sub> V <sub>REFL</sub>	— —	31/32 * V <sub>REFH</sub> V <sub>REFH</sub>	V	
C <sub>ADIN</sub>	Input capacitance	<ul style="list-style-type: none"> <li>16-bit mode</li> <li>8-bit / 10-bit / 12-bit modes</li> </ul>	— —	8 4	10 5	pF	
R <sub>ADIN</sub>	Input resistance		—	2	5	kΩ	
R <sub>AS</sub>	Analog source resistance	13-bit / 12-bit modes f <sub>ADCK</sub> < 4 MHz	—	—	5	kΩ	<a href="#">3</a>
f <sub>ADCK</sub>	ADC conversion clock frequency	≤ 13-bit mode	1.0	—	18.0	MHz	
f <sub>ADCK</sub>	ADC conversion clock frequency	16-bit mode	2.0	—	12.0	MHz	<a href="#">4</a>
C <sub>rate</sub>	ADC conversion rate	≤ 13-bit modes No ADC hardware averaging	20.000	—	818.330	Ksps	

*Table continues on the next page...*

**Table 28. 16-bit ADC operating conditions (continued)**

Symbol	Description	Conditions	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
		Continuous conversions enabled, subsequent conversion time					
$C_{rate}$	ADC conversion rate	16-bit mode No ADC hardware averaging Continuous conversions enabled, subsequent conversion time	37.037	—	461.467	Ksps	5

1. Typical values assume  $V_{DDA} = 3.0\text{ V}$ ,  $\text{Temp} = 25\text{ }^{\circ}\text{C}$ ,  $f_{ADCK} = 1.0\text{ MHz}$ , unless otherwise stated. Typical values are for reference only, and are not tested in production.
2. DC potential difference.
3. This resistance is external to MCU. To achieve the best results, the analog source resistance must be kept as low as possible. The results in this data sheet were derived from a system that had  $< 8\ \Omega$  analog source resistance. The  $R_{AS}/C_{AS}$  time constant should be kept to  $< 1\text{ ns}$ .
4. To use the maximum ADC conversion clock frequency,  $\text{CFG2}[\text{ADHSC}]$  must be set and  $\text{CFG1}[\text{ADLPC}]$  must be clear.
5. For guidelines and examples of conversion rate calculation, download the [ADC calculator tool](#).

**Figure 20. ADC input impedance equivalency diagram**

### 6.6.1.2 16-bit ADC electrical characteristics



**Table 29. 16-bit ADC characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ )**

Symbol	Description	Conditions <sup>1</sup>	Min.	Typ.	Max.	Unit	Notes
$I_{DDA\_ADC}$	Supply current		0.215	—	1.7	mA	3
$f_{ADACK}$	ADC asynchronous clock source	• ADLPC = 1, ADHSC = 0	1.2	2.4	3.9	MHz	$t_{ADACK} = 1/f_{ADACK}$
		• ADLPC = 1, ADHSC = 1	2.4	4.0	6.1	MHz	
		• ADLPC = 0, ADHSC = 0	3.0	5.2	7.3	MHz	
		• ADLPC = 0, ADHSC = 1	4.4	6.2	9.5	MHz	
	Sample Time	See Reference Manual chapter for sample times					
TUE	Total unadjusted error	• 12-bit modes • <12-bit modes	— —	±4 ±1.4	±6.8 ±2.1	LSB	
DNL	Differential non-linearity	• 12-bit modes • <12-bit modes	— —	±0.7 ±0.2	-1.1 to +1.9 -0.3 to 0.5	LSB <sup>3</sup>	4
INL	Integral non-linearity	• 12-bit modes • <12-bit modes	— —	±1.0 ±0.5	-2.7 to +1.9 -0.7 to +0.5	LSB <sup>3</sup>	4
$E_{FS}$	Full-scale error	• 12-bit modes • <12-bit modes	— —	-4 -1.4	-5.4 -1.8	LSB <sup>3</sup>	$V_{ADIN} = V_{DDA}$ <sup>4</sup>
$E_Q$	Quantization error	• 16-bit modes • ≤13-bit modes	— —	-1 to 0 —	— ±0.5	LSB <sup>3</sup>	
ENOB	Effective number of bits	16-bit differential mode • Avg = 32 • Avg = 4  16-bit single-ended mode • Avg = 32 • Avg = 4	12.8 11.9  12.2 11.4	14.5 13.8  13.9 13.1	— —  — —	bits bits  bits bits	
SINAD	Signal-to-noise plus distortion	See ENOB	6.02 × ENOB + 1.76			dB	
THD	Total harmonic distortion	16-bit differential mode • Avg = 32	—	-94	—	dB	
		16-bit single-ended mode • Avg = 32	—	-85	—	dB	
SFDR	Spurious free dynamic range	16-bit differential mode • Avg = 32	82	95	—	dB	5
		16-bit single-ended mode • Avg = 32	78	90	—	dB	

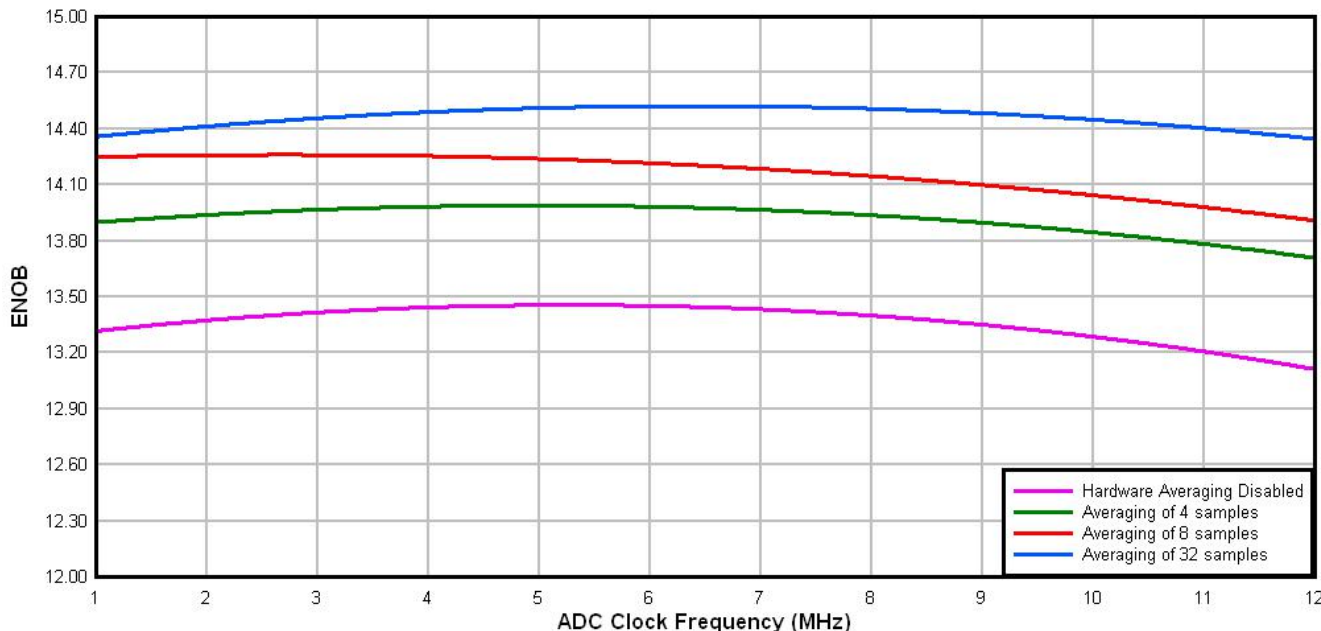
Table continues on the next page...

**Table 29. 16-bit ADC characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ ) (continued)**

Symbol	Description	Conditions <sup>1</sup> .	Min.	Typ.	Max.	Unit	Notes
$E_{IL}$	Input leakage error			$I_{in} \times R_{AS}$		mV	$I_{in}$ = leakage current  (refer to the MCU's voltage and current operating ratings)
	Temp sensor slope	Across the full temperature range of the device	1.55	1.62	1.69	mV/°C	
$V_{TEMP25}$	Temp sensor voltage	25 °C	706	716	726	mV	6

1. All accuracy numbers assume the ADC is calibrated with  $V_{REFH} = V_{DDA}$
2. The ADC supply current depends on the ADC conversion clock speed, conversion rate and ADC\_CFG1[ADLPC] (low power). For lowest power operation, ADC\_CFG1[ADLPC] must be set, the ADC\_CFG2[ADHSC] bit must be clear with 1 MHz ADC conversion clock speed.
3.  $1 \text{ LSB} = (V_{REFH} - V_{REFL})/2^N$
4. ADC conversion clock < 16 MHz, Max hardware averaging (AVGE = %1, AVGS = %11)
5. Input data is 1 kHz sine wave. ADC conversion clock < 12 MHz.
6. ADC conversion clock < 3 MHz

**Typical ADC 16-bit Differential ENOB vs ADC Clock  
100Hz, 90% FS Sine Input**



**Figure 21. Typical ENOB vs. ADC\_CLK for 16-bit differential mode**

Typical ADC 16-bit Single-Ended ENOB vs ADC Clock  
100Hz, 90% FS Sine Input

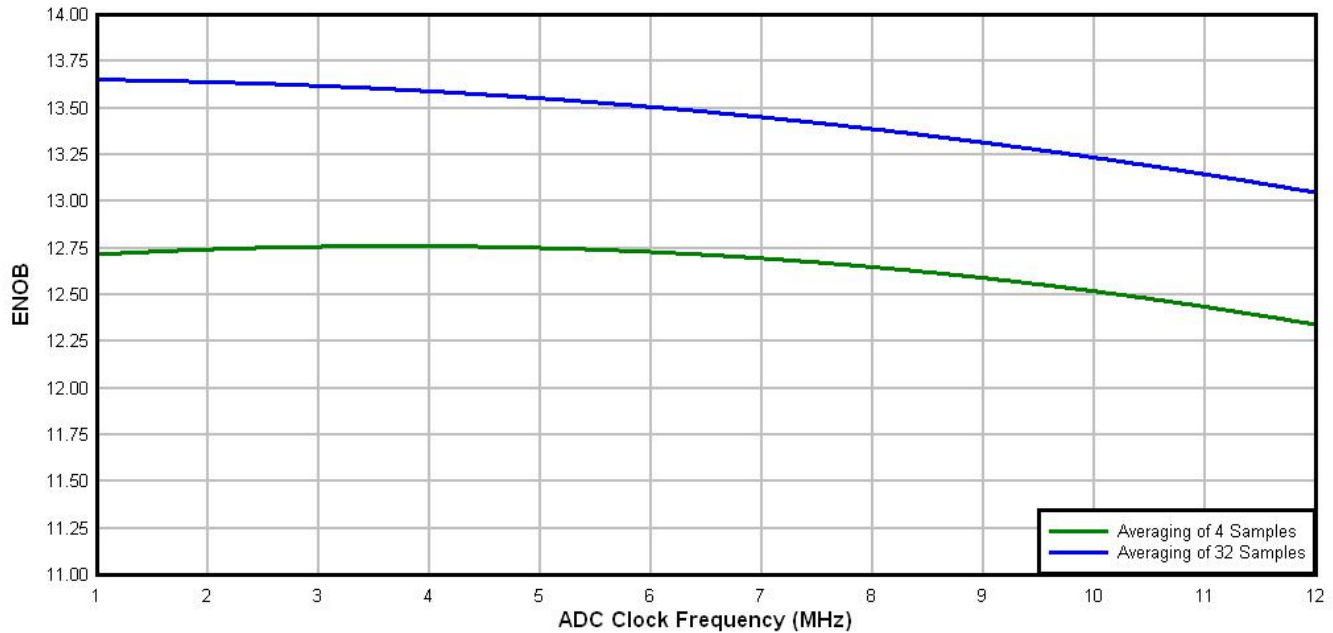


Figure 22. Typical ENOB vs. ADC\_CLK for 16-bit single-ended mode

### 6.6.1.3 16-bit ADC with PGA operating conditions

Table 30. 16-bit ADC with PGA operating conditions

Symbol	Description	Conditions	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
V <sub>DDA</sub>	Supply voltage	Absolute	1.71	—	3.6	V	
V <sub>REFPGA</sub>	PGA ref voltage		V <sub>REF_OUT</sub>	V <sub>REF_OUT</sub>	V <sub>REF_OUT</sub>	V	2, 3
V <sub>ADIN</sub>	Input voltage		V <sub>SSA</sub>	—	V <sub>DDA</sub>	V	
V <sub>CM</sub>	Input Common Mode range		V <sub>SSA</sub>	—	V <sub>DDA</sub>	V	
R <sub>PGAD</sub>	Differential input impedance	Gain = 1, 2, 4, 8 Gain = 16, 32 Gain = 64	—	128 64 32	—	kΩ	IN+ to IN- <sup>4</sup>
R <sub>AS</sub>	Analog source resistance		—	100	—	Ω	5
T <sub>S</sub>	ADC sampling time		1.25	—	—	μs	6
C <sub>rate</sub>	ADC conversion rate	≤ 13 bit modes No ADC hardware averaging Continuous conversions enabled Peripheral clock = 50 MHz	18.484	—	450	Ksps	7

Table continues on the next page...

**Table 30. 16-bit ADC with PGA operating conditions (continued)**

Symbol	Description	Conditions	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
		16 bit modes No ADC hardware averaging Continuous conversions enabled Peripheral clock = 50 MHz	37.037	—	250	Ksps	8

1. Typical values assume  $V_{DDA} = 3.0\text{ V}$ ,  $\text{Temp} = 25^\circ\text{C}$ ,  $f_{\text{ADCK}} = 6\text{ MHz}$  unless otherwise stated. Typical values are for reference only and are not tested in production.
2. ADC must be configured to use the internal voltage reference (VREF\_OUT)
3. PGA reference is internally connected to the VREF\_OUT pin. If the user wishes to drive VREF\_OUT with a voltage other than the output of the VREF module, the VREF module must be disabled.
4. For single ended configurations the input impedance of the driven input is  $R_{\text{PGAD}}/2$
5. The analog source resistance ( $R_{\text{AS}}$ ), external to MCU, should be kept as minimum as possible. Increased  $R_{\text{AS}}$  causes drop in PGA gain without affecting other performances. This is not dependent on ADC clock frequency.
6. The minimum sampling time is dependent on input signal frequency and ADC mode of operation. A minimum of  $1.25\mu\text{s}$  time should be allowed for  $F_{\text{in}}=4\text{ kHz}$  at 16-bit differential mode. Recommended ADC setting is: ADLSMP=1, ADLSTS=2 at 8 MHz ADC clock.
7. ADC clock = 18 MHz, ADLSMP = 1, ADLST = 00, ADHSC = 1
8. ADC clock = 12 MHz, ADLSMP = 1, ADLST = 01, ADHSC = 1

### 6.6.1.4 16-bit ADC with PGA characteristics

**Table 31. 16-bit ADC with PGA characteristics**

Symbol	Description	Conditions	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
$I_{\text{DDA\_PGA}}$	Supply current	Low power (ADC_PGA[PGALPb]=0)	—	420	644	$\mu\text{A}$	2
$I_{\text{DC\_PGA}}$	Input DC current		$\frac{2}{R_{\text{PGAD}}} \left( \frac{(V_{\text{REFPGA}} \times 0.583) - V_{\text{CM}}}{(\text{Gain} + 1)} \right)$			A	3
		Gain =1, $V_{\text{REFPGA}}=1.2\text{V}$ , $V_{\text{CM}}=0.5\text{V}$	—	1.54	—	$\mu\text{A}$	
		Gain =64, $V_{\text{REFPGA}}=1.2\text{V}$ , $V_{\text{CM}}=0.1\text{V}$	—	0.57	—	$\mu\text{A}$	
G	Gain <sup>4</sup>	<ul style="list-style-type: none"> <li>• PGAG=0</li> <li>• PGAG=1</li> <li>• PGAG=2</li> <li>• PGAG=3</li> <li>• PGAG=4</li> <li>• PGAG=5</li> <li>• PGAG=6</li> </ul>	0.95	1	1.05		$R_{\text{AS}} < 100\Omega$
BW	Input signal bandwidth	• 16-bit modes	—	—	4	kHz	
		• < 16-bit modes	—	—	40	kHz	

Table continues on the next page...

Table 31. 16-bit ADC with PGA characteristics (continued)

Symbol	Description	Conditions	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
PSRR	Power supply rejection ratio	Gain=1	—	-84	—	dB	V <sub>DDA</sub> = 3V ±100mV, f <sub>VDDA</sub> = 50Hz, 60Hz
CMRR	Common mode rejection ratio	• Gain=1	—	-84	—	dB	V <sub>CM</sub> = 500mV <sub>pp</sub> , f <sub>VCM</sub> = 50Hz, 100Hz
		• Gain=64	—	-85	—	dB	
V <sub>OFS</sub>	Input offset voltage	• Chopping disabled (ADC_PGA[PGACHPb] =1)	—	2.4	—	mV	Output offset = V <sub>OFS</sub> *(Gain+1)
		• Chopping enabled (ADC_PGA[PGACHPb] =0)	—	0.2	—	mV	
T <sub>GSW</sub>	Gain switching settling time		—	—	10	μs	5
dG/dT	Gain drift over full temperature range	• Gain=1	—	6	10	ppm/°C	
		• Gain=64	—	31	42	ppm/°C	
dG/dV <sub>DDA</sub>	Gain drift over supply voltage	• Gain=1	—	0.07	0.21	%/V	V <sub>DDA</sub> from 1.71 to 3.6V
		• Gain=64	—	0.14	0.31	%/V	
E <sub>IL</sub>	Input leakage error	All modes	I <sub>in</sub> × R <sub>AS</sub>			mV	I <sub>in</sub> = leakage current  (refer to the MCU's voltage and current operating ratings)
V <sub>PP,DIFF</sub>	Maximum differential input signal swing		$\left(\frac{(\min(V_x, V_{DDA}-V_x)-0.2) \times 4}{\text{Gain}}\right)$			V	6
			where V <sub>X</sub> = V <sub>REFPGA</sub> × 0.583				
SNR	Signal-to-noise ratio	• Gain=1	80	90	—	dB	16-bit differential mode, Average=32
		• Gain=64	52	66	—	dB	
THD	Total harmonic distortion	• Gain=1	85	100	—	dB	16-bit differential mode, Average=32, f <sub>in</sub> =100Hz
		• Gain=64	49	95	—	dB	
SFDR	Spurious free dynamic range	• Gain=1	85	105	—	dB	16-bit differential mode, Average=32, f <sub>in</sub> =100Hz
		• Gain=64	53	88	—	dB	
ENOB	Effective number of bits	• Gain=1, Average=4	11.6	13.4	—	bits	16-bit differential mode, f <sub>in</sub> =100Hz
		• Gain=1, Average=8	8.0	13.6	—	bits	
		• Gain=64, Average=4	7.2	9.6	—	bits	

Table continues on the next page...

**Table 31. 16-bit ADC with PGA characteristics (continued)**

Symbol	Description	Conditions	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
		<ul style="list-style-type: none"> <li>Gain=64, Average=8</li> <li>Gain=1, Average=32</li> <li>Gain=2, Average=32</li> <li>Gain=4, Average=32</li> <li>Gain=8, Average=32</li> <li>Gain=16, Average=32</li> <li>Gain=32, Average=32</li> <li>Gain=64, Average=32</li> </ul>	6.3	9.6	—	bits	
			12.8	14.5	—	bits	
			11.0	14.3	—	bits	
			7.9	13.8	—	bits	
			7.3	13.1	—	bits	
			6.8	12.5	—	bits	
			6.8	11.5	—	bits	
			7.5	10.6	—	bits	
SINAD	Signal-to-noise plus distortion ratio	See ENOB	6.02 × ENOB + 1.76			dB	

1. Typical values assume  $V_{DDA}=3.0V$ ,  $Temp=25^{\circ}C$ ,  $f_{ADCK}=6MHz$  unless otherwise stated.
2. This current is a PGA module adder, in addition to ADC conversion currents.
3. Between IN+ and IN-. The PGA draws a DC current from the input terminals. The magnitude of the DC current is a strong function of input common mode voltage ( $V_{CM}$ ) and the PGA gain.
4.  $Gain = 2^{PGAG}$
5. After changing the PGA gain setting, a minimum of 2 ADC+PGA conversions should be ignored.
6. Limit the input signal swing so that the PGA does not saturate during operation. Input signal swing is dependent on the PGA reference voltage and gain setting.

## 6.6.2 CMP and 6-bit DAC electrical specifications

**Table 32. Comparator and 6-bit DAC electrical specifications**

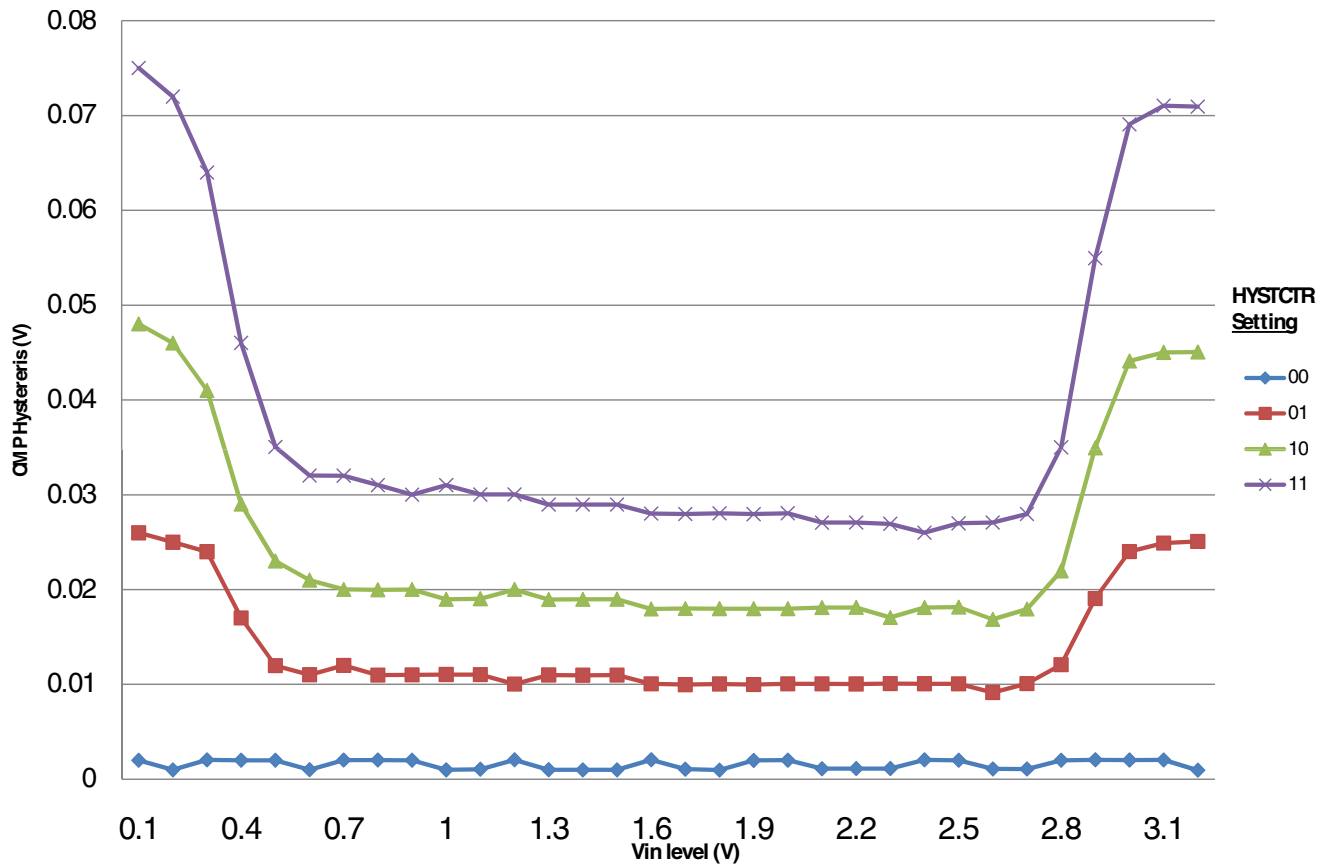
Symbol	Description	Min.	Typ.	Max.	Unit
$V_{DD}$	Supply voltage	1.71	—	3.6	V
$I_{DDHS}$	Supply current, High-speed mode (EN=1, PMODE=1)	—	—	200	$\mu A$
$I_{DDL S}$	Supply current, low-speed mode (EN=1, PMODE=0)	—	—	20	$\mu A$
$V_{AIN}$	Analog input voltage	$V_{SS} - 0.3$	—	$V_{DD}$	V
$V_{AIO}$	Analog input offset voltage	—	—	20	mV
$V_H$	Analog comparator hysteresis <sup>1</sup> <ul style="list-style-type: none"> <li>CR0[HYSTCTR] = 00</li> <li>CR0[HYSTCTR] = 01</li> <li>CR0[HYSTCTR] = 10</li> <li>CR0[HYSTCTR] = 11</li> </ul>	—	5	—	mV
		—	10	—	mV
		—	20	—	mV
		—	30	—	mV
$V_{CMPOH}$	Output high	$V_{DD} - 0.5$	—	—	V
$V_{CMPOI}$	Output low	—	—	0.5	V
$t_{DHS}$	Propagation delay, high-speed mode (EN=1, PMODE=1)	20	50	200	ns
$t_{DLS}$	Propagation delay, low-speed mode (EN=1, PMODE=0)	80	250	600	ns

Table continues on the next page...

**Table 32. Comparator and 6-bit DAC electrical specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit
	Analog comparator initialization delay <sup>2</sup>	—	—	40	μs
I <sub>DAC6b</sub>	6-bit DAC current adder (enabled)	—	7	—	μA
INL	6-bit DAC integral non-linearity	-0.5	—	0.5	LSB <sup>3</sup>
DNL	6-bit DAC differential non-linearity	-0.3	—	0.3	LSB

1. Typical hysteresis is measured with input voltage range limited to 0.6 to V<sub>DD</sub>-0.6 V.
2. Comparator initialization delay is defined as the time between software writes to change control inputs (Writes to CMP\_DACCR[DACEN], CMP\_DACCR[VRSEL], CMP\_DACCR[VOSEL], CMP\_MUXCR[PSEL], and CMP\_MUXCR[MSEL]) and the comparator output settling to a stable level.
3. 1 LSB = V<sub>reference</sub>/64

**Figure 23. Typical hysteresis vs. Vin level (VDD = 3.3 V, PMODE = 0)**

## Peripheral operating requirements and behaviors

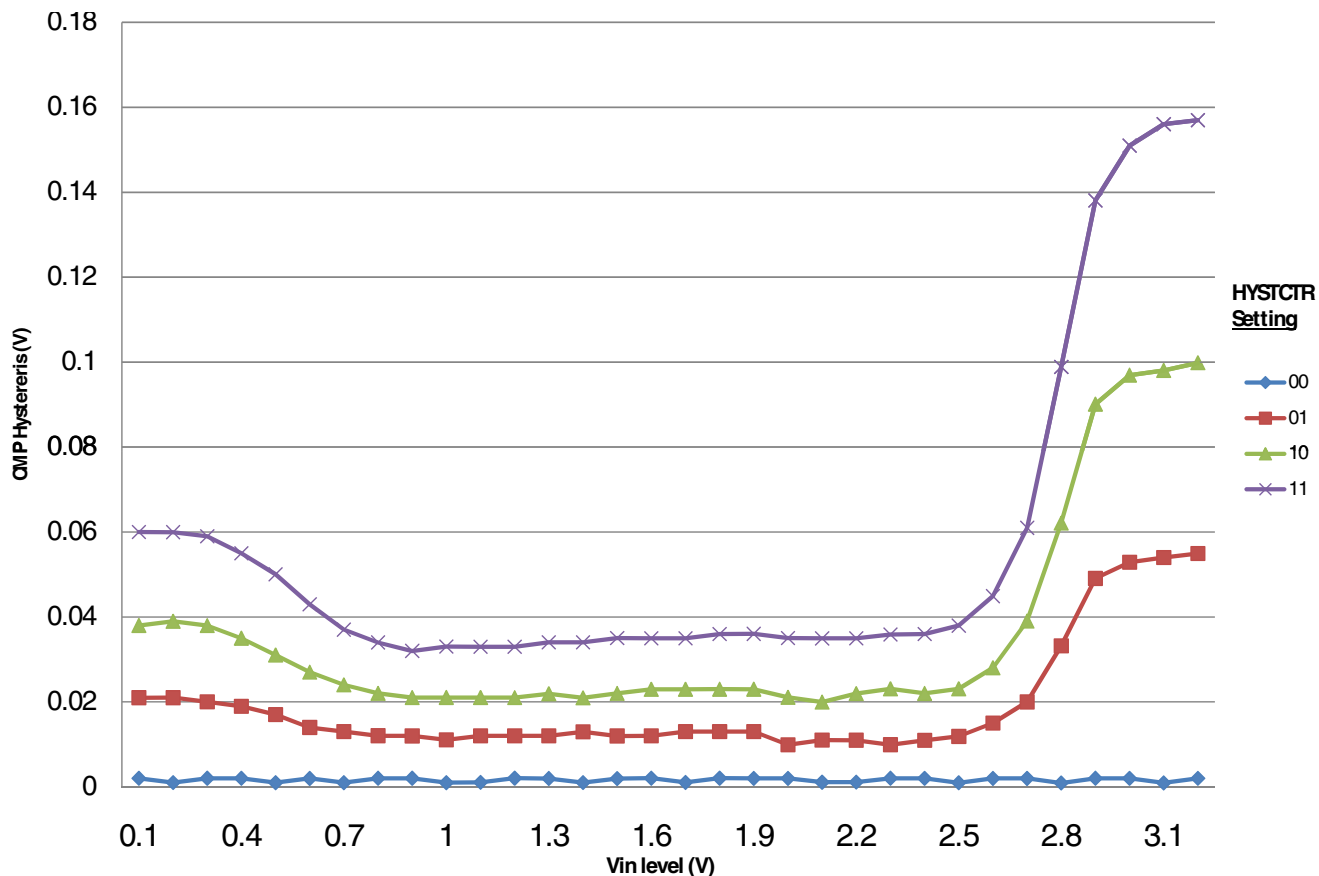


Figure 24. Typical hysteresis vs. Vin level (VDD = 3.3 V, PMODE = 1)

## 6.6.3 12-bit DAC electrical characteristics

### 6.6.3.1 12-bit DAC operating requirements

Table 33. 12-bit DAC operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
$V_{DDA}$	Supply voltage	1.71	3.6	V	
$V_{DACR}$	Reference voltage	1.13	3.6	V	1
$T_A$	Temperature	Operating temperature range of the device		°C	
$C_L$	Output load capacitance	—	100	pF	2
$I_L$	Output load current	—	1	mA	

1. The DAC reference can be selected to be  $V_{DDA}$  or the voltage output of the VREF module (VREF\_OUT)
2. A small load capacitance (47 pF) can improve the bandwidth performance of the DAC



### 6.6.3.2 12-bit DAC operating behaviors

Table 34. 12-bit DAC operating behaviors

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$I_{DDA\_DACLP}$	Supply current — low-power mode	—	—	150	$\mu\text{A}$	
$I_{DDA\_DACHP}$	Supply current — high-speed mode	—	—	700	$\mu\text{A}$	
$t_{DACLP}$	Full-scale settling time (0x080 to 0xF7F) — low-power mode	—	100	200	$\mu\text{s}$	
$t_{DACHP}$	Full-scale settling time (0x080 to 0xF7F) — high-power mode	—	15	30	$\mu\text{s}$	1
$t_{CCDACLP}$	Code-to-code settling time (0xBF8 to 0xC08) — low-power mode and high-speed mode	—	0.7	1	$\mu\text{s}$	1
$V_{dacoutl}$	DAC output voltage range low — high-speed mode, no load, DAC set to 0x000	—	—	100	mV	
$V_{dacouth}$	DAC output voltage range high — high-speed mode, no load, DAC set to 0xFFF	$V_{DACR} - 100$	—	$V_{DACR}$	mV	
INL	Integral non-linearity error — high speed mode	—	—	$\pm 8$	LSB	2
DNL	Differential non-linearity error — $V_{DACR} > 2\text{ V}$	—	—	$\pm 1$	LSB	3
DNL	Differential non-linearity error — $V_{DACR} = V_{REF\_OUT}$	—	—	$\pm 1$	LSB	4
$V_{OFFSET}$	Offset error	—	$\pm 0.4$	$\pm 0.8$	%FSR	
$E_G$	Gain error	—	$\pm 0.1$	$\pm 0.6$	%FSR	5
PSRR	Power supply rejection ratio, $V_{DDA} \geq 2.4\text{ V}$	60	—	90	dB	
$T_{CO}$	Temperature coefficient offset voltage	—	3.7	—	$\mu\text{V}/\text{C}$	
$T_{GE}$	Temperature coefficient gain error	—	0.000421	—	%FSR/C	
$R_{op}$	Output resistance (load = 3 k $\Omega$ )	—	—	250	$\Omega$	
SR	Slew rate -80h → F7Fh → 80h <ul style="list-style-type: none"> <li>High power (<math>SP_{HP}</math>)</li> <li>Low power (<math>SP_{LP}</math>)</li> </ul>	1.2 0.05	1.7 0.12	— —	V/ $\mu\text{s}$	
CT	Channel to channel cross talk	—	—	-80	dB	
BW	3dB bandwidth <ul style="list-style-type: none"> <li>High power (<math>SP_{HP}</math>)</li> <li>Low power (<math>SP_{LP}</math>)</li> </ul>	550 40	— —	— —	kHz	

- Settling within  $\pm 1$  LSB
- The INL is measured for 0 + 100 mV to  $V_{DACR} - 100$  mV
- The DNL is measured for 0 + 100 mV to  $V_{DACR} - 100$  mV
- The DNL is measured for 0 + 100 mV to  $V_{DACR} - 100$  mV with  $V_{DDA} > 2.4\text{ V}$
- Calculated by a best fit curve from  $V_{SS} + 100$  mV to  $V_{DACR} - 100$  mV

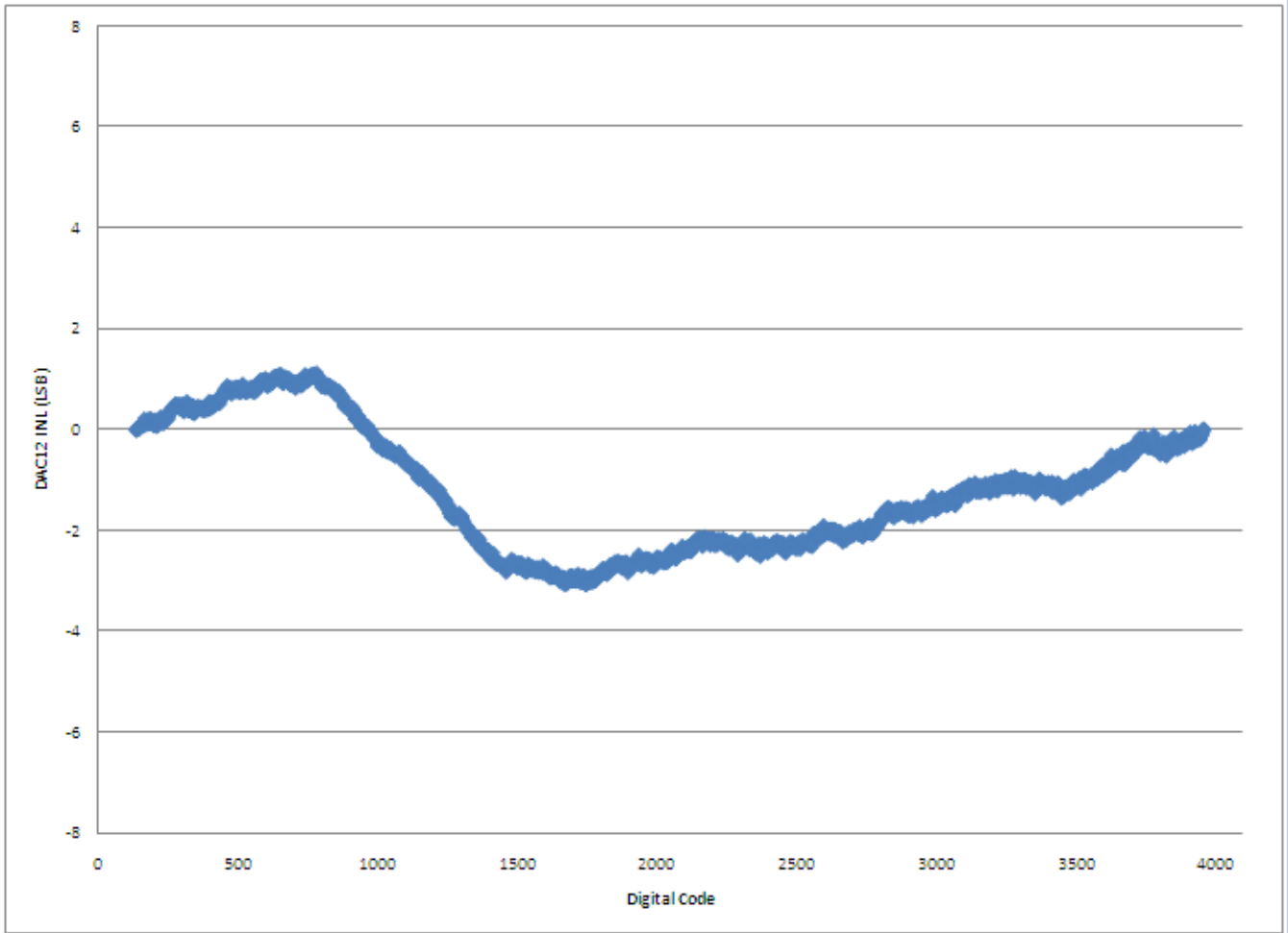


Figure 25. Typical INL error vs. digital code

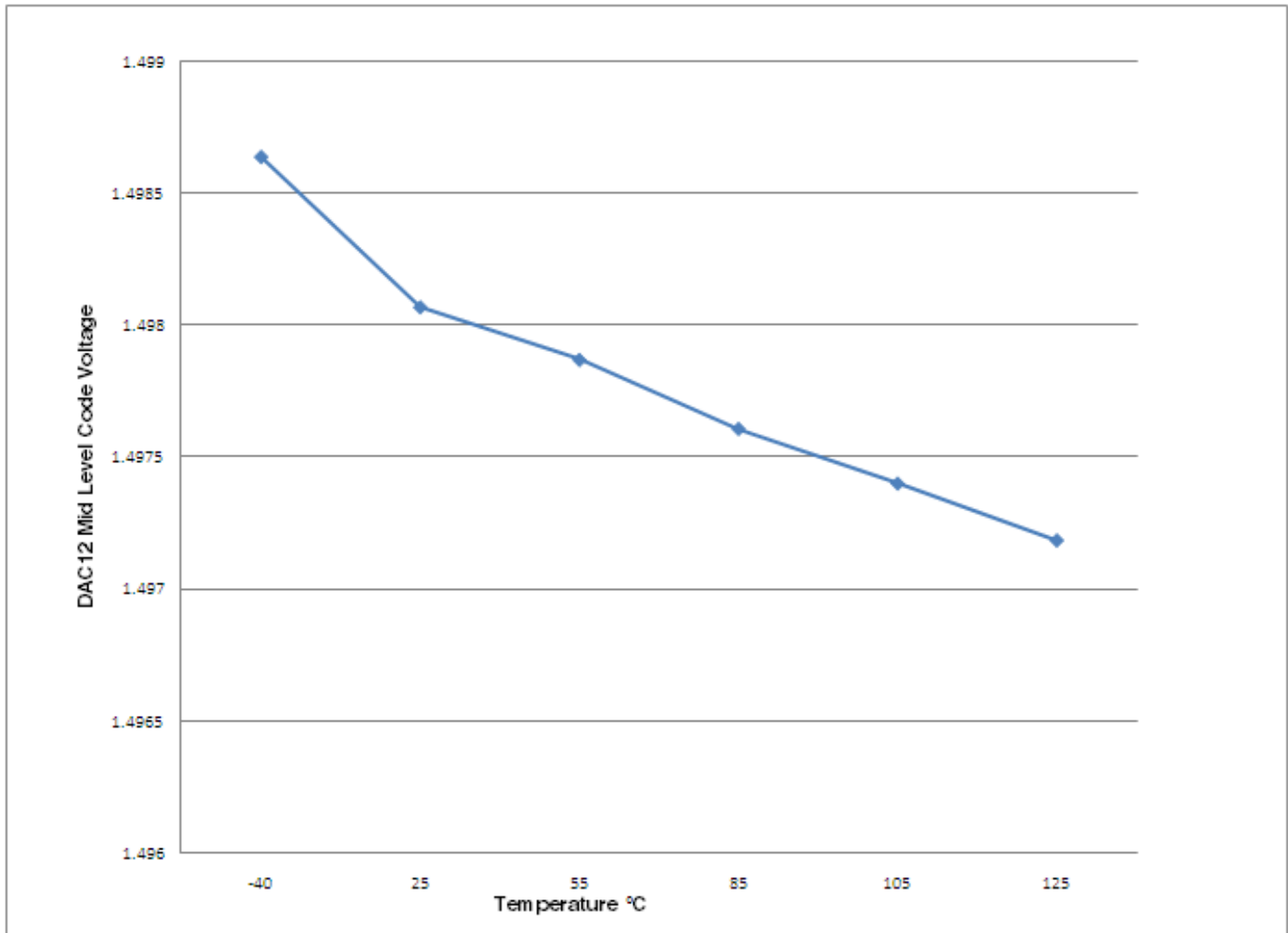


Figure 26. Offset at half scale vs. temperature

## 6.6.4 Voltage reference electrical specifications

Table 35. VREF full-range operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
V <sub>DDA</sub>	Supply voltage	1.71	3.6	V	
T <sub>A</sub>	Temperature	Operating temperature range of the device		°C	
C <sub>L</sub>	Output load capacitance	100		nF	1, 2

1. C<sub>L</sub> must be connected to VREF\_OUT if the VREF\_OUT functionality is being used for either an internal or external reference.
2. The load capacitance should not exceed +/-25% of the nominal specified C<sub>L</sub> value over the operating temperature range of the device.

**Table 36. VREF full-range operating behaviors**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$V_{out}$	Voltage reference output with factory trim at nominal $V_{DDA}$ and temperature=25C	1.1915	1.195	1.1977	V	1
$V_{out}$	Voltage reference output — factory trim	1.1584	—	1.2376	V	1
$V_{out}$	Voltage reference output — user trim	1.193	—	1.197	V	1
$V_{step}$	Voltage reference trim step	—	0.5	—	mV	1
$V_{tdrift}$	Temperature drift ( $V_{max} - V_{min}$ across the full temperature range)	—	—	80	mV	1
$I_{bg}$	Bandgap only current	—	—	80	$\mu$ A	
$I_{hp}$	High-power buffer current	—	—	1	mA	1
$\Delta V_{LOAD}$	Load regulation <ul style="list-style-type: none"> <li>• current = + 1.0 mA</li> <li>• current = - 1.0 mA</li> </ul>	—	2	—	mV	1, 2
$T_{stup}$	Buffer startup time	—	—	100	$\mu$ s	
$V_{vdrift}$	Voltage drift ( $V_{max} - V_{min}$ across the full voltage range)	—	2	—	mV	1

1. See the chip's Reference Manual for the appropriate settings of the VREF Status and Control register.
2. Load regulation voltage is the difference between the VREF\_OUT voltage with no load vs. voltage with defined load

**Table 37. VREF limited-range operating requirements**

Symbol	Description	Min.	Max.	Unit	Notes
$T_A$	Temperature	0	50	$^{\circ}$ C	

**Table 38. VREF limited-range operating behaviors**

Symbol	Description	Min.	Max.	Unit	Notes
$V_{out}$	Voltage reference output with factory trim	1.173	1.225	V	

## 6.7 Timers

See [General switching specifications](#).

## 6.8 Communication interfaces

## 6.8.1 Ethernet switching specifications

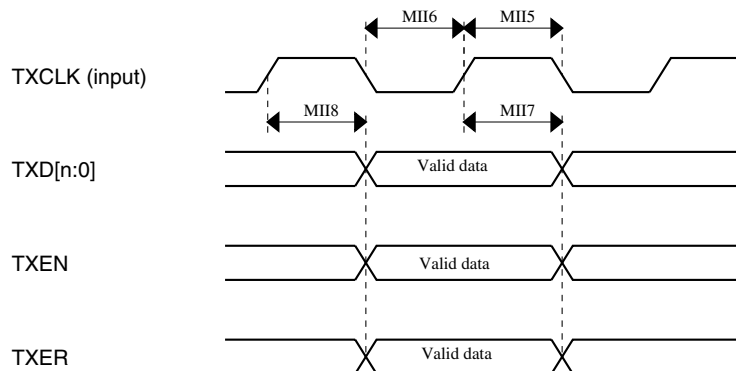
The following timing specs are defined at the chip I/O pin and must be translated appropriately to arrive at timing specs/constraints for the physical interface.

### 6.8.1.1 MII signal switching specifications

The following timing specs meet the requirements for MII style interfaces for a range of transceiver devices.

**Table 39. MII signal switching specifications**

Symbol	Description	Min.	Max.	Unit
—	RXCLK frequency	—	25	MHz
MII1	RXCLK pulse width high	35%	65%	RXCLK period
MII2	RXCLK pulse width low	35%	65%	RXCLK period
MII3	RXD[3:0], RXDV, RXER to RXCLK setup	5	—	ns
MII4	RXCLK to RXD[3:0], RXDV, RXER hold	5	—	ns
—	TXCLK frequency	—	25	MHz
MII5	TXCLK pulse width high	35%	65%	TXCLK period
MII6	TXCLK pulse width low	35%	65%	TXCLK period
MII7	TXCLK to TXD[3:0], TXEN, TXER invalid	2	—	ns
MII8	TXCLK to TXD[3:0], TXEN, TXER valid	—	25	ns



**Figure 27. RMI/MII transmit signal timing diagram**

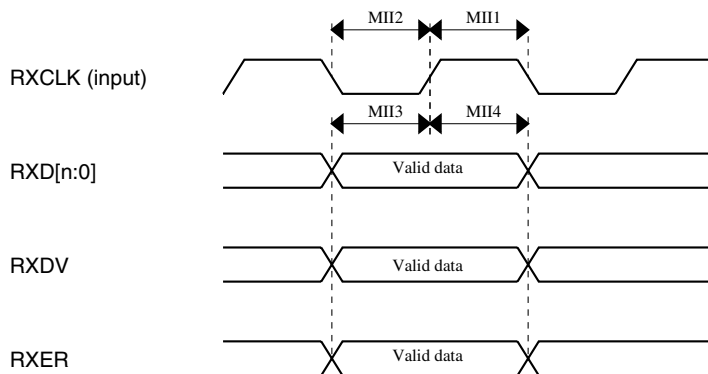


Figure 28. RMII/MII receive signal timing diagram

### 6.8.1.2 RMII signal switching specifications

The following timing specs meet the requirements for RMII style interfaces for a range of transceiver devices.

Table 40. RMII signal switching specifications

Num	Description	Min.	Max.	Unit
—	EXTAL frequency (RMII input clock RMII_CLK)	—	50	MHz
RMII1	RMII_CLK pulse width high	35%	65%	RMII_CLK period
RMII2	RMII_CLK pulse width low	35%	65%	RMII_CLK period
RMII3	RXD[1:0], CRS_DV, RXER to RMII_CLK setup	4	—	ns
RMII4	RMII_CLK to RXD[1:0], CRS_DV, RXER hold	2	—	ns
RMII7	RMII_CLK to TXD[1:0], TXEN invalid	4	—	ns
RMII8	RMII_CLK to TXD[1:0], TXEN valid	—	15	ns

### 6.8.2 USB electrical specifications

The USB electricals for the USB On-the-Go module conform to the standards documented by the Universal Serial Bus Implementers Forum. For the most up-to-date standards, visit [usb.org](http://usb.org).

### 6.8.3 USB DCD electrical specifications

Table 41. USB DCD electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit
V <sub>DP_SRC</sub>	USB_DP source voltage (up to 250 $\mu$ A)	0.5	—	0.7	V
V <sub>LGC</sub>	Threshold voltage for logic high	0.8	—	2.0	V
I <sub>DP_SRC</sub>	USB_DP source current	7	10	13	$\mu$ A
I <sub>DM_SINK</sub>	USB_DM sink current	50	100	150	$\mu$ A
R <sub>DM_DWN</sub>	D- pulldown resistance for data pin contact detect	14.25	—	24.8	k $\Omega$
V <sub>DAT_REF</sub>	Data detect voltage	0.25	0.325	0.4	V

### 6.8.4 USB VREG electrical specifications

Table 42. USB VREG electrical specifications

Symbol	Description	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
V <sub>REGIN</sub>	Input supply voltage	2.7	—	5.5	V	
I <sub>DDon</sub>	Quiescent current — Run mode, load current equal zero, input supply (V <sub>REGIN</sub> ) > 3.6 V	—	125	186	$\mu$ A	
I <sub>DDstby</sub>	Quiescent current — Standby mode, load current equal zero	—	1.1	10	$\mu$ A	
I <sub>DDoff</sub>	Quiescent current — Shutdown mode <ul style="list-style-type: none"> <li>V<sub>REGIN</sub> = 5.0 V and temperature=25 °C</li> <li>Across operating voltage and temperature</li> </ul>	—	650	—	nA	
		—	—	4	$\mu$ A	
I <sub>LOADrun</sub>	Maximum load current — Run mode	—	—	120	mA	
I <sub>LOADstby</sub>	Maximum load current — Standby mode	—	—	1	mA	
V <sub>Reg33out</sub>	Regulator output voltage — Input supply (V <sub>REGIN</sub> ) > 3.6 V <ul style="list-style-type: none"> <li>Run mode</li> <li>Standby mode</li> </ul>	3	3.3	3.6	V	
		2.1	2.8	3.6	V	
V <sub>Reg33out</sub>	Regulator output voltage — Input supply (V <sub>REGIN</sub> ) < 3.6 V, pass-through mode	2.1	—	3.6	V	3
C <sub>OUT</sub>	External output capacitor	1.76	2.2	8.16	$\mu$ F	
ESR	External output capacitor equivalent series resistance	1	—	100	m $\Omega$	
I <sub>LIM</sub>	Short circuit current	—	290	—	mA	

1. Typical values assume V<sub>REGIN</sub> = 5.0 V, Temp = 25 °C unless otherwise stated.

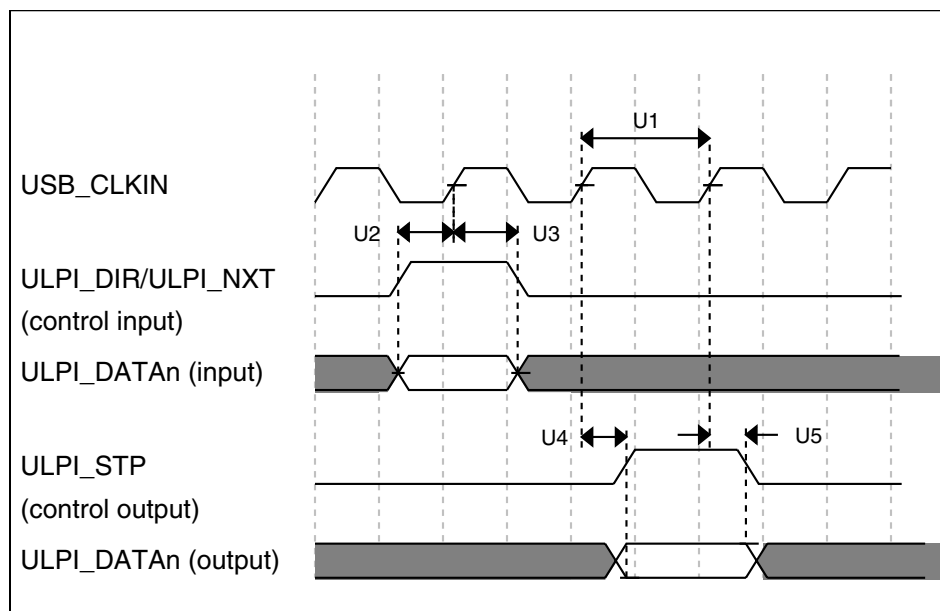
3. Operating in pass-through mode: regulator output voltage equal to the input voltage minus a drop proportional to I<sub>Load</sub>.

## 6.8.5 ULPI timing specifications

The ULPI interface is fully compliant with the industry standard UTMI+ Low Pin Interface. Control and data timing requirements for the ULPI pins are given in the following table. These timings apply to synchronous mode only. All timings are measured with respect to the clock as seen at the USB\_CLKIN pin.

**Table 43. ULPI timing specifications**

Num	Description	Min.	Typ.	Max.	Unit
	USB_CLKIN operating frequency	—	60	—	MHz
	USB_CLKIN duty cycle	—	50	—	%
U1	USB_CLKIN clock period	—	16.67	—	ns
U2	Input setup (control and data)	5	—	—	ns
U3	Input hold (control and data)	1	—	—	ns
U4	Output valid (control and data)	—	—	9.5	ns
U5	Output hold (control and data)	1	—	—	ns



**Figure 29. ULPI timing diagram**



## 6.8.6 CAN switching specifications

See [General switching specifications](#).

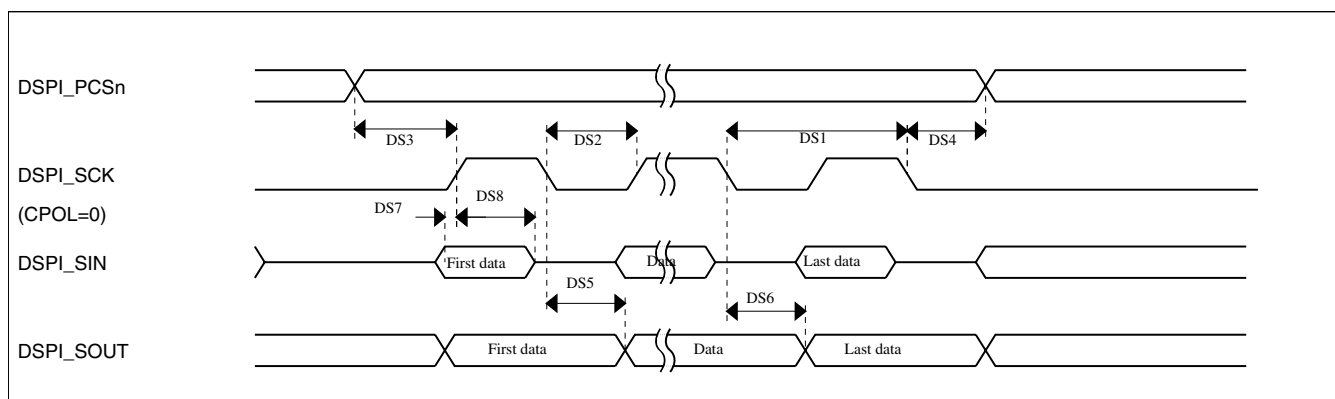
## 6.8.7 DSPI switching specifications (limited voltage range)

The DMA Serial Peripheral Interface (DSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The tables below provide DSPI timing characteristics for classic SPI timing modes. Refer to the DSPI chapter of the Reference Manual for information on the modified transfer formats used for communicating with slower peripheral devices.

**Table 44. Master mode DSPI timing (limited voltage range)**

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	2.7	3.6	V	
	Frequency of operation	—	30	MHz	
DS1	DSPI_SCK output cycle time	$2 \times t_{BUS}$	—	ns	
DS2	DSPI_SCK output high/low time	$(t_{SCK}/2) - 2$	$(t_{SCK}/2) + 2$	ns	
DS3	DSPI_PCS <sub>n</sub> valid to DSPI_SCK delay	$(t_{BUS} \times 2) - 2$	—	ns	1
DS4	DSPI_SCK to DSPI_PCS <sub>n</sub> invalid delay	$(t_{BUS} \times 2) - 2$	—	ns	2
DS5	DSPI_SCK to DSPI_SOUT valid	—	8.5	ns	
DS6	DSPI_SCK to DSPI_SOUT invalid	-2	—	ns	
DS7	DSPI_SIN to DSPI_SCK input setup	15	—	ns	
DS8	DSPI_SCK to DSPI_SIN input hold	0	—	ns	

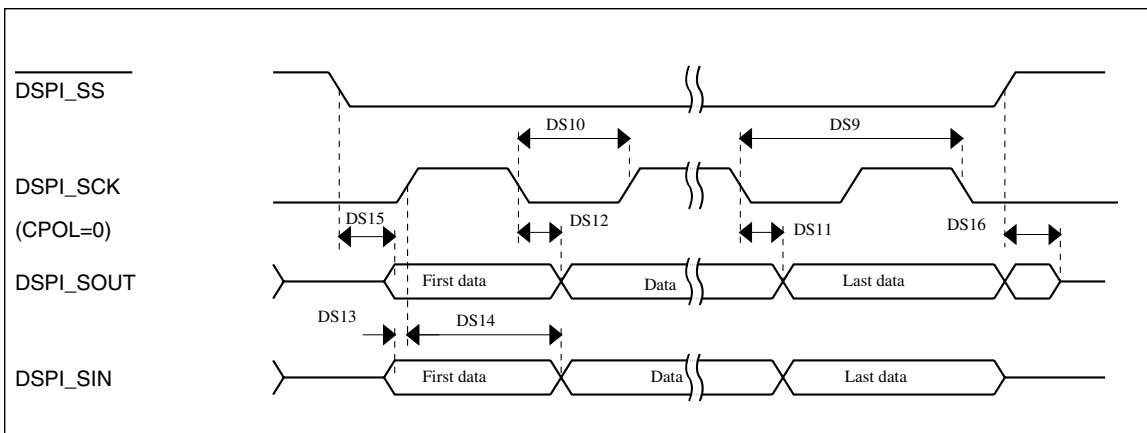
1. The delay is programmable in SPIx\_CTARN[PSSCK] and SPIx\_CTARN[CSSCK].
2. The delay is programmable in SPIx\_CTARN[PASC] and SPIx\_CTARN[ASC].



**Figure 30. DSPI classic SPI timing — master mode**

**Table 45. Slave mode DSPI timing (limited voltage range)**

Num	Description	Min.	Max.	Unit
	Operating voltage	2.7	3.6	V
	Frequency of operation		15	MHz
DS9	DSPI_SCK input cycle time	4 x t <sub>BUS</sub>	—	ns
DS10	DSPI_SCK input high/low time	(t <sub>SCK</sub> /2) - 2	(t <sub>SCK</sub> /2) + 2	ns
DS11	DSPI_SCK to DSPI_SOUT valid	—	10	ns
DS12	DSPI_SCK to DSPI_SOUT invalid	0	—	ns
DS13	DSPI_SIN to DSPI_SCK input setup	2	—	ns
DS14	DSPI_SCK to DSPI_SIN input hold	7	—	ns
DS15	DSPI_SS active to DSPI_SOUT driven	—	14	ns
DS16	DSPI_SS inactive to DSPI_SOUT not driven	—	14	ns



**Figure 31. DSPI classic SPI timing — slave mode**

### 6.8.8 DSPI switching specifications (full voltage range)

The DMA Serial Peripheral Interface (DSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The tables below provides DSPI timing characteristics for classic SPI timing modes. Refer to the DSPI chapter of the Reference Manual for information on the modified transfer formats used for communicating with slower peripheral devices.

**Table 46. Master mode DSPI timing (full voltage range)**

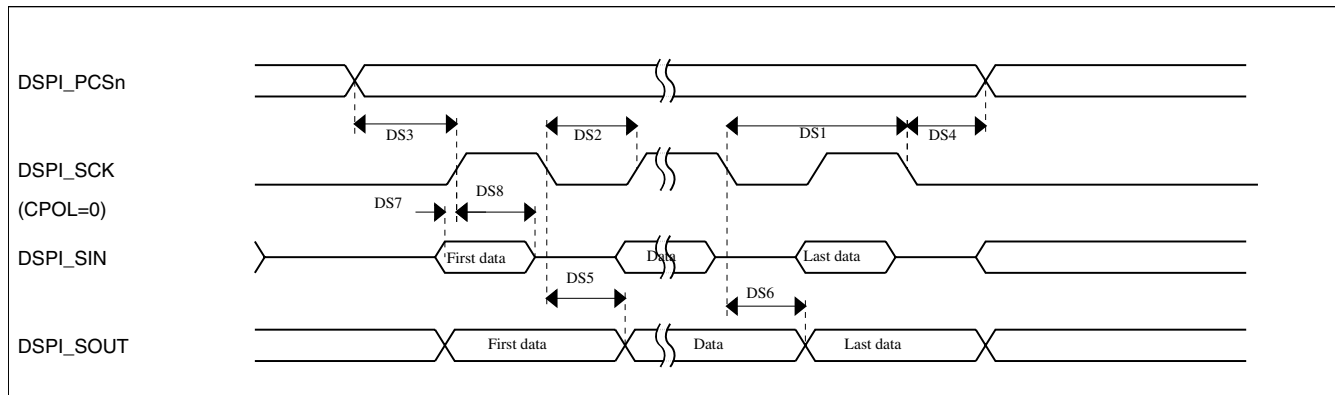
Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	1.71	3.6	V	1
	Frequency of operation	—	15	MHz	
DS1	DSPI_SCK output cycle time	4 x t <sub>BUS</sub>	—	ns	

Table continues on the next page...

**Table 46. Master mode DSPI timing (full voltage range) (continued)**

Num	Description	Min.	Max.	Unit	Notes
DS2	DSPI_SCK output high/low time	$(t_{SCK/2}) - 4$	$(t_{SCK/2}) + 4$	ns	
DS3	DSPI_PCSn valid to DSPI_SCK delay	$(t_{BUS} \times 2) - 4$	—	ns	2
DS4	DSPI_SCK to DSPI_PCSn invalid delay	$(t_{BUS} \times 2) - 4$	—	ns	3
DS5	DSPI_SCK to DSPI_SOUT valid	—	10	ns	
DS6	DSPI_SCK to DSPI_SOUT invalid	-4.5	—	ns	
DS7	DSPI_SIN to DSPI_SCK input setup	20.5	—	ns	
DS8	DSPI_SCK to DSPI_SIN input hold	0	—	ns	

1. The DSPI module can operate across the entire operating voltage for the processor, but to run across the full voltage range the maximum frequency of operation is reduced.
2. The delay is programmable in SPIx\_CTARn[PSSCK] and SPIx\_CTARn[CSSCK].
3. The delay is programmable in SPIx\_CTARn[PASC] and SPIx\_CTARn[ASC].

**Figure 32. DSPI classic SPI timing — master mode****Table 47. Slave mode DSPI timing (full voltage range)**

Num	Description	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
	Frequency of operation	—	7.5	MHz
DS9	DSPI_SCK input cycle time	$8 \times t_{BUS}$	—	ns
DS10	DSPI_SCK input high/low time	$(t_{SCK/2}) - 4$	$(t_{SCK/2}) + 4$	ns
DS11	DSPI_SCK to DSPI_SOUT valid	—	20	ns
DS12	DSPI_SCK to DSPI_SOUT invalid	0	—	ns
DS13	DSPI_SIN to DSPI_SCK input setup	2	—	ns
DS14	DSPI_SCK to DSPI_SIN input hold	7	—	ns
DS15	$\overline{DSPI\_SS}$ active to DSPI_SOUT driven	—	19	ns
DS16	$\overline{DSPI\_SS}$ inactive to DSPI_SOUT not driven	—	19	ns

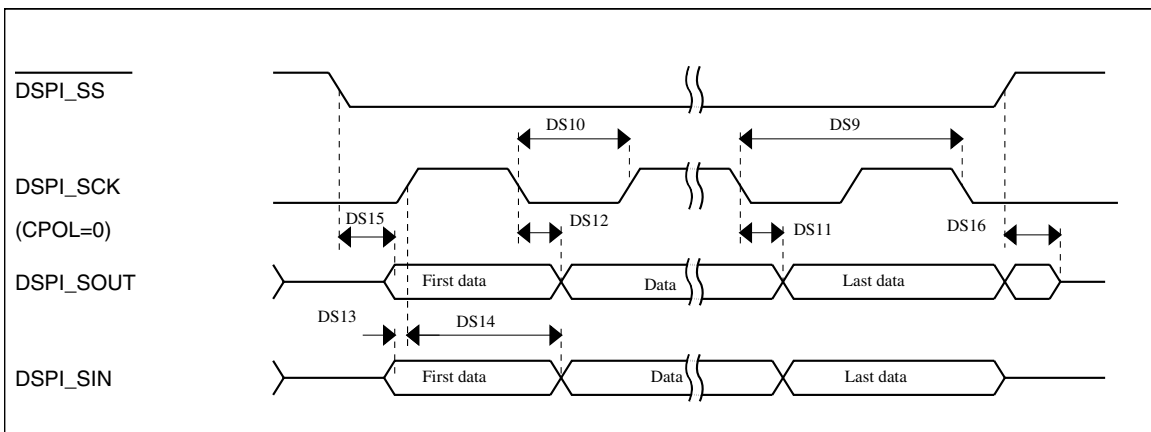


Figure 33. DSPI classic SPI timing — slave mode

### 6.8.9 Inter-Integrated Circuit Interface (I<sup>2</sup>C) timing

Table 48. I<sup>2</sup>C timing

Characteristic	Symbol	Standard Mode		Fast Mode		Unit
		Minimum	Maximum	Minimum	Maximum	
SCL Clock Frequency	$f_{SCL}$	0	100	0	400	kHz
Hold time (repeated) START condition. After this period, the first clock pulse is generated.	$t_{HD}; STA$	4	—	0.6	—	$\mu s$
LOW period of the SCL clock	$t_{LOW}$	4.7	—	1.3	—	$\mu s$
HIGH period of the SCL clock	$t_{HIGH}$	4	—	0.6	—	$\mu s$
Set-up time for a repeated START condition	$t_{SU}; STA$	4.7	—	0.6	—	$\mu s$
Data hold time for I <sup>2</sup> C bus devices	$t_{HD}; DAT$	0	3.45	0	0.9 <sup>1</sup>	$\mu s$
Data set-up time	$t_{SU}; DAT$	250	—	100 <sup>2</sup>	—	ns
Rise time of SDA and SCL signals	$t_r$	—	1000	$20 + 0.1C_b$ <sup>6</sup>	300	ns
Fall time of SDA and SCL signals	$t_f$	—	300	$20 + 0.1C_b$ <sup>3</sup>	300	ns
Set-up time for STOP condition	$t_{SU}; STO$	4	—	0.6	—	$\mu s$
Bus free time between STOP and START condition	$t_{BUF}$	4.7	—	1.3	—	$\mu s$
Pulse width of spikes that must be suppressed by the input filter	$t_{SP}$	N/A	N/A	0	50	ns

1. The master mode I<sup>2</sup>C deasserts ACK of an address byte simultaneously with the falling edge of SCL. If no slaves acknowledge this address byte, then a negative hold time can result, depending on the edge rates of the SDA and SCL lines.
2. The maximum  $t_{HD}; DAT$  must be met only if the device does not stretch the LOW period ( $t_{LOW}$ ) of the SCL signal.
3. A Fast mode I<sup>2</sup>C bus device can be used in a Standard mode I<sup>2</sup>C bus system, but the requirement  $t_{SU}; DAT \geq 250$  ns must then be met. This is automatically the case if the device does not stretch the LOW period of the SCL signal. If such a device does stretch the LOW period of the SCL signal, then it must output the next data bit to the SDA line  $t_{rmax} + t_{SU}; DAT = 1000 + 250 = 1250$  ns (according to the Standard mode I<sup>2</sup>C bus specification) before the SCL line is released.
4.  $C_b$  = total capacitance of the one bus line in pF.

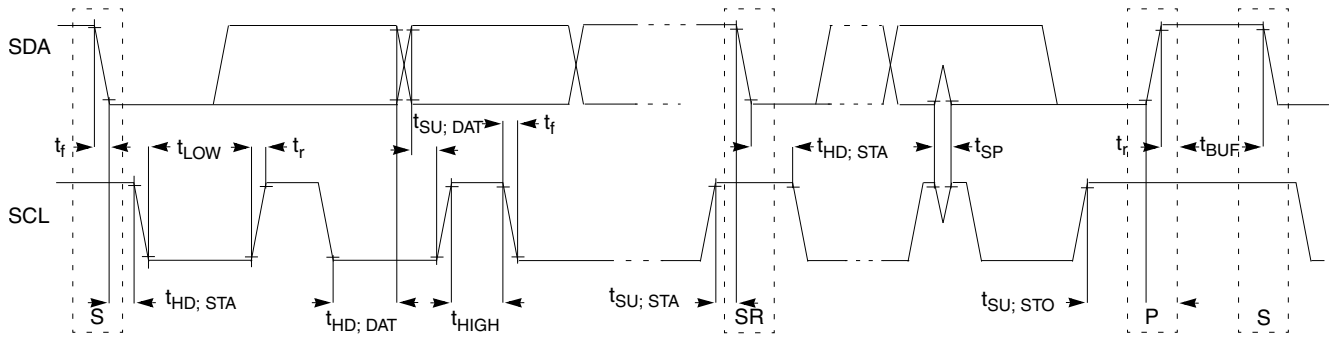


Figure 34. Timing definition for fast and standard mode devices on the I<sup>2</sup>C bus

## 6.8.10 UART switching specifications

See [General switching specifications](#).

## 6.8.11 SDHC specifications

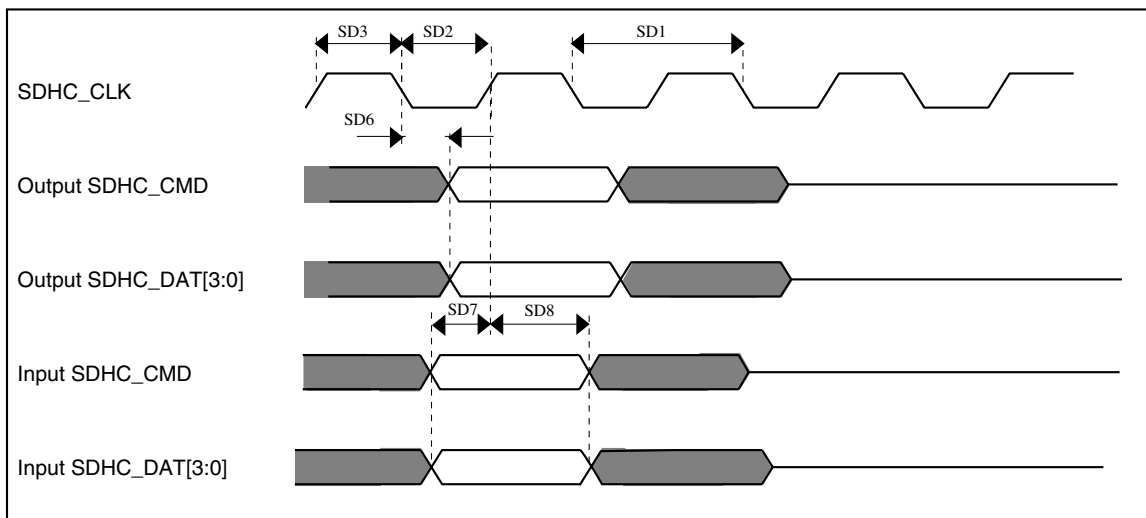
The following timing specs are defined at the chip I/O pin and must be translated appropriately to arrive at timing specs/constraints for the physical interface.

Table 49. SDHC switching specifications over a limited operating voltage range

Num	Symbol	Description	Min.	Max.	Unit
		Operating voltage	2.7	3.6	V
<b>Card input clock</b>					
SD1	f <sub>pp</sub>	Clock frequency (low speed)	0	400	kHz
	f <sub>pp</sub>	Clock frequency (SD\SDIO full speed\high speed)	0	25\50	MHz
	f <sub>pp</sub>	Clock frequency (MMC full speed\high speed)	0	20\50	MHz
	f <sub>OD</sub>	Clock frequency (identification mode)	0	400	kHz
SD2	t <sub>WL</sub>	Clock low time	7	—	ns
SD3	t <sub>WH</sub>	Clock high time	7	—	ns
SD4	t <sub>TLH</sub>	Clock rise time	—	3	ns
SD5	t <sub>THL</sub>	Clock fall time	—	3	ns
<b>SDHC output / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)</b>					
SD6	t <sub>OD</sub>	SDHC output delay (output valid)	-5	6.5	ns
<b>SDHC input / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)</b>					
SD7	t <sub>ISU</sub>	SDHC input setup time	5	—	ns
SD8	t <sub>IH</sub>	SDHC input hold time	0	—	ns

**Table 50. SDHC switching specifications over the full operating voltage range**

Num	Symbol	Description	Min.	Max.	Unit
		Operating voltage	1.71	3.6	V
<b>Card input clock</b>					
SD1	fpp	Clock frequency (low speed)	0	400	kHz
	fpp	Clock frequency (SD\SDIO full speed\high speed)	0	25\50	MHz
	fpp	Clock frequency (MMC full speed\high speed)	0	20\50	MHz
	f <sub>OD</sub>	Clock frequency (identification mode)	0	400	kHz
SD2	t <sub>WL</sub>	Clock low time	7	—	ns
SD3	t <sub>WH</sub>	Clock high time	7	—	ns
SD4	t <sub>TLH</sub>	Clock rise time	—	3	ns
SD5	t <sub>THL</sub>	Clock fall time	—	3	ns
<b>SDHC output / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)</b>					
SD6	t <sub>OD</sub>	SDHC output delay (output valid)	-5	6.5	ns
<b>SDHC input / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)</b>					
SD7	t <sub>ISU</sub>	SDHC input setup time	5	—	ns
SD8	t <sub>IH</sub>	SDHC input hold time	1.3	—	ns



**Figure 35. SDHC timing**

### 6.8.12 I2S/SAI switching specifications

This section provides the AC timing for the I2S/SAI module in master mode (clocks are driven) and slave mode (clocks are input). All timing is given for noninverted serial clock polarity (TCR2[BCP] is 0, RCR2[BCP] is 0) and a noninverted frame sync (TCR4[FSP]

is 0, RCR4[FSP] is 0). If the polarity of the clock and/or the frame sync have been inverted, all the timing remains valid by inverting the bit clock signal (BCLK) and/or the frame sync (FS) signal shown in the following figures.

### 6.8.12.1 Normal Run, Wait and Stop mode performance over a limited operating voltage range

This section provides the operating performance over a limited operating voltage for the device in Normal Run, Wait and Stop modes.

**Table 51. I2S/SAI master mode timing in Normal Run, Wait and Stop modes (limited voltage range)**

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	2.7	3.6	V
S1	I2S_MCLK cycle time	40	—	ns
S2	I2S_MCLK pulse width high/low	45%	55%	MCLK period
S3	I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)	80	—	ns
S4	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low	45%	55%	BCLK period
S5	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid	—	15	ns
S6	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid	0	—	ns
S7	I2S_TX_BCLK to I2S_TXD valid	—	15	ns
S8	I2S_TX_BCLK to I2S_TXD invalid	0	—	ns
S9	I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK	15	—	ns
S10	I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK	0	—	ns

Peripheral operating requirements and behaviors

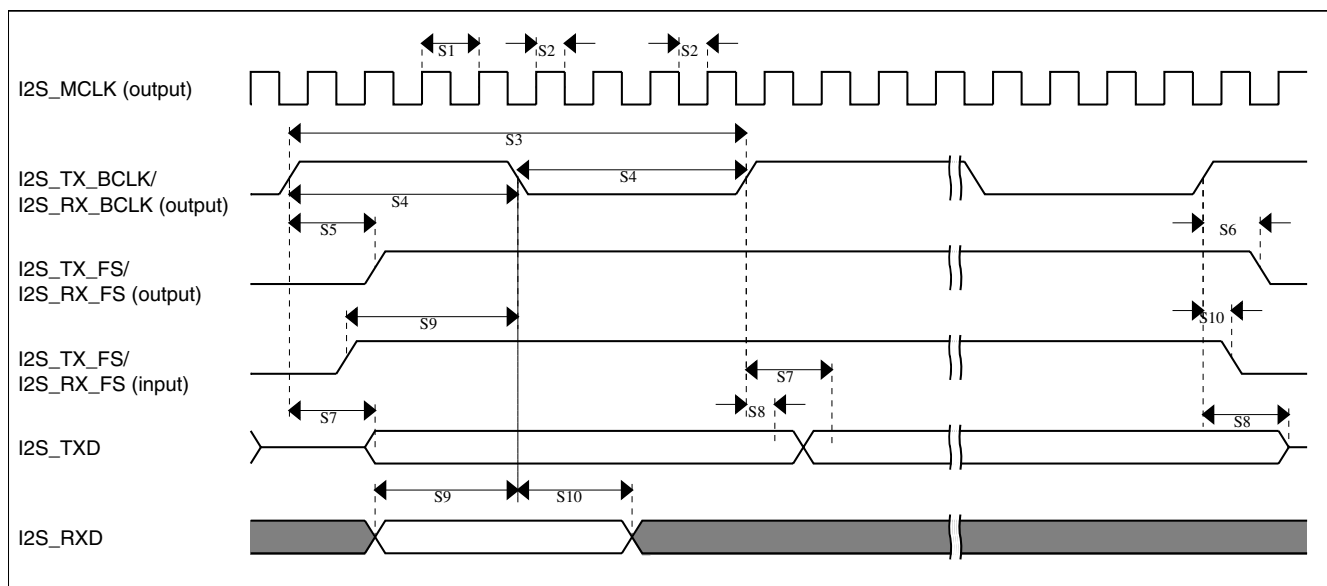


Figure 36. I2S/SAI timing — master modes

Table 52. I2S/SAI slave mode timing in Normal Run, Wait and Stop modes (limited voltage range)

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	2.7	3.6	V
S11	I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)	80	—	ns
S12	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input)	45%	55%	MCLK period
S13	I2S_TX_FS/I2S_RX_FS input setup before I2S_TX_BCLK/I2S_RX_BCLK	4.5	—	ns
S14	I2S_TX_FS/I2S_RX_FS input hold after I2S_TX_BCLK/I2S_RX_BCLK	2	—	ns
S15	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid <ul style="list-style-type: none"> <li>• Multiple SAI Synchronous mode</li> <li>• All other modes</li> </ul>	—	21 15	ns
S16	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid	0	—	ns
S17	I2S_RXD setup before I2S_RX_BCLK	4.5	—	ns
S18	I2S_RXD hold after I2S_RX_BCLK	2	—	ns
S19	I2S_TX_FS input assertion to I2S_TXD output valid <sup>1</sup>	—	25	ns

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear



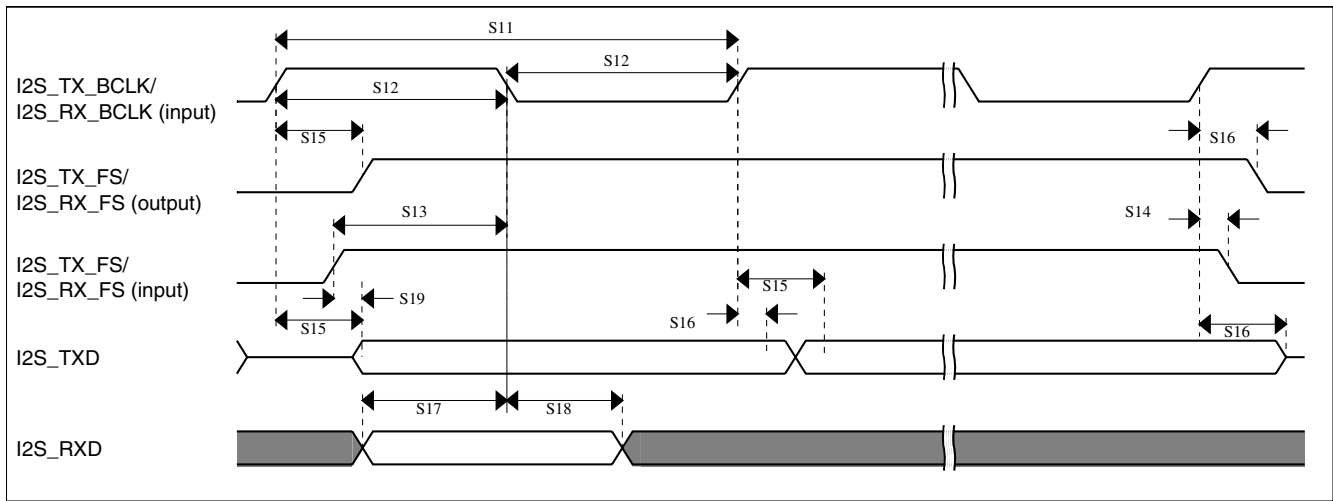


Figure 37. I2S/SAI timing — slave modes

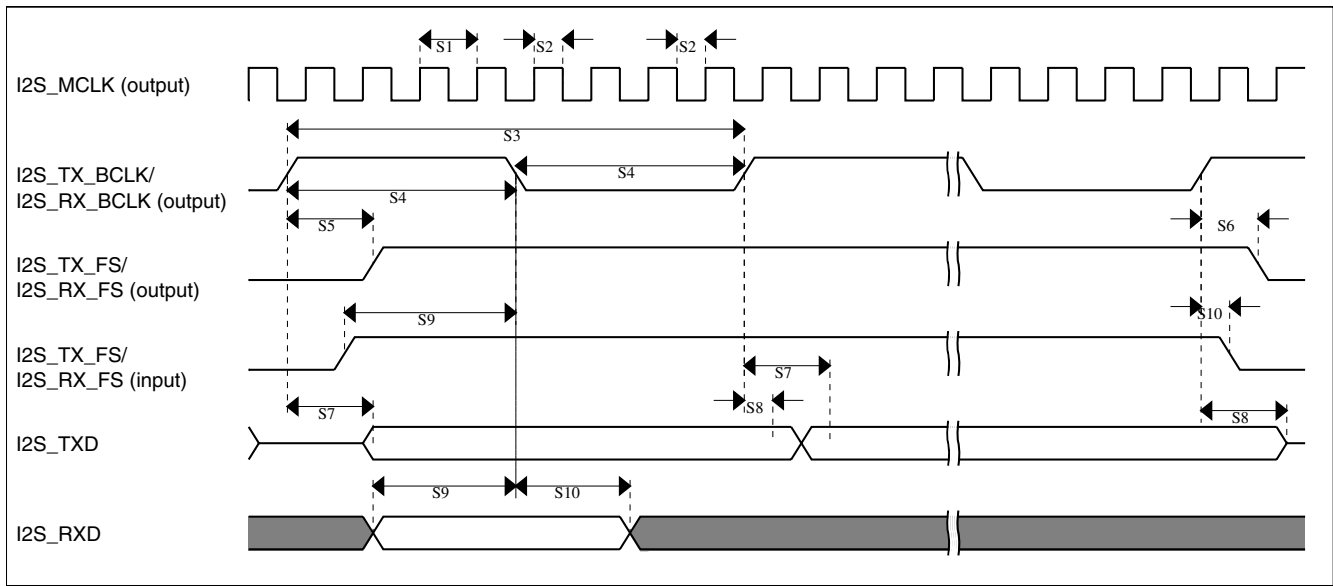
### 6.8.12.2 Normal Run, Wait and Stop mode performance over the full operating voltage range

This section provides the operating performance over the full operating voltage for the device in Normal Run, Wait and Stop modes.

Table 53. I2S/SAI master mode timing in Normal Run, Wait and Stop modes (full voltage range)

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S1	I2S_MCLK cycle time	40	—	ns
S2	I2S_MCLK pulse width high/low	45%	55%	MCLK period
S3	I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)	80	—	ns
S4	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low	45%	55%	BCLK period
S5	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid	—	15	ns
S6	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid	-1.0	—	ns
S7	I2S_TX_BCLK to I2S_TXD valid	—	15	ns
S8	I2S_TX_BCLK to I2S_TXD invalid	0	—	ns
S9	I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK	20.5	—	ns
S10	I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK	0	—	ns

## Peripheral operating requirements and behaviors



**Figure 38. I2S/SAI timing — master modes**

**Table 54. I2S/SAI slave mode timing in Normal Run, Wait and Stop modes (full voltage range)**

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S11	I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)	80	—	ns
S12	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input)	45%	55%	MCLK period
S13	I2S_TX_FS/I2S_RX_FS input setup before I2S_TX_BCLK/I2S_RX_BCLK	5.8	—	ns
S14	I2S_TX_FS/I2S_RX_FS input hold after I2S_TX_BCLK/I2S_RX_BCLK	2	—	ns
S15	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid <ul style="list-style-type: none"> <li>Multiple SAI Synchronous mode</li> <li>All other modes</li> </ul>	—	24 20.6	ns
S16	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid	0	—	ns
S17	I2S_RXD setup before I2S_RX_BCLK	5.8	—	ns
S18	I2S_RXD hold after I2S_RX_BCLK	2	—	ns
S19	I2S_TX_FS input assertion to I2S_TXD output valid <sup>1</sup>	—	25	ns

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear

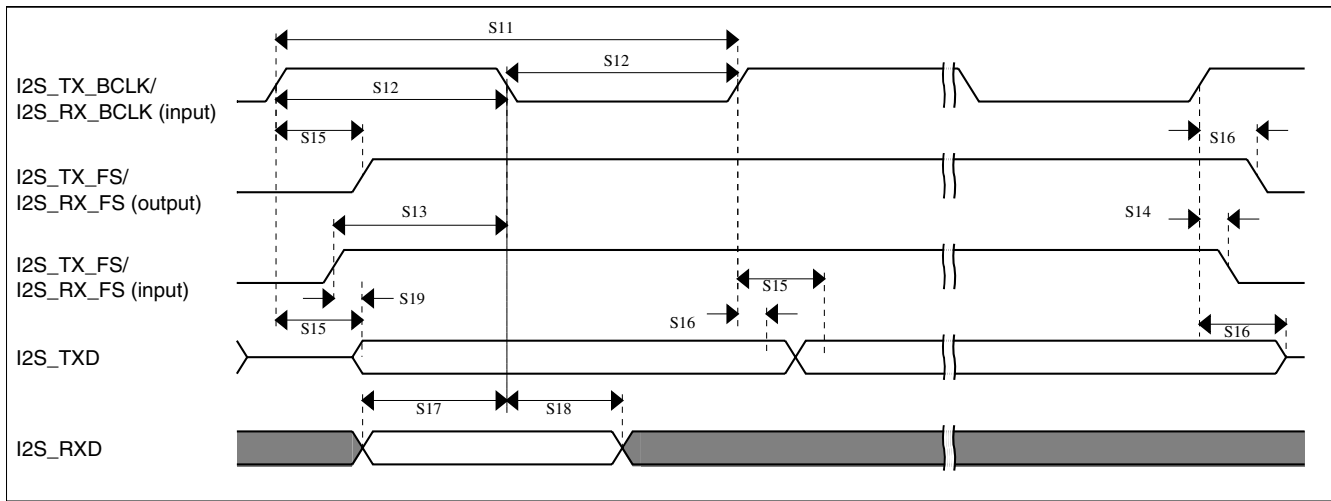


Figure 39. I2S/SAI timing — slave modes

### 6.8.12.3 VLPR, VLPW, and VLPS mode performance over the full operating voltage range

This section provides the operating performance over the full operating voltage for the device in VLPR, VLPW, and VLPS modes.

Table 55. I2S/SAI master mode timing in VLPR, VLPW, and VLPS modes (full voltage range)

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S1	I2S_MCLK cycle time	62.5	—	ns
S2	I2S_MCLK pulse width high/low	45%	55%	MCLK period
S3	I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)	250	—	ns
S4	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low	45%	55%	BCLK period
S5	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid	—	45	ns
S6	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid	0	—	ns
S7	I2S_TX_BCLK to I2S_TXD valid	—	45	ns
S8	I2S_TX_BCLK to I2S_TXD invalid	-1.6	—	ns
S9	I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK	45	—	ns
S10	I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK	0	—	ns

## Peripheral operating requirements and behaviors

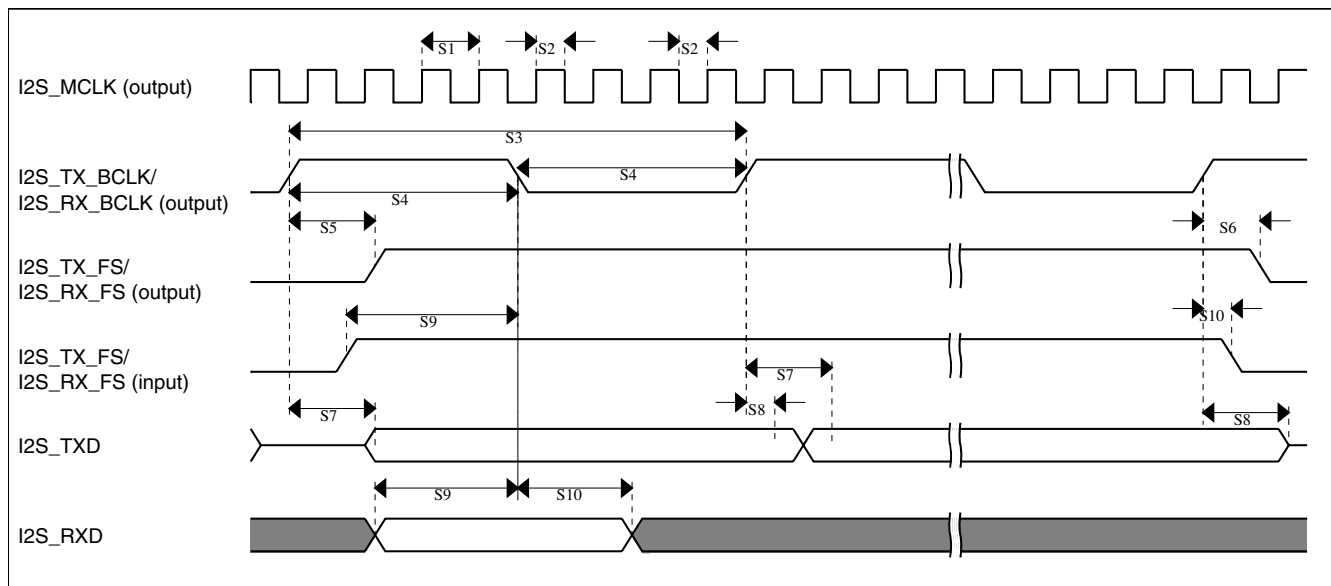


Figure 40. I2S/SAI timing — master modes

Table 56. I2S/SAI slave mode timing in VLPR, VLPW, and VLPS modes (full voltage range)

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S11	I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)	250	—	ns
S12	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input)	45%	55%	MCLK period
S13	I2S_TX_FS/I2S_RX_FS input setup before I2S_TX_BCLK/I2S_RX_BCLK	30	—	ns
S14	I2S_TX_FS/I2S_RX_FS input hold after I2S_TX_BCLK/I2S_RX_BCLK	3	—	ns
S15	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid	—	63	ns
S16	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid	0	—	ns
S17	I2S_RXD setup before I2S_RX_BCLK	30	—	ns
S18	I2S_RXD hold after I2S_RX_BCLK	2	—	ns
S19	I2S_TX_FS input assertion to I2S_TXD output valid <sup>1</sup>	—	72	ns

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear

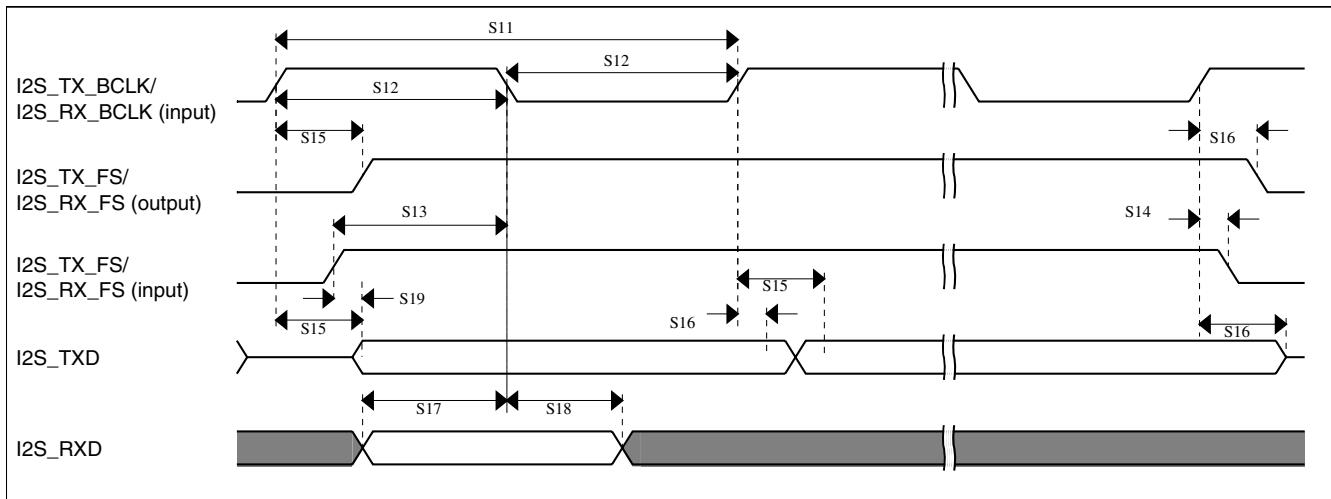


Figure 41. I2S/SAI timing — slave modes

## 6.9 Human-machine interfaces (HMI)

### 6.9.1 TSI electrical specifications

Table 57. TSI electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V <sub>DDTSI</sub>	Operating voltage	1.71	—	3.6	V	
C <sub>ELE</sub>	Target electrode capacitance range	1	20	500	pF	1
f <sub>REFmax</sub>	Reference oscillator frequency	—	8	15	MHz	3
f <sub>ELEmax</sub>	Electrode oscillator frequency	—	1	1.8	MHz	2, 4
C <sub>REF</sub>	Internal reference capacitor	—	1	—	pF	
V <sub>DELTA</sub>	Oscillator delta voltage	—	600	—	mV	2, 5
I <sub>REF</sub>	Reference oscillator current source base current <ul style="list-style-type: none"> <li>• 2 <math>\mu</math>A setting (REFCHRG = 0)</li> <li>• 32 <math>\mu</math>A setting (REFCHRG = 15)</li> </ul>	—	2 36	3 50	$\mu$ A	2,
I <sub>ELE</sub>	Electrode oscillator current source base current <ul style="list-style-type: none"> <li>• 2 <math>\mu</math>A setting (EXTCHRG = 0)</li> <li>• 32 <math>\mu</math>A setting (EXTCHRG = 15)</li> </ul>	—	2 36	3 50	$\mu$ A	2,
Pres5	Electrode capacitance measurement precision	—	8.3333	38400	fF/count	8
Pres20	Electrode capacitance measurement precision	—	8.3333	38400	fF/count	9
Pres100	Electrode capacitance measurement precision	—	8.3333	38400	fF/count	10
MaxSens	Maximum sensitivity	0.008	1.46	—	fF/count	11
Res	Resolution	—	—	16	bits	
T <sub>Con20</sub>	Response time @ 20 pF	8	15	25	$\mu$ s	12
I <sub>TSI_RUN</sub>	Current added in run mode	—	55	—	$\mu$ A	
I <sub>TSI_LP</sub>	Low power mode current adder	—	1.3	2.5	$\mu$ A	13

## Dimensions

1. The TSI module is functional with capacitance values outside this range. However, optimal performance is not guaranteed.
2. Fixed external capacitance of 20 pF.
3. REFCHRG = 2, EXTCHRG=0.
4. REFCHRG = 0, EXTCHRG = 10.
5.  $V_{DD} = 3.0\text{ V}$ .
6. Measured with a 5 pF electrode, reference oscillator frequency of 10 MHz, PS = 128, NSCN = 8; l<sub>ext</sub> = 16.
7. Measured with a 20 pF electrode, reference oscillator frequency of 10 MHz, PS = 128, NSCN = 2; l<sub>ext</sub> = 16.
8. Measured with a 20 pF electrode, reference oscillator frequency of 10 MHz, PS = 16, NSCN = 3; l<sub>ext</sub> = 16.
9. Sensitivity defines the minimum capacitance change when a single count from the TSI module changes. Sensitivity depends on the configuration used. The documented values are provided as examples calculated for a specific configuration of operating conditions using the following equation:  $(C_{ref} * I_{ext}) / (I_{ref} * PS * NSCN)$

The typical value is calculated with the following configuration:

$$I_{ext} = 6\ \mu\text{A (EXTCHRG = 2), PS = 128, NSCN = 2, I_{ref} = 16\ \mu\text{A (REFCHRG = 7), } C_{ref} = 1.0\ \text{pF}$$

The minimum value is calculated with the following configuration:

$$I_{ext} = 2\ \mu\text{A (EXTCHRG = 0), PS = 128, NSCN = 32, I_{ref} = 32\ \mu\text{A (REFCHRG = 15), } C_{ref} = 0.5\ \text{pF}$$

The highest possible sensitivity is the minimum value because it represents the smallest possible capacitance that can be measured by a single count.

10. Time to do one complete measurement of the electrode. Sensitivity resolution of 0.0133 pF, PS = 0, NSCN = 0, 1 electrode, EXTCHRG = 7.
11. REFCHRG=0, EXTCHRG=4, PS=7, NSCN=0F, LPSCNITV=F, LPO is selected (1 kHz), and fixed external capacitance of 20 pF. Data is captured with an average of 7 periods window.

## 7 Dimensions

### 7.1 Obtaining package dimensions

Package dimensions are provided in package drawings.

To find a package drawing, go to [freescale.com](http://freescale.com) and perform a keyword search for the drawing's document number:

If you want the drawing for this package	Then use this document number
144-pin MAPBGA	98ASA00222D

## 8 Pinout

### 8.1 Pins with active pull control after reset

The following pins are actively pulled up or down after reset:

**Table 58. Pins with active pull control after reset**

Pin	Active pull direction after reset
PTA0	pulldown
PTA1	pullup
PTA3	pullup
PTA4	pullup
RESET_b	pullup

## 8.2 K61 Signal Multiplexing and Pin Assignments

The following table shows the signals available on each pin and the locations of these pins on the devices supported by this document. The Port Control Module is responsible for selecting which ALT functionality is available on each pin.

144 MAP BGA	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
D3	PTE0	ADC1_SE4a	ADC1_SE4a	PTE0	SPI1_PCS1	UART1_TX	SDHC0_D1		I2C1_SDA	RTC_CLKOUT	
D2	PTE1/ LLWU_P0	ADC1_SE5a	ADC1_SE5a	PTE1/ LLWU_P0	SPI1_SOUT	UART1_RX	SDHC0_D0		I2C1_SCL	SPI1_SIN	
D1	PTE2/ LLWU_P1	ADC1_SE6a	ADC1_SE6a	PTE2/ LLWU_P1	SPI1_SCK	UART1_CTS_b	SDHC0_DCLK				
E4	PTE3	ADC1_SE7a	ADC1_SE7a	PTE3	SPI1_SIN	UART1_RTS_b	SDHC0_CMD			SPI1_SOUT	
E5	VDD	VDD	VDD								
F6	VSS	VSS	VSS								
E3	PTE4/ LLWU_P2	DISABLED		PTE4/ LLWU_P2	SPI1_PCS0	UART3_TX	SDHC0_D3				
E2	PTE5	DISABLED		PTE5	SPI1_PCS2	UART3_RX	SDHC0_D2		FTM3_CH0		
E1	PTE6	DISABLED		PTE6	SPI1_PCS3	UART3_CTS_b	I2S0_MCLK		FTM3_CH1	USB_SOF_OUT	
F4	PTE7	DISABLED		PTE7		UART3_RTS_b	I2S0_RXD0		FTM3_CH2		
F3	PTE8	ADC2_SE16	ADC2_SE16	PTE8	I2S0_RXD1	UART5_TX	I2S0_RX_FS		FTM3_CH3		
F2	PTE9	ADC2_SE17	ADC2_SE17	PTE9	I2S0_TXD1	UART5_RX	I2S0_RX_BCLK		FTM3_CH4		
F1	PTE10	DISABLED		PTE10		UART5_CTS_b	I2S0_TXD0		FTM3_CH5		
G4	PTE11	ADC3_SE16	ADC3_SE16	PTE11		UART5_RTS_b	I2S0_TX_FS		FTM3_CH6		
G3	PTE12	ADC3_SE17	ADC3_SE17	PTE12			I2S0_TX_BCLK		FTM3_CH7		
E6	VDD	VDD	VDD								
F7	VSS	VSS	VSS								
H3	VSS	VSS	VSS								
H1	USB0_DP	USB0_DP	USB0_DP								
H2	USB0_DM	USB0_DM	USB0_DM								
G1	VOUT33	VOUT33	VOUT33								

## Pinout

144 MAP BGA	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
G2	VREGIN	VREGIN	VREGIN								
J1	PGA2_DP/ ADC2_DP0/ ADC3_DP3/ ADC0_DP1	PGA2_DP/ ADC2_DP0/ ADC3_DP3/ ADC0_DP1	PGA2_DP/ ADC2_DP0/ ADC3_DP3/ ADC0_DP1								
J2	PGA2_DM/ ADC2_DM0/ ADC3_DM3/ ADC0_DM1	PGA2_DM/ ADC2_DM0/ ADC3_DM3/ ADC0_DM1	PGA2_DM/ ADC2_DM0/ ADC3_DM3/ ADC0_DM1								
K1	PGA3_DP/ ADC3_DP0/ ADC2_DP3/ ADC1_DP1	PGA3_DP/ ADC3_DP0/ ADC2_DP3/ ADC1_DP1	PGA3_DP/ ADC3_DP0/ ADC2_DP3/ ADC1_DP1								
K2	PGA3_DM/ ADC3_DM0/ ADC2_DM3/ ADC1_DM1	PGA3_DM/ ADC3_DM0/ ADC2_DM3/ ADC1_DM1	PGA3_DM/ ADC3_DM0/ ADC2_DM3/ ADC1_DM1								
L1	PGA0_DP/ ADC0_DP0/ ADC1_DP3	PGA0_DP/ ADC0_DP0/ ADC1_DP3	PGA0_DP/ ADC0_DP0/ ADC1_DP3								
L2	PGA0_DM/ ADC0_DM0/ ADC1_DM3	PGA0_DM/ ADC0_DM0/ ADC1_DM3	PGA0_DM/ ADC0_DM0/ ADC1_DM3								
M1	PGA1_DP/ ADC1_DP0/ ADC0_DP3	PGA1_DP/ ADC1_DP0/ ADC0_DP3	PGA1_DP/ ADC1_DP0/ ADC0_DP3								
M2	PGA1_DM/ ADC1_DM0/ ADC0_DM3	PGA1_DM/ ADC1_DM0/ ADC0_DM3	PGA1_DM/ ADC1_DM0/ ADC0_DM3								
H5	VDDA	VDDA	VDDA								
G5	VREFH	VREFH	VREFH								
G6	VREFL	VREFL	VREFL								
H6	VSSA	VSSA	VSSA								
K3	ADC1_SE16/ CMP2_IN2/ ADC0_SE22	ADC1_SE16/ CMP2_IN2/ ADC0_SE22	ADC1_SE16/ CMP2_IN2/ ADC0_SE22								
J3	ADC0_SE16/ CMP1_IN2/ ADC0_SE21	ADC0_SE16/ CMP1_IN2/ ADC0_SE21	ADC0_SE16/ CMP1_IN2/ ADC0_SE21								
M3	VREF_OUT/ CMP1_IN5/ CMP0_IN5/ ADC1_SE18	VREF_OUT/ CMP1_IN5/ CMP0_IN5/ ADC1_SE18	VREF_OUT/ CMP1_IN5/ CMP0_IN5/ ADC1_SE18								
L3	DAC0_OUT/ CMP1_IN3/ ADC0_SE23	DAC0_OUT/ CMP1_IN3/ ADC0_SE23	DAC0_OUT/ CMP1_IN3/ ADC0_SE23								
L4	DAC1_OUT/ CMP0_IN4/ CMP2_IN3/ ADC1_SE23	DAC1_OUT/ CMP0_IN4/ CMP2_IN3/ ADC1_SE23	DAC1_OUT/ CMP0_IN4/ CMP2_IN3/ ADC1_SE23								



144 MAP BGA	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
L5	TAMPER0/ RTC_ WAKEUP_B	TAMPER0/ RTC_ WAKEUP_B	TAMPER0/ RTC_ WAKEUP_B								
K5	TAMPER1	TAMPER1	TAMPER1								
K4	TAMPER2	TAMPER2	TAMPER2								
J4	TAMPER3	TAMPER3	TAMPER3								
H4	TAMPER4	TAMPER4	TAMPER4								
M4	TAMPER5	TAMPER5	TAMPER5								
M7	XTAL32	XTAL32	XTAL32								
M6	EXTAL32	EXTAL32	EXTAL32								
L6	VBAT	VBAT	VBAT								
J5	PTA0	JTAG_TCLK/ SWD_CLK/ EZP_CLK	TSIO_CH1	PTA0	UART0_CTS_ b/ UART0_COL_b	FTM0_CH5				JTAG_TCLK/ SWD_CLK	EZP_CLK
J6	PTA1	JTAG_TDI/ EZP_DI	TSIO_CH2	PTA1	UART0_RX	FTM0_CH6				JTAG_TDI	EZP_DI
K6	PTA2	JTAG_TDO/ TRACE_SWO/ EZP_DO	TSIO_CH3	PTA2	UART0_TX	FTM0_CH7				JTAG_TDO/ TRACE_SWO	EZP_DO
K7	PTA3	JTAG_TMS/ SWD_DIO	TSIO_CH4	PTA3	UART0_RTS_b	FTM0_CH0				JTAG_TMS/ SWD_DIO	
L7	PTA4/ LLWU_P3	NMI_b/ EZP_CS_b	TSIO_CH5	PTA4/ LLWU_P3		FTM0_CH1				NMI_b	EZP_CS_b
M8	PTA5	DISABLED		PTA5	USB_CLKIN	FTM0_CH2	RMIIO_RXER/ MII0_RXER	CMP2_OUT	I2S0_TX_BCLK	JTAG_TRST_b	
E7	VDD	VDD	VDD								
G7	VSS	VSS	VSS								
J7	PTA6	ADC3_SE6a	ADC3_SE6a	PTA6	ULPI_CLK	FTM0_CH3	I2S1_RXD0			TRACE_ CLKOUT	
J8	PTA7	ADC0_SE10	ADC0_SE10	PTA7	ULPI_DIR	FTM0_CH4	I2S1_RX_BCLK			TRACE_D3	
K8	PTA8	ADC0_SE11	ADC0_SE11	PTA8	ULPI_NXT	FTM1_CH0	I2S1_RX_FS		FTM1_QD_ PHA	TRACE_D2	
L8	PTA9	ADC3_SE5a	ADC3_SE5a	PTA9	ULPI_STP	FTM1_CH1	MII0_RXD3		FTM1_QD_ PHB	TRACE_D1	
M9	PTA10	ADC3_SE4a	ADC3_SE4a	PTA10	ULPI_DATA0	FTM2_CH0	MII0_RXD2		FTM2_QD_ PHA	TRACE_D0	
L9	PTA11	ADC3_SE15	ADC3_SE15	PTA11	ULPI_DATA1	FTM2_CH1	MII0_RXCLK		FTM2_QD_ PHB		
K9	PTA12	CMP2_IN0	CMP2_IN0	PTA12	CAN0_TX	FTM1_CH0	RMIIO_RXD1/ MII0_RXD1		I2S0_TXD0	FTM1_QD_ PHA	
J9	PTA13/ LLWU_P4	CMP2_IN1	CMP2_IN1	PTA13/ LLWU_P4	CAN0_RX	FTM1_CH1	RMIIO_RXD0/ MII0_RXD0		I2S0_TX_FS	FTM1_QD_ PHB	
L10	PTA14	CMP3_IN0	CMP3_IN0	PTA14	SPI0_PCS0	UART0_TX	RMIIO_CRS_ DV/ MII0_RXDV		I2S0_RX_BCLK	I2S0_TXD1	

## Pinout

144 MAP BGA	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
L11	PTA15	CMP3_IN1	CMP3_IN1	PTA15	SPI0_SCK	UART0_RX	RMIIO_TXEN/ MII0_TXEN		I2S0_RXD0		
K10	PTA16	CMP3_IN2	CMP3_IN2	PTA16	SPI0_SOUT	UART0_CTS_ b/ UART0_COL_b	RMIIO_TXD0/ MII0_TXD0		I2S0_RX_FS	I2S0_RXD1	
K11	PTA17	ADC1_SE17	ADC1_SE17	PTA17	SPI0_SIN	UART0_RTS_b	RMIIO_TXD1/ MII0_TXD1		I2S0_MCLK		
E8	VDD	VDD	VDD								
G8	VSS	VSS	VSS								
M12	PTA18	EXTAL0	EXTAL0	PTA18		FTM0_FLT2	FTM_CLKIN0				
M11	PTA19	XTAL0	XTAL0	PTA19		FTM1_FLT0	FTM_CLKIN1		LPTMR0_ALT1		
L12	RESET_b	RESET_b	RESET_b								
K12	PTA24	CMP3_IN4	CMP3_IN4	PTA24	ULPI_DATA2		MII0_TXD2		FB_A29		
J12	PTA25	CMP3_IN5	CMP3_IN5	PTA25	ULPI_DATA3		MII0_TXCLK		FB_A28		
J11	PTA26	ADC2_SE15	ADC2_SE15	PTA26	ULPI_DATA4		MII0_TXD3		FB_A27		
J10	PTA27	ADC2_SE14	ADC2_SE14	PTA27	ULPI_DATA5		MII0_CRS		FB_A26		
H12	PTA28	ADC2_SE13	ADC2_SE13	PTA28	ULPI_DATA6		MII0_TXER		FB_A25		
H11	PTA29	ADC2_SE12	ADC2_SE12	PTA29	ULPI_DATA7		MII0_COL		FB_A24		
H10	PTB0/ LLWU_P5	ADC0_SE8/ ADC1_SE8/ ADC2_SE8/ ADC3_SE8/ TSIO_CH0	ADC0_SE8/ ADC1_SE8/ ADC2_SE8/ ADC3_SE8/ TSIO_CH0	PTB0/ LLWU_P5	I2C0_SCL	FTM1_CH0	RMIIO_MDIO/ MII0_MDIO		FTM1_QD_ PHA		
H9	PTB1	ADC0_SE9/ ADC1_SE9/ ADC2_SE9/ ADC3_SE9/ TSIO_CH6	ADC0_SE9/ ADC1_SE9/ ADC2_SE9/ ADC3_SE9/ TSIO_CH6	PTB1	I2C0_SDA	FTM1_CH1	RMIIO_MDC/ MII0_MDC		FTM1_QD_ PHB		
G12	PTB2	ADC0_SE12/ TSIO_CH7	ADC0_SE12/ TSIO_CH7	PTB2	I2C0_SCL	UART0_RTS_b	ENET0_1588_ TMR0		FTM0_FLT3		
G11	PTB3	ADC0_SE13/ TSIO_CH8	ADC0_SE13/ TSIO_CH8	PTB3	I2C0_SDA	UART0_CTS_ b/ UART0_COL_b	ENET0_1588_ TMR1		FTM0_FLT0		
G10	PTB4	ADC1_SE10	ADC1_SE10	PTB4			ENET0_1588_ TMR2		FTM1_FLT0		
G9	PTB5	ADC1_SE11	ADC1_SE11	PTB5			ENET0_1588_ TMR3		FTM2_FLT0		
F12	PTB6	ADC1_SE12	ADC1_SE12	PTB6				FB_AD23			
F11	PTB7	ADC1_SE13	ADC1_SE13	PTB7				FB_AD22			
F10	PTB8	DISABLED		PTB8		UART3_RTS_b		FB_AD21			
F9	PTB9	DISABLED		PTB9	SPI1_PCS1	UART3_CTS_b		FB_AD20			
E12	PTB10	ADC1_SE14	ADC1_SE14	PTB10	SPI1_PCS0	UART3_RX	I2S1_TX_BCLK	FB_AD19	FTM0_FLT1		
E11	PTB11	ADC1_SE15	ADC1_SE15	PTB11	SPI1_SCK	UART3_TX	I2S1_TX_FS	FB_AD18	FTM0_FLT2		
H7	VSS	VSS	VSS								
F5	VDD	VDD	VDD								

144 MAP BGA	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
E10	PTB16	TSI0_CH9	TSI0_CH9	PTB16	SPI1_SOUT	UART0_RX	I2S1_TXD0	FB_AD17	EWM_IN		
E9	PTB17	TSI0_CH10	TSI0_CH10	PTB17	SPI1_SIN	UART0_TX	I2S1_TXD1	FB_AD16	EWM_OUT_b		
D12	PTB18	TSI0_CH11	TSI0_CH11	PTB18	CAN0_TX	FTM2_CH0	I2S0_TX_BCLK	FB_AD15	FTM2_QD_PHA		
D11	PTB19	TSI0_CH12	TSI0_CH12	PTB19	CAN0_RX	FTM2_CH1	I2S0_TX_FS	FB_OE_b	FTM2_QD_PHB		
D10	PTB20	ADC2_SE4a	ADC2_SE4a	PTB20	SPI2_PCS0			FB_AD31/ NFC_DATA15	CMP0_OUT		
D9	PTB21	ADC2_SE5a	ADC2_SE5a	PTB21	SPI2_SCK			FB_AD30/ NFC_DATA14	CMP1_OUT		
C12	PTB22	DISABLED		PTB22	SPI2_SOUT			FB_AD29/ NFC_DATA13	CMP2_OUT		
C11	PTB23	DISABLED		PTB23	SPI2_SIN	SPI0_PCS5		FB_AD28/ NFC_DATA12	CMP3_OUT		
B12	PTC0	ADC0_SE14/ TSI0_CH13	ADC0_SE14/ TSI0_CH13	PTC0	SPI0_PCS4	PDB0_EXTRG		FB_AD14/ NFC_DATA11	I2S0_TXD1		
B11	PTC1/ LLWU_P6	ADC0_SE15/ TSI0_CH14	ADC0_SE15/ TSI0_CH14	PTC1/ LLWU_P6	SPI0_PCS3	UART1_RTS_b	FTM0_CH0	FB_AD13/ NFC_DATA10	I2S0_TXD0		
A12	PTC2	ADC0_SE4b/ CMP1_IN0/ TSI0_CH15	ADC0_SE4b/ CMP1_IN0/ TSI0_CH15	PTC2	SPI0_PCS2	UART1_CTS_b	FTM0_CH1	FB_AD12/ NFC_DATA9	I2S0_TX_FS		
A11	PTC3/ LLWU_P7	CMP1_IN1	CMP1_IN1	PTC3/ LLWU_P7	SPI0_PCS1	UART1_RX	FTM0_CH2	CLKOUT	I2S0_TX_BCLK		
H8	VSS	VSS	VSS								
A9	PTC4/ LLWU_P8	DISABLED		PTC4/ LLWU_P8	SPI0_PCS0	UART1_TX	FTM0_CH3	FB_AD11/ NFC_DATA8	CMP1_OUT	I2S1_TX_BCLK	
D8	PTC5/ LLWU_P9	DISABLED		PTC5/ LLWU_P9	SPI0_SCK	LPTMR0_ALT2	I2S0_RXD0	FB_AD10/ NFC_DATA7	CMP0_OUT	I2S1_TX_FS	
C8	PTC6/ LLWU_P10	CMP0_IN0	CMP0_IN0	PTC6/ LLWU_P10	SPI0_SOUT	PDB0_EXTRG	I2S0_RX_BCLK	FB_AD9/ NFC_DATA6	I2S0_MCLK		
B8	PTC7	CMP0_IN1	CMP0_IN1	PTC7	SPI0_SIN	USB_SOF_OUT	I2S0_RX_FS	FB_AD8/ NFC_DATA5			
A8	PTC8	ADC1_SE4b/ CMP0_IN2	ADC1_SE4b/ CMP0_IN2	PTC8		FTM3_CH4	I2S0_MCLK	FB_AD7/ NFC_DATA4			
D7	PTC9	ADC1_SE5b/ CMP0_IN3	ADC1_SE5b/ CMP0_IN3	PTC9		FTM3_CH5	I2S0_RX_BCLK	FB_AD6/ NFC_DATA3	FTM2_FLT0		
C7	PTC10	ADC1_SE6b	ADC1_SE6b	PTC10	I2C1_SCL	FTM3_CH6	I2S0_RX_FS	FB_AD5/ NFC_DATA2	I2S1_MCLK		
B7	PTC11/ LLWU_P11	ADC1_SE7b	ADC1_SE7b	PTC11/ LLWU_P11	I2C1_SDA	FTM3_CH7	I2S0_RXD1	FB_RW_b/ NFC_WE			
A7	PTC12	DISABLED		PTC12		UART4_RTS_b		FB_AD27	FTM3_FLT0		
D6	PTC13	DISABLED		PTC13		UART4_CTS_b		FB_AD26			
C6	PTC14	DISABLED		PTC14		UART4_RX		FB_AD25			
B6	PTC15	DISABLED		PTC15		UART4_TX		FB_AD24			

## Pinout

144 MAP BGA	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
A6	PTC16	DISABLED		PTC16	CAN1_RX	UART3_RX	ENET0_1588_TMR0	FB_CS5_b/ FB_TSIZ1/ FB_BE23_16_b	NFC_RB		
D5	PTC17	DISABLED		PTC17	CAN1_TX	UART3_TX	ENET0_1588_TMR1	FB_CS4_b/ FB_TSIZ0/ FB_BE31_24_b	NFC_CE0_b		
C5	PTC18	DISABLED		PTC18		UART3_RTS_b	ENET0_1588_TMR2	FB_TBST_b/ FB_CS2_b/ FB_BE15_8_b	NFC_CE1_b		
B5	PTC19	DISABLED		PTC19		UART3_CTS_b	ENET0_1588_TMR3	FB_CS3_b/ FB_BE7_0_b	FB_TA_b		
A5	PTD0/ LLWU_P12	DISABLED		PTD0/ LLWU_P12	SPI0_PCS0	UART2_RTS_b	FTM3_CH0	FB_ALE/ FB_CS1_b/ FB_TS_b	I2S1_RXD1		
D4	PTD1	ADC0_SE5b	ADC0_SE5b	PTD1	SPI0_SCK	UART2_CTS_b	FTM3_CH1	FB_CS0_b	I2S1_RXD0		
C4	PTD2/ LLWU_P13	DISABLED		PTD2/ LLWU_P13	SPI0_SOUT	UART2_RX	FTM3_CH2	FB_AD4	I2S1_RX_FS		
B4	PTD3	DISABLED		PTD3	SPI0_SIN	UART2_TX	FTM3_CH3	FB_AD3	I2S1_RX_BCLK		
A4	PTD4/ LLWU_P14	DISABLED		PTD4/ LLWU_P14	SPI0_PCS1	UART0_RTS_b	FTM0_CH4	FB_AD2/ NFC_DATA1	EWM_IN		
A3	PTD5	ADC0_SE6b	ADC0_SE6b	PTD5	SPI0_PCS2	UART0_CTS_b/ UART0_COL_b	FTM0_CH5	FB_AD1/ NFC_DATA0	EWM_OUT_b		
A2	PTD6/ LLWU_P15	ADC0_SE7b	ADC0_SE7b	PTD6/ LLWU_P15	SPI0_PCS3	UART0_RX	FTM0_CH6	FB_AD0	FTM0_FLT0		
M10	VSS	VSS	VSS								
F8	VDD	VDD	VDD								
A1	PTD7	DISABLED		PTD7	CMT_IRO	UART0_TX	FTM0_CH7		FTM0_FLT1		
C9	PTD8	DISABLED		PTD8	I2C0_SCL	UART5_RX			FB_A16/ NFC_CLE		
B9	PTD9	DISABLED		PTD9	I2C0_SDA	UART5_TX			FB_A17/ NFC_ALE		
B3	PTD10	DISABLED		PTD10		UART5_RTS_b			FB_A18/ NFC_RE		
B2	PTD11	DISABLED		PTD11	SPI2_PCS0	UART5_CTS_b	SDHC0_CLKIN		FB_A19		
B1	PTD12	DISABLED		PTD12	SPI2_SCK	FTM3_FLT0	SDHC0_D4		FB_A20		
C3	PTD13	DISABLED		PTD13	SPI2_SOUT		SDHC0_D5		FB_A21		
C2	PTD14	DISABLED		PTD14	SPI2_SIN		SDHC0_D6		FB_A22		
C1	PTD15	DISABLED		PTD15	SPI2_PCS1		SDHC0_D7		FB_A23		
M5	NC	NC	NC								
A10	NC	NC	NC								
B10	NC	NC	NC								
C10	NC	NC	NC								

## 8.3 K61 Pinouts

The below figure shows the pinout diagram for the devices supported by this document. Many signals may be multiplexed onto a single pin. To determine what signals can be used on which pin, see the previous section.

	1	2	3	4	5	6	7	8	9	10	11	12	
A	PTD7	PTD6/ LLWU_P15	PTD5	PTD4/ LLWU_P14	PTD0/ LLWU_P12	PTC16	PTC12	PTC8	PTC4/ LLWU_P8	NC	PTC3/ LLWU_P7	PTC2	A
B	PTD12	PTD11	PTD10	PTD3	PTC19	PTC15	PTC11/ LLWU_P11	PTC7	PTD9	NC	PTC1/ LLWU_P6	PTC0	B
C	PTD15	PTD14	PTD13	PTD2/ LLWU_P13	PTC18	PTC14	PTC10	PTC6/ LLWU_P10	PTD8	NC	PTB23	PTB22	C
D	PTE2/ LLWU_P1	PTE1/ LLWU_P0	PTE0	PTD1	PTC17	PTC13	PTC9	PTC5/ LLWU_P9	PTB21	PTB20	PTB19	PTB18	D
E	PTE6	PTE5	PTE4/ LLWU_P2	PTE3	VDD	VDD	VDD	VDD	PTB17	PTB16	PTB11	PTB10	E
F	PTE10	PTE9	PTE8	PTE7	VDD	VSS	VSS	VDD	PTB9	PTB8	PTB7	PTB6	F
G	VOOUT33	VREGIN	PTE12	PTE11	VREFH	VREFL	VSS	VSS	PTB5	PTB4	PTB3	PTB2	G
H	USB0_DP	USB0_DM	VSS	TAMPER4	VDDA	VSSA	VSS	VSS	PTB1	PTB0/ LLWU_P5	PTA29	PTA28	H
J	PGA2_DP/ ADC2_DP0/ ADC3_DP3/ ADC0_DP1	PGA2_DM/ ADC2_DM0/ ADC3_DM3/ ADC0_DM1	ADC0_SE16/ CMP1_IN2/ ADC0_SE21	TAMPER3	PTA0	PTA1	PTA6	PTA7	PTA13/ LLWU_P4	PTA27	PTA26	PTA25	J
K	PGA3_DP/ ADC3_DP0/ ADC2_DP3/ ADC1_DP1	PGA3_DM/ ADC3_DM0/ ADC2_DM3/ ADC1_DM1	ADC1_SE16/ CMP2_IN2/ ADC0_SE22	TAMPER2	TAMPER1	PTA2	PTA3	PTA8	PTA12	PTA16	PTA17	PTA24	K
L	PGA0_DP/ ADC0_DP0/ ADC1_DP3	PGA0_DM/ ADC0_DM0/ ADC1_DM3	DAC0_OUT/ /CMP1_IN3/ ADC0_SE23	DAC1_OUT/ CMP0_IN4/ CMP2_IN3/ ADC1_SE23	TAMPER0/ RTC_ _WAKEUP_B	VBAT	PTA4/ LLWU_P3	PTA9	PTA11	PTA14	PTA15	RESET_b	L
M	PGA1_DP/ ADC1_DP0/ ADC0_DP3	PGA1_DM/ ADC1_DM0/ ADC0_DM3	VREF_OUT/ CMP1_IN5/ CMP0_IN5/ ADC1_SE18	TAMPER5	NC	EXTAL32	XTAL32	PTA5	PTA10	VSS	PTA19	PTA18	M

Figure 42. K61 144 MAPBGA Pinout Diagram

## 9 Revision History

The following table provides a revision history for this document.

K61 Sub-Family, Rev5, 10/2013.

Table 59. Revision History

Rev. No.	Date	Substantial Changes
3	3/2012	Initial public release
4	10/2012	Replaced TBDs throughout.
5	10/2013	<p>Changes for 4N96B mask set:</p> <ul style="list-style-type: none"> <li>• Min VDD operating requirement specification updated to support operation down to 1.71V.</li> </ul> <p>New specifications:</p> <ul style="list-style-type: none"> <li>• Added Vodpu specification.</li> <li>• Removed loz, loz_dds, and loz_tamper Hi-Z leakage specifications. They have been replaced by new lina, lind, and Zind specifications.</li> <li>• Fpll_ref_acc specification has been added.</li> <li>• I<sup>2</sup>C module was previously covered by the general switching specifications. To provide more detail on I<sup>2</sup>C operation a dedicated Inter-Integrated Circuit Interface (I<sup>2</sup>C) timing section has been added.</li> </ul> <p>Modified specifications:</p> <ul style="list-style-type: none"> <li>• Vref_dds max spec has been updated.</li> <li>• Tpor spec has been split into two specifications based on VDD slew rate.</li> <li>• Trd1allx and Trd1alln max have been updated.</li> <li>• 16-bit ADC Temp sensor slope and Temp sensor voltage (Vtemp25) have been modified. The typical values that were listed previously have been updated, and min and max specifications have been added.</li> </ul> <p>Corrections:</p> <ul style="list-style-type: none"> <li>• Some versions of the datasheets listed incorrect clock mode information in the "Diagram: Typical IDD_RUN operating behavior section." These errors have been corrected.</li> <li>• Fintf_ft specification was previously shown as a max value. It has been corrected to be shown as a typical value as originally intended.</li> <li>• Corrected DDR write and read timing diagrams to show the correct location of the Tcmv specification.</li> <li>• SDHC peripheral 50MHz high speed mode options were left out of the last datasheet. These have been added to the SDHC specifications section.</li> </ul>



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